S7IGLxxxNC0

Stacked Multi-chip Product (MCP) 512/256/128 Megabit (32/16/8 M x 16-bit) CMOS 3.0 Volt-only MirrorBit[™] Page-mode Flash Memory with 64 Megabit (4M x 16-bit) pSRAM



Data Sheet

ADVANCE INFORMATION

Distinctive Characteristics

MCP Features

Power supply voltage of 2.7 to 3.1V

High Performance

- 100 ns access time (S71GL128N, S71GL256N)
- 110 ns access time (S71GL512N)
- 25 ns page read times
- Packages:
 - 9.0 x 12.0 mm x 1.2 mm FBGA (TLD084) (S71GL512N)
 - 8.0 x 11.6 mm x 1.2 mm FBGA (TLA084) (S71GL128N, S71GL256N)
- Operating Temperature
 - -25°C to +85°C (Wireless)

General Description

The S71GL Series is a product line of stacked Multi-chip Product (MCP) packages and consists of

- One Flash memory die
- One pSRAM

The products covered by this document are listed in the table below. For details about their specifications, please refer to the individual constituent datasheets for further details.

| | | Flash Memory Density | | | | |
|---------------|-------|----------------------|-------------|-------------|--|--|
| | | 512 Mb | 256 Mb | 128 Mb | | |
| pSRAM Density | 64 Mb | S71GL512NC0 | S71GL256NC0 | S71GL128NC0 | | |

This document contains information on a product under development at Spansion LLC. The information is intended to help you evaluate this product. Spansion LLC reserves the right to change or discontinue work on this proposed product without notice.



S7IGLxxxNC0

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| MCP Compatible Package | |
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| MCP Compatible Package | 16 |
| | |

S29GLxxxN MirrorBit[™] Flash Family

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Product Selector Guide

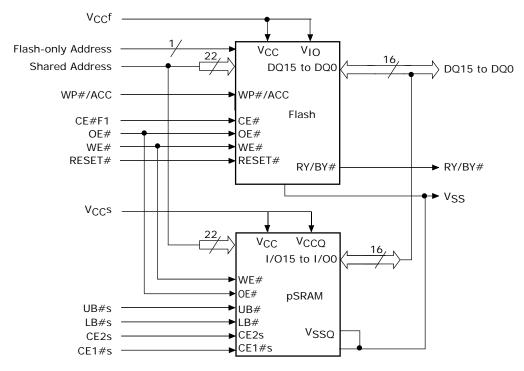
| \$71GL512NC0 | | | | | | | | |
|---|-----|-------|----|--|--|--|--|--|
| Access Times at V _{CC} = 2.7 - 3.1 V | Fla | Flash | | | | | | |
| Max. Access Time (ns) | 110 | 100 | 70 | | | | | |
| Max. CE# Access Time (ns) | 110 | 100 | 70 | | | | | |
| Max. Page Access Time (ns) | 25 | | 25 | | | | | |
| Max. OE# Access Time (ns) | 2 | 25 | | | | | | |

| S7IGL256NC0 | | | | | | | | |
|---|---|----|----|--|--|--|--|--|
| Access Times at V _{CC} = 2.7 - 3.1 V | Access Times at V _{CC} = 2.7 - 3.1 V Flash | | | | | | | |
| Max. Access Time (ns) | 100 | 90 | 70 | | | | | |
| Max. CE# Access Time (ns) | 100 | 90 | 70 | | | | | |
| Max. Page Access Time (ns) | 2 | 25 | | | | | | |
| Max. OE# Access Time (ns) | 25 | | 25 | | | | | |

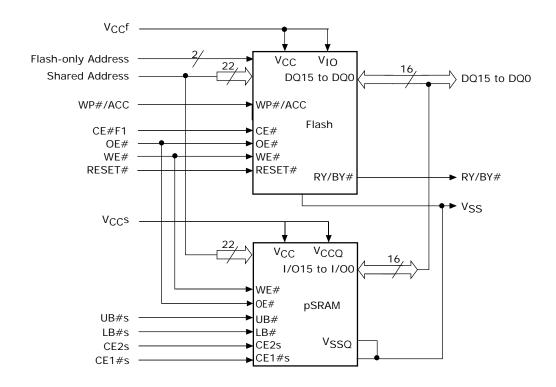
| S7IGLI28NC0 | | | | | | | | |
|---|-----|-------|----|--|--|--|--|--|
| Access Times at V _{CC} = 2.7 - 3.1 V | Fla | pSRAM | | | | | | |
| Max. Access Time (ns) | 100 | 90 | 70 | | | | | |
| Max. CE# Access Time (ns) | 100 | 90 | 70 | | | | | |
| Max. Page Access Time (ns) | 25 | | 25 | | | | | |
| Max. OE# Access Time (ns) | 25 | | 25 | | | | | |



MCP Block Diagram (I28Mb Flash + 64Mb pSRAM)

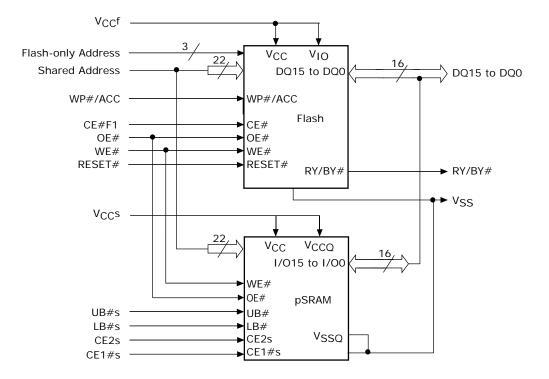


MCP Block Diagram (256Mb Flash + 64Mb pSRAM)





MCP Block Diagram (512Mb Flash + 64Mb pSRAM)





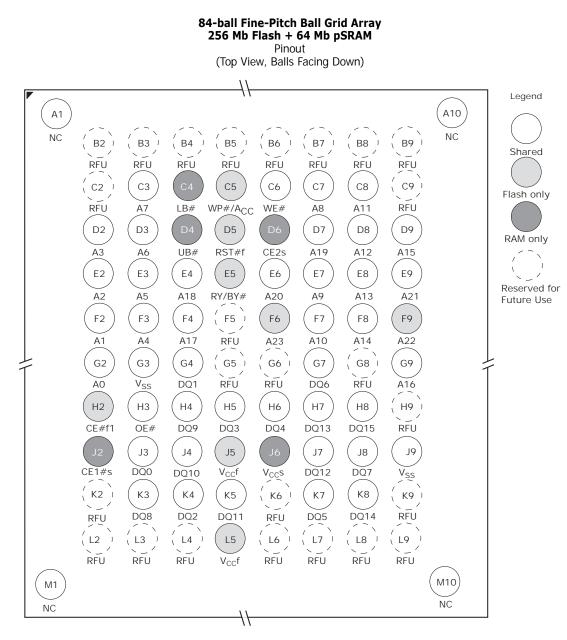
Connection Diagrams

512 Mb Flash + 64 Mb pSRAM Pinout

84-ball Fine-Pitch Ball Grid Array 512 Mb Flash + 64 Mb pSRAM Pinout (Top View, Balls Facing Down) Legend A10 A1 NC NC (́ В5) 1 , B4 J B6 B2) B3) Β7 B8 B9) ١ Shared RFU RFU RFU RFU RFU RFU RFU RFU C2 C3 C5 C6 С7 С8 C9 Flash only WP#/A_{CC} RFU WE# A11 RFU Α7 LB# A8 D3 D5 D7 D8 D2 D9 RAM only A6 UB# RST#f CE2s A19 A12 A15 А3) E9 E2 E3 E4 E5 E8 E6 E7 Reserved for A2 Α5 A18 RY/BY# A20 Α9 A13 A21 Future Use F3 F4 F5 F6 F7 F8 F9 F2) A1 A4 A17 RFU A10 A14 A22 A23 G2 G3 G4 G7 G8 G9 G5) G6) V_{SS} AO DQ1 RFU RFU DQ6 A24 A16 H2 Η4 Η7 Н3 Η5 H6 Н8 (́ H9) CE#f1 DQ4 OE# DQ9 DQ3 DQ13 DQ15 RFU J4 J9 J3 J5 J7 J8 CE1#s V_{SS} DQO DQ12 DQ7 DQ10 $V_{CC}f$ V_{CC}s К3 К2 Κ4 Κ5 К6 Κ7 K8 Κ9 < _ / DQ14 RFU DQ8 DQ2 DQ5 RFU DQ11 RFU L2 L3 L5 L7) L8) L9 L4 L6 RFU RFU RFU RFU RFU RFU $V_{CC}f$ RFU M10 M1 NC NC ₩



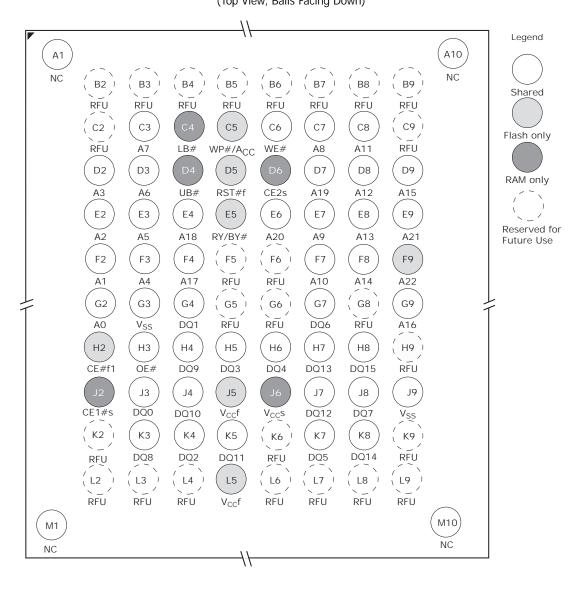
256 Mb Flash + 64 Mb pSRAM Pinout





I28 Mb Flash + 64 Mb pSRAM Pinout

84-ball Fine-Pitch Ball Grid Array 128 Mb Flash + 64 Mb pSRAM Pinout (Top View, Balls Facing Down)

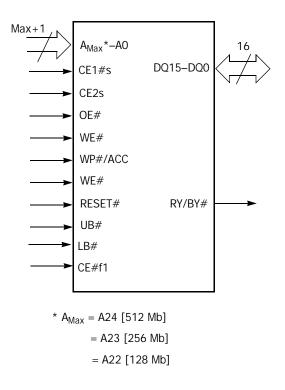




Input/Output Descriptions

| A24-A0 | = | 25 Address inputs (512 Mb) |
|-------------------|---|---|
| A23-A0 | = | 24 Address inputs (256 Mb) |
| A22-A0 | = | 23 Address inputs (128 Mb) |
| DQ15-DQ0 | = | Data input/output |
| OE# | = | Output Enable input. Asynchronous relative to CLK for the Burst mode. |
| WE# | = | Write Enable input. |
| V _{SS} | = | Ground |
| NC | = | No Connect; not connected internally |
| RESET# | = | Hardware reset input. Low = device resets and returns to reading array data |
| WP#/ACC | = | Hardware write protect input / programming acceleration input. |
| CE1#s, CE2s | = | Chip-enable input for pSRAM. |
| CE#f1 | = | Chip-enable input for Flash 1. |
| V _{CC} f | = | Flash 3.0 Volt-only single power supply. |
| V _{CC} s | = | pSRAM Power Supply. |
| UB#s | = | Upper Byte Control (pSRAM). |
| LB#s | = | Lower Byte Control (pSRAM). |
| RFU | = | Reserved for future use. |
| RY/BY# | = | Ready/Busy output. |

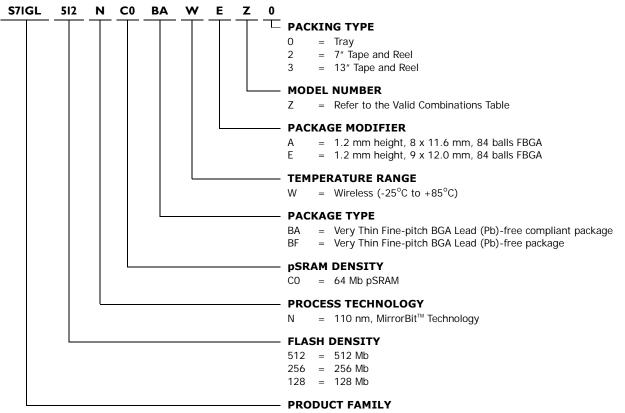
Logic Symbol





Ordering Information

The order number (Valid Combination) is formed by the following:



S71GL Multi-chip Product (MCP) 3.0 Volt-only Uniform Sector Page Mode Flash Memory with pSRAM



| S71GL | 512NC0 Valid C | Combinatior | IS | | | | | | |
|---------------------------------|--------------------------|---|-----------------|-------------------------------------|---------------------------------|---------------------|---|--|--------------------|
| Base Ordering Part Number | Package & Temperature | Package Modifier/ Model Number | Packing Type | Flash Initial/Page Speed (ns) | Address Sector Protection | (p)SRAM Supplier | (p)SRAM Type/ Access Time (ns) | Package Type | Package Marking |
| | | EU | | 110/25 | Lowest Add | Type 7 | | 0 10 | |
| S71GL512NC0 | BAW | EZ | 0, 2, 3 | 110/25 | Highest Add | Type / | 70/25 | 9mmx12mm 84-ball Lead (Pb)-free Compliant | |
| | | ET | (Note 1) |) 100 (Note 3)/ | Lowest Add | Turne 7 | 70/25 | | |
| | | EY | | 25 | Highest Add | Type 7 | | Compliant | (Note 2) |
| | | EU | | 110/25 | Lowest Add | | | | (Note 2) |
| S71GL512NC0 | BFW | EZ | 0, 2, 3 | | Highest Add | Jhest Add | 70/25 | 9mmx12mm 84-ball Lead | |
| | | ET | (Note 1) | 100 (Note 3)/ | Lowest Add | | | (Pb)-free | |
| | | EY | | 25 | Highest Add | Type 7 | | | |

Notes:

1. 2.

Type 0 is standard. Specify other options as required. BGA package marking omits leading "S" and packing type designator from ordering part number.

3. Contact the factory for the 100 ns speed option.

Valid Combinations

Valid Combinations list configurations planned to be supported in vol-ume for this device. Consult your local sales office to confirm avail-ability of specific valid combinations and to check on newly released combinations.



| S71GL | 256NC0 Valid (| Combination | IS | | | | | | |
|---------------------------------|--------------------------|---|-----------------|---|---------------------------------|---------------------|---|--|--------------------|
| Base Ordering Part Number | Package & Temperature | Package Modifier/ Model Number | Packing Type | Flash Initial/ Page Speed (ns) | Address Sector Protection | (p)SRAM Supplier | (p)SRAM Type/ Access Time (ns) | Package Type | Package Marking |
| | | AU | | 100/25 | Lowest Add | Type 7 | | | |
| \$71CL254NC0 | 71GL256NC0 BAW AT | | 0, 2, 3 | 100725 | Highest Add | Type 7 | 70/25 | 8mmx11.6mm 84-ball Lead (Pb)-free Compliant | |
| 37TGL250NCU | | | (Note 1) | 90 (Note 3)/ | Lowest Add | | | | |
| | | AY | | 25 | Highest Add | Type 7 | | Compliant | (Note 2) |
| | | AU | | 100/25 | Lowest Add | Type 7 | | | (Note 2) |
| S71GL256NC0 | BFW | AZ | 0, 2, 3 | 100/25 | Highest Add | турет | 70/25 | 8mmx11.6mm 84-ball Lead | |
| 371622501000 | STIGE250NCO BEW | | (Note 1) | 90 (Note 3)/ | Lowest Add | Tupo 7 | 10/25 | (Pb)-free | |
| | | AY | | 25 | Highest Add | Туре 7 | | | |

Notes:

1. 2.

Type 0 is standard. Specify other options as required. BGA package marking omits leading "S" and packing type designator from ordering part number.

3. Contact the factory for the 90 ns speed option.

Valid Combinations

Valid Combinations list configurations planned to be supported in vol-ume for this device. Consult your local sales office to confirm avail-ability of specific valid combinations and to check on newly released combinations.



| S71GL | 128NC0 Valid | Combination | s | | | | | | |
|---------------------------------|--------------------------|---|-----------------|-------------------------------------|---------------------------------|---------------------|---|----------------------------|--------------------|
| Base Ordering Part Number | Package & Temperature | Package Modifier/ Model Number | Packing Type | Flash Initial/Page Speed (ns) | Address Sector Protection | (p)SRAM Supplier | (p)SRAM Type/ Access Time (ns) | Package Type | Package Marking |
| | | AU | | 100/25 | Lowest Add | Type 7 | | 0 | |
| S71GL128NC0 | BAW | AZ | 0, 2, 3 | 100725 | Highest Add | Type 7 | 70/25 | 8mmx11.6mm 84-ball Lead | |
| STIGLIZONCO | DAW | AT | (Note 1) | 90 (Note 3)/ | Lowest Add | Type 7 | 70/25 | (Pb)-free Compliant | |
| | | AY | | 25 | Highest Add | Type 7 | | compliant | (Note 2) |
| | | AU | | 100/25 | Lowest Add | Type 7 | | | (Note 2) |
| S71GL128NC0 | BFW | AZ | 0, 2, 3 | 100/25 | Highest Add | Type 7 | 70/25 | 8mmx11.6mm 84-ball Lead | |
| 371GL120NCU | DEAN | AT | (Note 1) | 90 (Note 3)/ | Lowest Add | Tupo 7 | /0/25 | (Pb)-free | |
| | | AY | | 25 | Highest Add | Type 7 | | | |

Notes:

1. 2.

Type 0 is standard. Specify other options as required. BGA package marking omits leading "S" and packing type designator from ordering part number.

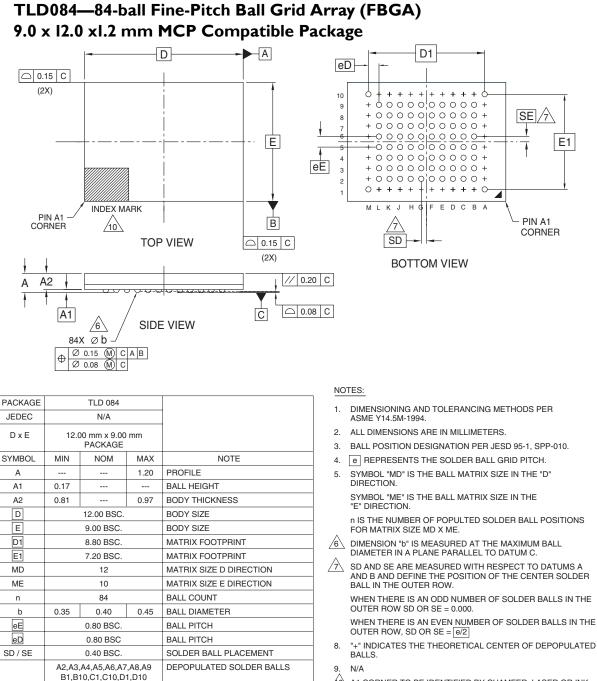
3. Contact the factory for the 90 ns speed option.

Valid Combinations

Valid Combinations list configurations planned to be supported in vol-ume for this device. Consult your local sales office to confirm avail-ability of specific valid combinations and to check on newly released combinations.



Physical Dimensions



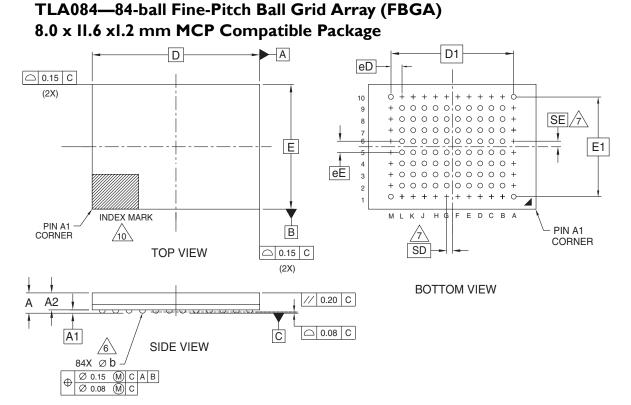
A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.

3367\ 16-038.22a

E1,E10,F1,F10,G1,G10

H1,H10,J1,J10,K1,K10 L1,L10,M2,M3,M4,M5,M6, M7,M8,M9

Note: BSC is an ANSI standard for Basic Space Centering



| PACKAGE | | TLA 084 | | |
|---------|--------------------------|---|-------------------------------|--------------------------|
| JEDEC | | N/A | | |
| D x E | 11.6 | 60 mm x 8.00 PACKAGE | mm | |
| SYMBOL | MIN | NOM | MAX | NOTE |
| A | | | 1.20 | PROFILE |
| A1 | 0.17 | | | BALL HEIGHT |
| A2 | 0.81 | | 0.97 | BODY THICKNESS |
| D | | 11.60 BSC. | | BODY SIZE |
| E | | 8.00 BSC. | | BODY SIZE |
| D1 | | 8.80 BSC. | | MATRIX FOOTPRINT |
| E1 | | 7.20 BSC. | | MATRIX FOOTPRINT |
| MD | | 12 | | MATRIX SIZE D DIRECTION |
| ME | | 10 | | MATRIX SIZE E DIRECTION |
| n | | 84 | | BALL COUNT |
| Øb | 0.35 | 0.40 | 0.45 | BALL DIAMETER |
| eE | | 0.80 BSC. | | BALL PITCH |
| eD | | 0.80 BSC | | BALL PITCH |
| SD / SE | | 0.40 BSC. | | SOLDER BALL PLACEMENT |
| | B1,B1 E1,E H1,H10, | A4,A5,A6,A7 10,C1,C10,D1 10,F1,F10,G1 J1,J10,K1,K1 M4,M5,M6,M | 1,D10, 1,G10, 0,L1,L10, | DEPOPULATED SOLDER BALLS |

Note: BSC is an ANSI standard for Basic Space Centering

NOTES:

- 1. DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH.
- 5. SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.

SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION.

n IS THE NUMBER OF POPULTED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.

DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.

 $\not / \overline{ \ }$ SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.

WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW SD OR SE = 0.000.

WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = $\boxed{e/2}$

8. "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.

A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.

3372-2 \ 16-038.22a

^{9.} N/A

S29GLxxxN MirrorBit[™] Flash Family

S29GL5I2N, S29GL256N, S29GLI28N 5I2 Megabit, 256 Megabit, and I28 Megabit, 3.0 Volt-only Page Mode Flash Memory featuring II0 nm MirrorBit process technology

Data Sheet

Distinctive Characteristics

Architectural Advantages

- Single power supply operation
 - 3 volt read, erase, and program operations
- Enhanced VersatileI/O[™] control
 - All input levels (address, control, and DQ input levels) and outputs are determined by voltage on V_{IO} input. V_{IO} range is 1.65 to V_{CC}
- Manufactured on 110 nm MirrorBit process technology
- Secured Silicon Sector region
 - 128-word/256-byte sector for permanent, secure identification through an 8-word/16-byte random Electronic Serial Number, accessible through a command sequence
 - May be programmed and locked at the factory or by the customer
- Flexible sector architecture
 - S29GL512N: Five hundred twelve 64 Kword (128 Kbyte) sectors
 - S29GL256N: Two hundred fifty-six 64 Kword (128 Kbyte) sectors
 - S29GL128N: One hundred twenty-eight 64 Kword (128 Kbyte) sectors
- Compatibility with JEDEC standards
 - Provides pinout and software compatibility for singlepower supply flash, and superior inadvertent write protection
- 100,000 erase cycles per sector typical
- 20-year data retention typical

Performance Characteristics

High performance

- 90 ns access time (S29GL128N, S29GL256N, S29GL512N)
- 8-word/16-byte page read buffer
- 25 ns page read times
- 16-word/32-byte write buffer reduces overall programming time for multiple-word updates
- Low power consumption (typical values at 3.0 V, 5 MHz)
 - 25 mA typical active read current;
 - 50 mA typical erase/program current
 - 1 µA typical standby mode current

Software & Hardware Features

Software features

- Program Suspend & Resume: read other sectors before programming operation is completed
- Erase Suspend & Resume: read/program other sectors before an erase operation is completed
- Data# polling & toggle bits provide status
- Unlock Bypass Program command reduces overall multiple-word programming time
- CFI (Common Flash Interface) compliant: allows host system to identify and accommodate multiple flash devices

Hardware features

- Advanced Sector Protection
- WP#/ACC input accelerates programming time (when high voltage is applied) for greater throughput during system production. Protects first or last sector regardless of sector protection settings
- Hardware reset input (RESET#) resets device
- Ready/Busy# output (RY/BY#) detects program or erase cycle completion

This document contains information on a product under development at Spansion LLC. The information is intended to help you evaluate this product. Spansion LLC reserves the right to change or discontinue work on this proposed product without notice.



ADVANCE INFORMATION



General Description

The S29GL512/256/128N family of devices are 3.0V single power flash memory manufactured using 110 nm MirrorBit technology. The S29GL512N is a 512 Mbit, organized as 33,554,432 words or 67,108,864 bytes. The S29GL256N is a 256 Mbit, organized as 16,777,216 words or 33,554,432 bytes. The S29GL128N is a 128 Mbit, organized as 8,388,608 words or 16,777,216 bytes. The device can be programmed either in the host system or in standard EPROM programmers.

Access times as fast as 90 ns (S29GL128N, S29GL256N, S29GL512N) are available. Note that each access time has a specific operating voltage range (V_{CC}) and an I/O voltage range (V_{IO}), as specified in the "Product Selector Guide" section. The devices are offered in a 56-pin TSOP or 64-ball Fortified BGA package. Each device has separate chip enable (CE#), write enable (WE#) and output enable (OE#) controls.

Each device requires only a **single 3.0 volt power supply** for both read and write functions. In addition to a V_{CC} input, a high-voltage **accelerated program** (WP#/ACC) input provides shorter programming times through increased current. This feature is intended to facilitate factory throughput during system production, but may also be used in the field if desired.

The devices are entirely command set compatible with the **JEDEC singlepower-supply Flash standard**. Commands are written to the device using standard microprocessor write timing. Write cycles also internally latch addresses and data needed for the programming and erase operations.

The **sector erase architecture** allows memory sectors to be erased and reprogrammed without affecting the data contents of other sectors. The device is fully erased when shipped from the factory.

Device programming and erasure are initiated through command sequences. Once a program or erase operation has begun, the host system need only poll the DQ7 (Data# Polling) or DQ6 (toggle) **status bits** or monitor the **Ready/Busy#** (**RY/BY#**) output to determine whether the operation is complete. To facilitate programming, an **Unlock Bypass** mode reduces command sequence overhead by requiring only two write cycles to program data instead of four.

The **Enhanced VersatileI/O[™]** (V_{IO}) control allows the host system to set the voltage levels that the device generates and tolerates on all input levels (address, chip control, and DQ input levels) to the same voltage level that is asserted on the V_{IO} pin. This allows the device to operate in a 1.8 V or 3 V system environment as required.

Hardware data protection measures include a low V_{CC} detector that automatically inhibits write operations during power transitions. **Persistent Sector Protection** provides in-system, command-enabled protection of any combination of sectors using a single power supply at V_{CC}. **Password Sector Protection** prevents unauthorized write and erase operations in any combination of sectors through a user-defined 64-bit password.

The **Erase Suspend/Erase Resume** feature allows the host system to pause an erase operation in a given sector to read or program any other sector and then complete the erase operation. The **Program Suspend/Program Resume** feature enables the host system to pause a program operation in a given sector to read any other sector and then complete the program operation.

The **hardware RESET# pin** terminates any operation in progress and resets the device, after which it is then ready for a new operation. The RESET# pin may be



tied to the system reset circuitry. A system reset would thus also reset the device, enabling the host system to read boot-up firmware from the Flash memory device.

The device reduces power consumption in the **standby mode** when it detects specific voltage levels on CE# and RESET#, or when addresses have been stable for a specified period of time.

The **Secured Silicon Sector** provides a 128-word/256-byte area for code or data that can be permanently protected. Once this sector is protected, no further changes within the sector can occur.

The **Write Protect (WP#/ACC)** feature protects the first or last sector by asserting a logic low on the WP# pin.

MirrorBit flash technology combines years of Flash memory manufacturing experience to produce the highest levels of quality, reliability and cost effectiveness. The device electrically erases all bits within a sector simultaneously via hot-hole assisted erase. The data is programmed using hot electron injection.

Product Selector Guide

S29GL512N

| Part Number | | S29GL512N | | | | |
|----------------------|------------------------|-------------------------------|----|-----|-----|-----|
| | V 27.24V | V _{IO} = 2.7–3.6 V | | 10 | 11 | |
| Speed Option | $V_{CC} = 2.7 - 3.6 V$ | V _{IO} = 1.65–1.95 V | | | | 11 |
| | $V_{CC} = 3.0-3.6V$ | $V_{10} = 3.0-3.6V$ | 90 | | | |
| Max. Access Time (r | ns) | | 90 | 100 | 110 | 110 |
| Max. CE# Access Tir | me (ns) | | 90 | 100 | 110 | 110 |
| Max. Page access tir | ne (ns) | | 25 | 25 | 25 | 30 |
| Max. OE# Access Tir | me (ns) | | 25 | 25 | 25 | 30 |

S29GL256N

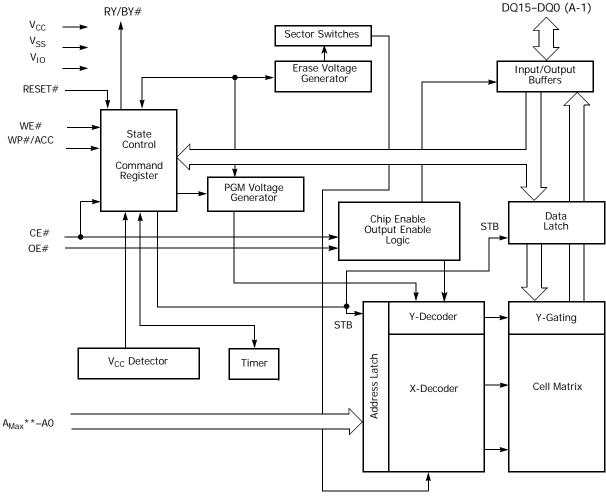
| Part Number | | S29 | GL256N | | | |
|----------------------|---------------------------------|---------------------------------|--------|-----|-----|-----|
| | V 27.24V | $V_{10} = 2.7 - 3.6 V$ | | 10 | 11 | |
| Speed Option | $V_{CC} = 2.7 - 3.6 V$ | V _{IO} = 1.65–1.95 V | | | | 11 |
| | V_{CC} = Regulated (3.0-3.6V) | V_{IO} = Regulated (3.0-3.6V) | 90 | | | |
| Max. Access Time (ns | 3) | | 90 | 100 | 110 | 110 |
| Max. CE# Access Tim | e (ns) | | 90 | 100 | 110 | 110 |
| Max. Page access tim | e (ns) | | 25 | 25 | 25 | 30 |
| Max. OE# Access Tim | ne (ns) | | 25 | 25 | 25 | 30 |

S29GLI28N

| Part Number | | S29 | GL128N | | | |
|-----------------------|---------------------------------|---------------------------------|--------|-----|-----|-----|
| | V 27.24V | $V_{10} = 2.7 - 3.6 V$ | | 10 | 11 | |
| Speed Option | $V_{CC} = 2.7 - 3.6 V$ | V _{IO} = 1.65–1.95 V | | | | 11 |
| | V_{CC} = Regulated (3.0-3.6V) | V_{IO} = Regulated (3.0-3.6V) | 90 | | | |
| Max. Access Time (ns) |) | | 90 | 100 | 110 | 110 |
| Max. CE# Access Time | e (ns) | | 90 | 100 | 110 | 110 |
| Max. Page access time | e (ns) | | 25 | 25 | 25 | 30 |
| Max. OE# Access Time | e (ns) | | 25 | 25 | 25 | 30 |



Block Diagram



Notes:

1. $A_{Max} GL512N = A24$, $A_{Max} GL256N = A23$, $A_{Max} GL128N = A22$

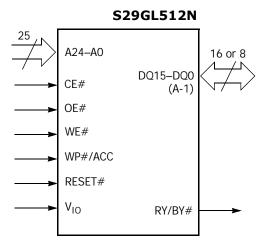


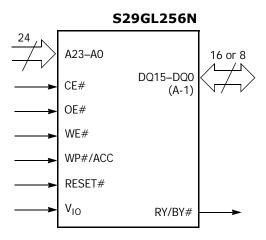
Pin Description

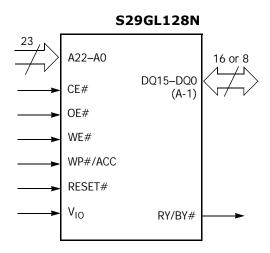
| A24–A0 | = | 25 Address inputs (512 Mb) |
|-----------------|---|---|
| A23–A0 | = | 24 Address inputs (256 Mb) |
| A22–A0 | = | 23 Address inputs (128 Mb) |
| DQ14-DQ0 | = | 15 Data inputs/outputs |
| DQ15/A-1 | = | DQ15 (Data input/output, word mode), A-1 (LSB |
| | | Address input |
| CE# | = | Chip Enable input |
| OE# | = | Output Enable input |
| WE# | = | Write Enable input |
| WP#/ACC | = | Hardware Write Protect input; |
| | | Acceleration input |
| RESET# | = | Hardware Reset Pin input |
| RY/BY# | = | Ready/Busy output |
| V _{CC} | = | 3.0 volt-only single power supply |
| | | (see Product Selector Guide for speed options and |
| | | voltage supply tolerances) |
| V _{IO} | = | Output Buffer power |
| V _{SS} | = | Device Ground |
| NC | = | Pin Not Connected Internally |



Logic Symbol











Device Bus Operations

This section describes the requirements and use of the device bus operations, which are initiated through the internal command register. The command register itself does not occupy any addressable memory location. The register is a latch used to store the commands, along with the address and data information needed to execute the command. The contents of the register serve as inputs to the internal state machine. The state machine outputs dictate the function of the device. Table 1 lists the device bus operations, the inputs and control levels they require, and the resulting output. The following subsections describe each of these operations in further detail.

| Operation | CE# | OE# | WE# | RESET# | WP#/ ACC | Addresses (Note 1) | DQ0-DQ15 |
|-----------------------|--------------------|-----|-----|----------------------------|-----------------|-----------------------|------------------|
| Read | L | L | Н | Н | Х | A _{IN} | D _{OUT} |
| Write (Program/Erase) | L | Н | L | Н | Note 2 | A _{IN} | (Note 3) |
| Accelerated Program | L | Н | L | Н | V _{HH} | A _{IN} | (Note 3) |
| Standby | $V_{CC} \pm 0.3 V$ | x | х | V _{CC} ± 0.3 V | Н | Х | High-Z |
| Output Disable | L | Н | Н | Н | Х | Х | High-Z |
| Reset | Х | Х | Х | L | Х | Х | High-Z |

| Table I | Davica | Due O | novotiona |
|----------|--------|-------|-----------|
| Table I. | Device | Bus O | perations |

Legend: $L = Logic Low = V_{IL}$, $H = Logic High = V_{IH}$, $V_{ID} = 11.5-12.5 V$, $V_{HH} = 11.5-12.5V$, X = Don't Care, SA = Sector Address, $A_{IN} = Address In$, $D_{IN} = Data In$, $D_{OUT} = Data Out$

Notes:

- 1. Addresses are AMax:A0 in word mode. Sector addresses are A_{Max}:A16 in both modes.
- 2. If $WP\# = V_{IL}$, the first or last sector group remains protected. If $WP\# = V_{IH}$, the first or last sector will be protected or unprotected as determined by the method described in "Write Protect (WP#)". All sectors are unprotected when shipped from the factory (The Secured Silicon Sector may be factory protected depending on version ordered.)
- 3. D_{IN} or D_{OUT} as required by command sequence, data polling, or sector protect algorithm (see Figure 2, Figure 4, and Figure 5).

VersatileIO[™] (V_{IO}) Control

The **VersatileIO**TM (V_{IO}) control allows the host system to set the voltage levels that the device generates and tolerates on CE# and DQ I/Os to the same voltage level that is asserted on V_{IO}. See Ordering Information for V_{IO} options on this device.

For example, a V_{I/O} of 1.65 V to 3.6 V allows for I/O at the 1.8 or 3 volt levels, driving and receiving signals to and from other 1.8-V or 3-V devices on the same data bus.

Requirements for Reading Array Data

To read array data from the outputs, the system must drive the CE# and OE# pins to V_{IL}. CE# is the power control and selects the device. OE# is the output control and gates array data to the output pins. WE# should remain at V_{IH}.

The internal state machine is set for reading array data upon device power-up, or after a hardware reset. This ensures that no spurious alteration of the memory



content occurs during the power transition. No command is necessary in this mode to obtain array data. Standard microprocessor read cycles that assert valid addresses on the device address inputs produce valid data on the device data outputs. The device remains enabled for read access until the command register contents are altered.

See "Reading Array Data" on page 67 for more information. Refer to the AC Read-Only Operations table for timing specifications and to Figure 11 for the timing diagram. Refer to the DC Characteristics table for the active current specification on reading array data.

Page Mode Read

The device is capable of fast page mode read and is compatible with the page mode Mask ROM read operation. This mode provides faster read access speed for random locations within a page. The page size of the device is 8 words/16 bytes. The appropriate page is selected by the higher address bits A(max)–A3. Address bits A2–A0 determine the specific word within a page. This is an asynchronous operation; the microprocessor supplies the specific word location.

The random or initial page access is equal to t_{ACC} or t_{CE} and subsequent page read accesses (as long as the locations specified by the microprocessor falls within that page) is equivalent to t_{PACC} . When CE# is de-asserted and reasserted for a subsequent access, the access time is t_{ACC} or t_{CE} . Fast page mode accesses are obtained by keeping the "read-page addresses" constant and changing the "intra-read page" addresses.

Writing Commands/Command Sequences

To write a command or command sequence (which includes programming data to the device and erasing sectors of memory), the system must drive WE# and CE# to V_{IL}, and OE# to V_{IH}.

The device features an **Unlock Bypass** mode to facilitate faster programming. Once the device enters the Unlock Bypass mode, only two write cycles are required to program a word or byte, instead of four. The "Word Program Command Sequence" section has details on programming data to the device using both standard and Unlock Bypass command sequences.

An erase operation can erase one sector, multiple sectors, or the entire device. Table 2, Table 4, and Table 5 indicate the address space that each sector occupies.

Refer to the DC Characteristics table for the active current specification for the write mode. The AC Characteristics section contains timing specification tables and timing diagrams for write operations.

Write Buffer

Write Buffer Programming allows the system write to a maximum of 16 words/32 bytes in one programming operation. This results in faster effective programming time than the standard programming algorithms. See "Write Buffer" for more information.

Accelerated Program Operation

The device offers accelerated program operations through the ACC function. This is one of two functions provided by the WP#/ACC pin. This function is primarily intended to allow faster manufacturing throughput at the factory.



If the system asserts V_{HH} on this pin, the device automatically enters the aforementioned Unlock Bypass mode, temporarily unprotects any protected sector groups, and uses the higher voltage on the pin to reduce the time required for program operations. The system would use a two-cycle program command sequence as required by the Unlock Bypass mode. Removing V_{HH} from the WP#/ ACC pin returns the device to normal operation. Note that the WP#/ACC pin must not be at V_{HH} for operations other than accelerated programming, or device damage may result. WP# has an internal pullup; when unconnected, WP# is at V_{IH} .

Autoselect Functions

If the system writes the autoselect command sequence, the device enters the autoselect mode. The system can then read autoselect codes from the internal register (which is separate from the memory array) on DQ7–DQ0. Standard read cycle timings apply in this mode. Refer to the "Autoselect Mode" section on page 53 and "Autoselect Command Sequence" section on page 67 sections for more information.

Standby Mode

When the system is not reading or writing to the device, it can place the device in the standby mode. In this mode, current consumption is greatly reduced, and the outputs are placed in the high impedance state, independent of the OE# input.

The device enters the CMOS standby mode when the CE# and RESET# pins are both held at V_{IO} ± 0.3 V. (Note that this is a more restricted voltage range than V_{IH}.) If CE# and RESET# are held at V_{IH}, but not within V_{IO} ± 0.3 V, the device will be in the standby mode, but the standby current will be greater. The device requires standard access time (t_{CE}) for read access when the device is in either of these standby modes, before it is ready to read data.

If the device is deselected during erasure or programming, the device draws active current until the operation is completed.

Refer to the "DC Characteristics" section on page 91 for the standby current specification.

Automatic Sleep Mode

The automatic sleep mode minimizes Flash device energy consumption. The device automatically enables this mode when addresses remain stable for t_{ACC} + 30 ns. The automatic sleep mode is independent of the CE#, WE#, and OE# control signals. Standard address access timings provide new data when addresses are changed. While in sleep mode, output data is latched and always available to the system. Refer to the "DC Characteristics" section on page 91 for the automatic sleep mode current specification.

RESET#: Hardware Reset Pin

The RESET# pin provides a hardware method of resetting the device to reading array data. When the RESET# pin is driven low for at least a period of t_{RP} , the device immediately terminates any operation in progress, tristates all output pins, and ignores all read/write commands for the duration of the RESET# pulse. The device also resets the internal state machine to reading array data. The operation that was interrupted should be reinitiated once the device is ready to accept another command sequence, to ensure data integrity.



Current is reduced for the duration of the RESET# pulse. When RESET# is held at V_{SS}±0.3 V, the device draws CMOS standby current (I_{CC5}). If RESET# is held at V_{IL} but not within V_{SS}±0.3 V, the standby current will be greater.

The RESET# pin may be tied to the system reset circuitry. A system reset would thus also reset the Flash memory, enabling the system to read the boot-up firmware from the Flash memory.

Refer to the AC Characteristics tables for RESET# parameters and to Figure 13 for the timing diagram.

Output Disable Mode

When the OE# input is at $V_{IH^{\prime}}$ output from the device is disabled. The output pins are placed in the high impedance state.

| Sector | | - | | A | 24-A 1 | 16 | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | | |
|--------|---|---|---|---|---------------|----|------------------------------------|-----------------------------------|---|--------|-----------------|
| SA0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0000000-000FFFF |
| SA1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0010000-001FFFF |
| SA2 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0020000-002FFFF |
| SA3 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0030000-003FFFF |
| SA4 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0040000-004FFFF |
| SA5 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0050000-005FFFF |
| SA6 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0060000-006FFFF |
| SA7 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0070000-007FFFF |
| SA8 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0080000-008FFFF |
| SA9 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0090000-009FFFF |
| SA10 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 00A0000-00AFFFF |
| SA11 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 00B0000-00BFFFF |
| SA12 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 00C0000-00CFFFF |
| SA13 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 00D0000-00DFFFF |
| SA14 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 00E0000-00EFFFF |
| SA15 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 00F0000-00FFFFF |
| SA16 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0100000-010FFFF |
| SA17 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0110000-011FFFF |
| SA18 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0120000-012FFFF |
| SA19 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0130000-013FFFF |
| SA20 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0140000-014FFFF |
| SA21 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0150000-015FFFF |
| SA22 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0160000-016FFFF |
| SA23 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0170000-017FFFF |

Table 2. Sector Address Table-S29GL5I2N



T

| Sector | | | | A | 24-A1 | 16 | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | | |
|--------|---|---|---|---|-------|----|------------------------------------|-----------------------------------|---|--------|-----------------|
| SA24 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0180000-018FFFF |
| SA25 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0190000-019FFFF |
| SA26 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 01A0000-01AFFFF |
| SA27 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 01B0000-01BFFFF |
| SA28 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 01C0000-01CFFFF |
| SA29 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 01D0000-01DFFFF |
| SA30 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 01E0000-01EFFFF |
| SA31 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 01F0000-01FFFFF |
| SA32 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0200000-020FFFF |
| SA33 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0210000-021FFFF |
| SA34 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0220000-022FFFF |
| SA35 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0230000-023FFFF |
| SA36 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0240000-024FFFF |
| SA37 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0250000-025FFFF |
| SA38 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0260000-026FFFF |
| SA39 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0270000-027FFFF |
| SA40 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0280000-028FFFF |
| SA41 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0290000-029FFFF |
| SA42 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 02A0000-02AFFFF |
| SA43 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 02B0000-02BFFFF |
| SA44 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 02C0000-02CFFFF |
| SA45 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 02D0000-02DFFFF |
| SA46 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 02E0000-02EFFFF |
| SA47 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 02F0000-02FFFFF |
| SA48 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0300000-030FFFF |
| SA49 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0310000-031FFFF |
| SA50 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0320000-032FFFF |
| SA51 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0330000-033FFFF |
| SA52 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0340000-034FFFF |
| SA53 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0350000-035FFFF |
| SA54 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0360000-036FFFF |
| SA55 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0370000-037FFFF |
| SA56 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0380000-038FFFF |
| SA57 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0390000-039FFFF |

Table 2. Sector Address Table-S29GL5I2N (Continued)

128/64

03A0000-03AFFFF

SA58



Table 2. Sector Address Table–S29GL5I2N (Continued)

| Sector | | | | A | 24-A1 | 16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA59 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 03B0000-03BFFFF |
| SA60 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 03C0000-03CFFFF |
| SA61 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 03D0000-03DFFFF |
| SA62 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 03E0000-03EFFFF |
| SA63 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 03F0000-03FFFFF |
| SA64 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0400000-040FFFF |
| SA65 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0410000-041FFFF |
| SA66 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0420000-042FFFF |
| SA67 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0430000-043FFFF |
| SA68 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0440000-044FFFF |
| SA69 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0450000-045FFFF |
| SA70 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0460000-046FFFF |
| SA71 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0470000-047FFFF |
| SA72 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0480000-048FFFF |
| SA73 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0490000-049FFFF |
| SA74 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 04A0000-04AFFFF |
| SA75 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 04B0000-04BFFFF |
| SA76 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 04C0000-04CFFFF |
| SA77 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 04D0000-04DFFFF |
| SA78 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 04E0000-04EFFFF |
| SA79 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 04F0000-04FFFFF |
| SA80 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0500000-050FFFF |
| SA81 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0510000-051FFFF |
| SA82 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0520000-052FFFF |
| SA83 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0530000-053FFFF |
| SA84 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0540000-054FFFF |
| SA85 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0550000-055FFFF |
| SA86 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0560000-056FFFF |
| SA87 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0570000-057FFFF |
| SA88 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0580000-058FFFF |
| SA89 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0590000-059FFFF |
| SA90 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 05A0000-05AFFFF |
| SA91 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 05B0000-05BFFFF |
| SA92 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 05C0000-05CFFFF |
| SA93 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 05D0000-05DFFFF |



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| Sect | or | | | | A | 24-A1 | L6 | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | | |
|------------------|----|---|---|---|---|-------|----|------------------------------------|-----------------------------------|---|--------|-----------------|
| SA9 | 4 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 05E0000-05EFFFF |
| SA9 | 5 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 05F0000-05FFFFF |
| SA9 | 6 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0600000-060FFFF |
| SA9 | 7 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0610000-061FFFF |
| SA9 | 8 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0620000-062FFFF |
| SA9 | 9 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0630000-063FFFF |
| SA10 | 00 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0640000-064FFFF |
| SA10 | D1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0650000-065FFFF |
| SA10 | 02 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0660000-066FFFF |
| SA10 | 03 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0670000-067FFFF |
| SA10 | D4 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0680000-068FFFF |
| SA10 | 05 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0690000-069FFFF |
| SA10 | 06 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 06A0000-06AFFFF |
| SA10 | 07 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 06B0000-06BFFFF |
| SA10 | 28 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 06C0000-06CFFFF |
| SA10 | 09 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 06D0000-06DFFFF |
| SA1 ² | 10 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 06E0000-06EFFFF |
| SA1 ² | 11 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 06F0000-06FFFFF |
| SA1 | 12 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0700000-070FFFF |
| SA11 | 13 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0710000-071FFFF |
| SA1 | 14 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0720000-072FFFF |
| SA11 | 15 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0730000-073FFFF |
| SA1 | 16 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0740000-074FFFF |
| SA11 | 17 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0750000-075FFFF |
| SA1 | 18 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0760000-076FFFF |
| SA1 | 19 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0770000-077FFFF |
| SA12 | 20 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0780000-078FFFF |
| SA12 | 21 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0790000-079FFFF |
| SA12 | 22 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 07A0000-07AFFFF |
| SA12 | 23 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 07B0000-07BFFFF |
| SA12 | 24 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 07C0000-07CFFFF |
| SA12 | 25 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 07D0000-07DFFFF |
| SA12 | 26 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 07E0000-07EFFFF |
| SA12 | 27 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 07F0000-07FFFFF |

Table 2. Sector Address Table-S29GL5I2N (Continued)

128/64

0800000-080FFFF

SA128



Table 2. Sector Address Table–S29GL5I2N (Continued)

| Sector | | | | A | 24-A1 | 16 | · | - | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA129 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0810000-081FFFF |
| SA130 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0820000-082FFFF |
| SA131 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0830000-083FFFF |
| SA132 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0840000-084FFFF |
| SA133 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0850000-085FFFF |
| SA134 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0860000-086FFFF |
| SA135 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0870000-087FFFF |
| SA136 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0880000-088FFFF |
| SA137 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0890000-089FFFF |
| SA138 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 08A0000-08AFFFF |
| SA139 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 08B0000-08BFFFF |
| SA140 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 08C0000-08CFFFF |
| SA141 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 08D0000-08DFFFF |
| SA142 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 08E0000-08EFFFF |
| SA143 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 08F0000-08FFFFF |
| SA144 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0900000-090FFFF |
| SA145 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0910000-091FFFF |
| SA146 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0920000-092FFFF |
| SA147 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0930000-093FFFF |
| SA148 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0940000-094FFFF |
| SA149 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0950000-095FFFF |
| SA150 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0960000-096FFFF |
| SA151 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0970000-097FFFF |
| SA152 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0980000-098FFFF |
| SA153 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0990000-099FFFF |
| SA154 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 09A0000-09AFFFF |
| SA155 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 09B0000-09BFFFF |
| SA156 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 09C0000-09CFFFF |
| SA157 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 09D0000-09DFFFF |
| SA158 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 09E0000-09EFFFF |
| SA159 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 09F0000-09FFFFF |
| SA160 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0A00000-0A0FFFF |
| SA161 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0A10000-0A1FFFF |
| SA162 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0A20000-0A2FFFF |
| SA163 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0A30000-0A3FFFF |



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| Sector | | | | A | 24-A: | L6 | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | | |
|--------|---|---|---|---|-------|----|------------------------------------|-----------------------------------|---|--------|-----------------|
| SA164 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0A40000-0A4FFFF |
| SA165 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0A50000-0A5FFFF |
| SA166 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0A60000-0A6FFFF |
| SA167 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0A70000-0A7FFFF |
| SA168 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0A80000-0A8FFFF |
| SA169 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0A90000-0A9FFFF |
| SA170 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 0AA0000-0AAFFFF |
| SA171 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 0AB0000-0ABFFFF |
| SA172 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 0AC0000-0ACFFFF |
| SA173 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 0AD0000–0ADFFFF |
| SA174 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 0AE0000-0AEFFFF |
| SA175 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 0AF0000-0AFFFFF |
| SA176 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0B00000-0B0FFFF |
| SA177 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0B10000-0B1FFFF |
| SA178 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0B20000-0B2FFFF |
| SA179 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0B30000-0B3FFFF |
| SA180 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0B40000-0B4FFFF |
| SA181 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0B50000-0B5FFFF |
| SA182 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0B60000-0B6FFFF |
| SA183 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0B70000-0B7FFFF |
| SA184 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0B80000-0B8FFFF |
| SA185 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0B90000-0B9FFFF |
| SA186 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 0BA0000-0BAFFFF |
| SA187 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 0BB0000-0BBFFFF |
| SA188 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 0BC0000-0BCFFFF |
| SA189 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 0BD0000-0BDFFFF |
| SA190 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | OBE0000-OBEFFFF |
| SA191 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 0BF0000-0BFFFFF |
| SA192 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0C00000-0C0FFFF |
| SA193 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0C10000-0C1FFFF |
| SA194 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0C20000-0C2FFFF |
| SA195 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0C30000-0C3FFFF |
| SA196 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0C40000-0C4FFFF |
| SA197 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0C50000-0C5FFFF |

Table 2. Sector Address Table–S29GL5I2N (Continued)

128/64

0C60000-0C6FFFF

SA198

0

1

1

0

0

0

1

1

0



| Sector | | | | A | 24-A1 | L6 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA199 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0C70000-0C7FFFF |
| SA200 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0C80000-0C8FFFF |
| SA201 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0C90000-0C9FFFF |
| SA202 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 0CA0000-0CAFFFF |
| SA203 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | OCB0000-OCBFFFF |
| SA204 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 0CC0000-0CCFFFF |
| SA205 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 0CD0000-0CDFFFF |
| SA206 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | OCE0000-OCEFFFF |
| SA207 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | OCF0000-0CFFFFF |
| SA208 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0D00000-0D0FFFF |
| SA209 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0D10000-0D1FFFF |
| SA210 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0D20000-0D2FFFF |
| SA211 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0D30000-0D3FFFF |
| SA212 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0D40000-0D4FFFF |
| SA213 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0D50000-0D5FFFF |
| SA214 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0D60000-0D6FFFF |
| SA215 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0D70000-0D7FFFF |
| SA216 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0D80000-0D8FFFF |
| SA217 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0D90000-0D9FFFF |
| SA218 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 0DA0000-0DAFFFF |
| SA219 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 0DB0000-0DBFFFF |
| SA220 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 0DC0000-0DCFFFF |
| SA221 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 0DD0000-0DDFFFF |
| SA222 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 0DE0000-0DEFFFF |
| SA223 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 0DF0000-0DFFFFF |
| SA224 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | OEOOOOO-OEOFFFF |
| SA225 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | OE10000-OE1FFFF |
| SA226 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0E20000-0E2FFFF |
| SA227 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0E30000-0E3FFFF |
| SA228 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0E40000-0E4FFFF |
| SA229 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0E50000-0E5FFFF |
| SA230 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0E60000-0E6FFFF |
| SA231 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0E70000-0E7FFF |
| SA232 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0E80000-0E8FFFF |
| SA233 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0E90000-0E9FFFF |



| Sector | | | | A | 24-A1 | 16 | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | | |
|--------|---|---|---|---|-------|----|------------------------------------|-----------------------------------|---|--------|-----------------|
| SA234 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 0EA0000-0EAFFFF |
| SA235 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 0EB0000-0EBFFFF |
| SA236 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 0EC0000-0ECFFFF |
| SA237 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 0ED0000-0EDFFFF |
| SA238 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | OEE0000-OEEFFFF |
| SA239 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 0EF0000-0EFFFFF |
| SA240 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | OF00000-OF0FFFF |
| SA241 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | OF10000-OF1FFFF |
| SA242 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0F20000-0F2FFFF |
| SA243 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | OF30000-OF3FFFF |
| SA244 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | OF40000-OF4FFFF |
| SA245 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | OF50000-OF5FFFF |
| SA246 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0F60000-0F6FFFF |
| SA247 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | OF70000-OF7FFFF |
| SA248 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0F80000-0F8FFFF |
| SA249 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0F90000-0F9FFFF |
| SA250 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | OFA0000-OFAFFFF |
| SA251 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | OFB0000-OFBFFFF |
| SA252 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | OFC0000-OFCFFFF |
| SA253 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 0FD0000–0FDFFFF |
| SA254 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | OFE0000-OFEFFFF |
| SA255 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | OFF0000-OFFFFFF |
| SA256 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1000000-100FFFF |
| SA257 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1010000-101FFFF |
| SA258 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1020000-102FFFF |
| SA259 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1030000-103FFFF |
| SA260 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1040000-104FFFF |
| SA261 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1050000-105FFFF |
| SA262 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1060000-106FFFF |
| SA263 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1070000-107FFFF |
| SA264 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1080000-108FFFF |
| SA265 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1090000-109FFFF |
| SA266 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 10A0000-10AFFFF |
| SA267 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 10B0000-10BFFFF |

Table 2. Sector Address Table–S29GL5I2N (Continued)

128/64

10C0000-10CFFFF

SA268

1

0

0

0

0

1

1

0

0



Table 2. Sector Address Table–S29GL5I2N (Continued)

| Sector | | | | A | 24-A1 | 16 | | _ | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA269 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 10D0000-10DFFFF |
| SA270 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 10E0000-10EFFFF |
| SA271 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 10F0000-10FFFFF |
| SA272 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1100000-110FFFF |
| SA273 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1110000-111FFFF |
| SA274 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 1120000-112FFFF |
| SA275 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1130000-113FFFF |
| SA276 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1140000-114FFFF |
| SA277 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1150000-115FFFF |
| SA278 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1160000-116FFFF |
| SA279 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1170000-117FFFF |
| SA280 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 1180000-118FFFF |
| SA281 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1190000-119FFFF |
| SA282 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 11A0000-11AFFFF |
| SA283 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 11B0000-11BFFFF |
| SA284 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 11C0000-11CFFFF |
| SA285 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 11D0000-11DFFFF |
| SA286 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 11E0000-11EFFFF |
| SA287 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 11F0000-11FFFFF |
| SA288 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1200000-120FFFF |
| SA289 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1210000-121FFFF |
| SA290 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1220000-122FFFF |
| SA291 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1230000-123FFFF |
| SA292 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1240000-124FFFF |
| SA293 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1250000-125FFFF |
| SA294 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1260000-126FFFF |
| SA295 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1270000-127FFFF |
| SA296 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1280000-128FFFF |
| SA297 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1290000-129FFFF |
| SA298 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 12A0000-12AFFFF |
| SA299 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 12B0000-12BFFFF |
| SA300 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 12C0000-12CFFFF |
| SA301 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 12D0000-12DFFFF |
| SA302 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 12E0000-12EFFFF |
| SA303 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 12F0000-12FFFFF |



| Sector | | | | A | 24-A1 | L6 | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | | |
|--------|---|---|---|---|-------|----|------------------------------------|-----------------------------------|---|--------|-----------------|
| SA304 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1300000-130FFFF |
| SA305 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1310000–131FFFF |
| SA306 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 1320000–132FFFF |
| SA307 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1330000-133FFFF |
| SA308 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1340000–134FFFF |
| SA309 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1350000-135FFFF |
| SA310 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1360000-136FFFF |
| SA311 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1370000–137FFFF |
| SA312 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 1380000–138FFFF |
| SA313 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1390000-139FFFF |
| SA314 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 13A0000–13AFFFF |
| SA315 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 13B0000-13BFFFF |
| SA316 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 13C0000-13CFFFF |
| SA317 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 13D0000–13DFFFF |
| SA318 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 13E0000-13EFFFF |
| SA319 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 13F0000-13FFFFF |
| SA320 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1400000-140FFFF |
| SA321 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1410000-141FFFF |
| SA322 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1420000-142FFFF |
| SA323 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1430000-143FFFF |
| SA324 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1440000-144FFFF |
| SA325 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1450000-145FFFF |
| SA326 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1460000-146FFFF |
| SA327 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1470000-147FFFF |
| SA328 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1480000-148FFFF |
| SA329 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1490000-149FFFF |
| SA330 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 14A0000-14AFFFF |
| SA331 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 14B0000-14BFFFF |
| SA332 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 14C0000-14CFFFF |
| SA333 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 14D0000-14DFFFF |
| SA334 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 14E0000-14EFFFF |
| SA335 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 14F0000-14FFFFF |
| SA336 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1500000-150FFFF |
| SA337 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1510000-151FFFF |
| | | | | | | | | | | | |

Table 2. Sector Address Table–S29GL5I2N (Continued)

128/64

1520000-152FFFF

SA338

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Table 2. Sector Address Table–S29GL5I2N (Continued)

| Sector | | | | A | 24-A1 | L6 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA339 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1530000-153FFFF |
| SA340 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1540000-154FFFF |
| SA341 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1550000-155FFFF |
| SA342 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1560000-156FFFF |
| SA343 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1570000-157FFFF |
| SA344 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 1580000–158FFFF |
| SA345 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1590000-159FFFF |
| SA346 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 15A0000–15AFFFF |
| SA347 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 15B0000-15BFFFF |
| SA348 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 15C0000-15CFFFF |
| SA349 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 15D0000–15DFFFF |
| SA350 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 15E0000-15EFFFF |
| SA351 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 15F0000-15FFFFF |
| SA352 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1600000-160FFFF |
| SA353 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1610000–161FFFF |
| SA354 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1620000-162FFFF |
| SA355 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1630000–163FFFF |
| SA356 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1640000–164FFFF |
| SA357 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1650000–165FFFF |
| SA358 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1660000–166FFFF |
| SA359 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1670000–167FFFF |
| SA360 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1680000–168FFFF |
| SA361 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1690000–169FFFF |
| SA362 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 16A0000–16AFFFF |
| SA363 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 16B0000-16BFFFF |
| SA364 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 16C0000-16CFFFF |
| SA365 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 16D0000–16DFFFF |
| SA366 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 16E0000-16EFFFF |
| SA367 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 16F0000-16FFFFF |
| SA368 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1700000-170FFFF |
| SA369 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1710000–171FFFF |
| SA370 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 1720000–172FFFF |
| SA371 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1730000–173FFFF |
| SA372 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1740000-174FFFF |
| SA373 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1750000–175FFFF |



| Sector | | | | A | 24-A1 | L6 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA374 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1760000-176FFFF |
| SA375 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1770000-177FFFF |
| SA376 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 1780000–178FFFF |
| SA377 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1790000-179FFFF |
| SA378 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 17A0000–17AFFFF |
| SA379 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 17B0000–17BFFFF |
| SA380 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 17C0000-17CFFFF |
| SA381 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 17D0000–17DFFFF |
| SA382 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 17E0000-17EFFFF |
| SA383 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 17F0000-17FFFFF |
| SA384 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1800000-180FFFF |
| SA385 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1810000–181FFFF |
| SA386 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1820000–182FFFF |
| SA387 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1830000–183FFFF |
| SA388 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1840000–184FFFF |
| SA389 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1850000–185FFFF |
| SA390 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1860000–186FFFF |
| SA391 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1870000–187FFFF |
| SA392 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1880000–188FFFF |
| SA393 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1890000–189FFFF |
| SA394 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 18A0000–18AFFFF |
| SA395 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 18B0000-18BFFFF |
| SA396 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 18C0000-18CFFFF |
| SA397 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 18D0000-18DFFFF |
| SA398 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 18E0000-18EFFFF |
| SA399 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 18F0000-18FFFFF |
| SA400 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1900000–190FFFF |
| SA401 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1910000–191FFFF |
| SA402 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 1920000–192FFFF |
| SA403 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1930000–193FFFF |
| SA404 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1940000–194FFFF |
| SA405 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1950000–195FFFF |
| SA406 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1960000-196FFFF |
| SA407 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1970000–197FFFF |

Table 2. Sector Address Table–S29GL5I2N (Continued)

128/64

1980000-198FFFF

SA408

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Table 2. Sector Address Table–S29GL5I2N (Continued)

| Sector | | - | | A | 24-A1 | 16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA409 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1990000-199FFFF |
| SA410 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 19A0000–19AFFFF |
| SA411 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 19B0000-19BFFFF |
| SA412 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 19C0000-19CFFFF |
| SA413 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 19D0000-19DFFFF |
| SA414 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 19E0000-19EFFFF |
| SA415 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 19F0000-19FFFFF |
| SA416 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1A00000-1A0FFFF |
| SA417 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1A10000-1A1FFFF |
| SA418 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1A20000-1A2FFFF |
| SA419 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1A30000–1A3FFFF |
| SA420 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1A40000-1A4FFFF |
| SA421 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1A50000-1A5FFFF |
| SA422 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1A60000-1A6FFFF |
| SA423 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1A70000-1A7FFFF |
| SA424 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1A80000-1A8FFFF |
| SA425 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1A90000-1A9FFFF |
| SA426 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 1AA0000–1AAFFFF |
| SA427 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 1AB0000–1ABFFFF |
| SA428 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 1AC0000-1ACFFFF |
| SA429 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 1AD0000–1ADFFFF |
| SA430 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 1AE0000–1AEFFFF |
| SA431 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 1AF0000–1AFFFFF |
| SA432 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1B00000-1B0FFFF |
| SA433 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1B10000-1B1FFFF |
| SA434 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 1B20000-1B2FFFF |
| SA435 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1B30000-1B3FFFF |
| SA436 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1B40000-1B4FFFF |
| SA437 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1B50000-1B5FFFF |
| SA438 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1B60000-1B6FFFF |
| SA439 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1B70000–1B7FFFF |
| SA440 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 1B80000–1B8FFFF |
| SA441 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1B90000–1B9FFFF |
| SA442 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 1BA0000–1BAFFFF |
| SA443 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 1BB0000–1BBFFFF |



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| Sector | | | | A | 24-A1 | 16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA444 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 1BC0000-1BCFFFF |
| SA445 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 1BD0000–1BDFFFF |
| SA446 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 1BE0000–1BEFFFF |
| SA447 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 1BF0000–1BFFFFF |
| SA448 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1C00000-1C0FFFF |
| SA449 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1C10000-1C1FFFF |
| SA450 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1C20000-1C2FFFF |
| SA451 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1C30000-1C3FFFF |
| SA452 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1C40000-1C4FFFF |
| SA453 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1C50000-1C5FFFF |
| SA454 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1C60000-1C6FFFF |
| SA455 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1C70000-1C7FFFF |
| SA456 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1C80000-1C8FFFF |
| SA457 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1C90000-1C9FFFF |
| SA458 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 1CA0000-1CAFFFF |
| SA459 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 1CB0000-1CBFFFF |
| SA460 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 1CC0000-1CCFFFF |
| SA461 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 1CD0000-1CDFFFF |
| SA462 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 1CE0000-1CEFFFF |
| SA463 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 1CF0000-1CFFFFF |
| SA464 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1D00000-1D0FFFF |
| SA465 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1D10000-1D1FFFF |
| SA466 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 1D20000-1D2FFFF |
| SA467 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1D30000-1D3FFFF |
| SA468 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1D40000-1D4FFFF |
| SA469 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1D50000-1D5FFFF |
| SA470 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1D60000-1D6FFFF |
| SA471 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1D70000-1D7FFFF |
| SA472 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 1D80000-1D8FFFF |
| SA473 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1D90000-1D9FFFF |
| SA474 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 1DA0000–1DAFFFF |
| SA475 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 1DB0000-1DBFFFF |
| SA476 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 1DC0000-1DCFFFF |
| SA477 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 1DD0000-1DDFFFF |

Table 2. Sector Address Table–S29GL5I2N (Continued)

128/64

1DE0000-1DEFFFF

SA478

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| Table 2. | Sector Address | Table-S29GL5I2N | (Continued) |
|----------|----------------|-----------------|-------------|
|----------|----------------|-----------------|-------------|

| Sector | | | | A | 24-A1 | 16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|---|-------|----|---|---|---|------------------------------------|-----------------------------------|
| SA479 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 1DF0000–1DFFFFF |
| SA480 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 1E00000-1E0FFFF |
| SA481 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 1E10000-1E1FFFF |
| SA482 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 1E20000-1E2FFFF |
| SA483 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 1E30000-1E3FFFF |
| SA484 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 1E40000-1E4FFFF |
| SA485 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 1E50000-1E5FFFF |
| SA486 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 1E60000-1E6FFFF |
| SA487 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 1E70000-1E7FFFF |
| SA488 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 1E80000-1E8FFFF |
| SA489 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 1E90000-1E9FFFF |
| SA490 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 1EA0000–1EAFFFF |
| SA491 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 1EB0000-1EBFFFF |
| SA492 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 1EC0000-1ECFFFF |
| SA493 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 1ED0000–1EDFFFF |
| SA494 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 1EE0000-1EEFFFF |
| SA495 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 1EF0000-1EFFFFF |
| SA496 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 1F00000-1F0FFFF |
| SA497 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 1F10000-1F1FFFF |
| SA498 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 1F20000-1F2FFFF |
| SA499 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 1F30000-1F3FFFF |
| SA500 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 1F40000–1F4FFFF |
| SA501 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 1F50000-1F5FFFF |
| SA502 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 1F60000-1F6FFFF |
| SA503 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 1F70000-1F7FFFF |
| SA504 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 1F80000-1F8FFFF |
| SA505 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 1F90000-1F9FFFF |
| SA506 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 1FA0000–1FAFFFF |
| SA507 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 1FB0000–1FBFFFF |
| SA508 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 1FC0000–1FCFFFF |
| SA509 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 1FD0000–1FDFFFF |
| SA510 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 1FE0000–1FEFFFF |
| SA511 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 1FF0000–1FFFFFF |



Table 3. Sector Address Table-S29GL256N

| Sector | | | | A23- | -A16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|------|------|---|---|---|------------------------------------|-----------------------------------|
| SAO | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0000000-000FFFF |
| SA1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0010000-001FFFF |
| SA2 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0020000-002FFFF |
| SA3 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0030000-003FFFF |
| SA4 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0040000-004FFFF |
| SA5 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0050000-005FFFF |
| SA6 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0060000-006FFFF |
| SA7 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0070000-007FFFF |
| SA8 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0080000-008FFFF |
| SA9 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0090000-009FFFF |
| SA10 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 00A0000-00AFFFF |
| SA11 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 00B0000-00BFFFF |
| SA12 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 00C0000-00CFFFF |
| SA13 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 00D0000-00DFFFF |
| SA14 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 00E0000-00EFFFF |
| SA15 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 00F0000-00FFFFF |
| SA16 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0100000-010FFFF |
| SA17 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0110000-011FFFF |
| SA18 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0120000-012FFFF |
| SA19 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0130000-013FFFF |
| SA20 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0140000-014FFFF |
| SA21 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0150000-015FFFF |
| SA22 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0160000-016FFFF |
| SA23 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0170000-017FFFF |
| SA24 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0180000-018FFFF |
| SA25 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0190000-019FFFF |
| SA26 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 01A0000-01AFFFF |
| SA27 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 01B0000-01BFFFF |
| SA28 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 01C0000-01CFFFF |
| SA29 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 01D0000-01DFFFF |
| SA30 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 01E0000-01EFFFF |
| SA31 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 01F0000–01FFFFF |
| SA32 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0200000-020FFFF |
| SA33 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0210000-021FFFF |



Table 3. Sector Address Table-S29GL256N (Continued)

| Sector | | | | A23- | -A16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|------|------|---|---|---|------------------------------------|-----------------------------------|
| SA34 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0220000-022FFFF |
| SA35 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0230000-023FFFF |
| SA36 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0240000-024FFFF |
| SA37 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0250000-025FFFF |
| SA38 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0260000-026FFFF |
| SA39 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0270000-027FFFF |
| SA40 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0280000-028FFFF |
| SA41 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0290000-029FFFF |
| SA42 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 02A0000-02AFFFF |
| SA43 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 02B0000-02BFFFF |
| SA44 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 02C0000-02CFFFF |
| SA45 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 02D0000-02DFFFF |
| SA46 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 02E0000-02EFFFF |
| SA47 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 02F0000-02FFFFF |
| SA48 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0300000-030FFFF |
| SA49 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0310000-031FFFF |
| SA50 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0320000-032FFFF |
| SA51 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0330000-033FFFF |
| SA52 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0340000-034FFFF |
| SA53 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0350000-035FFFF |
| SA54 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0360000-036FFFF |
| SA55 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0370000-037FFFF |
| SA56 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0380000-038FFFF |
| SA57 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0390000-039FFFF |
| SA58 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 03A0000-03AFFFF |
| SA59 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 03B0000-03BFFFF |
| SA60 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 03C0000-03CFFFF |
| SA61 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 03D0000-03DFFFF |
| SA62 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 03E0000–03EFFFF |
| SA63 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 03F0000–03FFFFF |
| SA64 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0400000-040FFFF |
| SA65 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0410000-041FFFF |
| SA66 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0420000-042FFFF |
| SA67 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0430000-043FFFF |
| SA68 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0440000-044FFFF |



Table 3. Sector Address Table-S29GL256N (Continued)

| Sector | | | | A23- | -A16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|------|------|---|---|---|------------------------------------|-----------------------------------|
| SA69 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0450000-045FFFF |
| SA70 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0460000-046FFFF |
| SA71 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0470000-047FFFF |
| SA72 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0480000-048FFFF |
| SA73 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0490000-049FFFF |
| SA74 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 04A0000-04AFFFF |
| SA75 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 04B0000-04BFFFF |
| SA76 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 04C0000-04CFFFF |
| SA77 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 04D0000-04DFFFF |
| SA78 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 04E0000-04EFFFF |
| SA79 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 04F0000-04FFFFF |
| SA80 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0500000-050FFFF |
| SA81 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0510000-051FFFF |
| SA82 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0520000-052FFFF |
| SA83 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0530000-053FFFF |
| SA84 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0540000-054FFFF |
| SA85 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0550000-055FFFF |
| SA86 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0560000-056FFFF |
| SA87 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0570000-057FFFF |
| SA88 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0580000-058FFFF |
| SA89 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0590000-059FFFF |
| SA90 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 05A0000-05AFFFF |
| SA91 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 05B0000-05BFFFF |
| SA92 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 05C0000-05CFFFF |
| SA93 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 05D0000-05DFFFF |
| SA94 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 05E0000-05EFFFF |
| SA95 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 05F0000-05FFFFF |
| SA96 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0600000-060FFFF |
| SA97 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0610000-061FFFF |
| SA98 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0620000-062FFFF |
| SA99 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0630000-063FFFF |
| SA100 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0640000-064FFFF |
| SA101 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0650000-065FFFF |
| SA102 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0660000-066FFFF |
| SA103 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0670000-067FFFF |



Table 3. Sector Address Table-S29GL256N (Continued)

| Sector | | | | A23- | -A16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|------|------|---|---|---|------------------------------------|-----------------------------------|
| SA104 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0680000-068FFFF |
| SA105 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0690000-069FFFF |
| SA106 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 06A0000-06AFFFF |
| SA107 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 06B0000-06BFFFF |
| SA108 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 06C0000-06CFFFF |
| SA109 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 06D0000-06DFFFF |
| SA110 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 06E0000-06EFFFF |
| SA111 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 06F0000-06FFFFF |
| SA112 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0700000-070FFFF |
| SA113 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0710000-071FFFF |
| SA114 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0720000-072FFFF |
| SA115 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0730000-073FFFF |
| SA116 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0740000-074FFFF |
| SA117 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0750000-075FFFF |
| SA118 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0760000-076FFFF |
| SA119 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0770000-077FFFF |
| SA120 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0780000-078FFFF |
| SA121 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0790000-079FFFF |
| SA122 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 07A0000-07AFFFF |
| SA123 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 07B0000-07BFFFF |
| SA124 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 07C0000-07CFFFF |
| SA125 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 07D0000-07DFFFF |
| SA126 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 07E0000-07EFFFF |
| SA127 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 07F0000-07FFFFF |
| SA128 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0800000-080FFFF |
| SA129 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0810000-081FFFF |
| SA130 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0820000-082FFFF |
| SA131 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0830000-083FFFF |
| SA132 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0840000-084FFFF |
| SA133 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0850000-085FFFF |
| SA134 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0860000-086FFFF |
| SA135 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0870000-087FFFF |
| SA136 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0880000-088FFFF |
| SA137 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0890000-089FFFF |
| SA138 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 08A0000–08AFFFF |



Table 3. Sector Address Table-S29GL256N (Continued)

| Sector | | | | A23- | -A16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|---|------|------|---|---|---|------------------------------------|-----------------------------------|
| SA139 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 08B0000-08BFFFF |
| SA140 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 08C0000-08CFFFF |
| SA141 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 08D0000-08DFFFF |
| SA142 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 08E0000-08EFFFF |
| SA143 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 08F0000-08FFFFF |
| SA144 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0900000-090FFFF |
| SA145 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0910000-091FFFF |
| SA146 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0920000-092FFFF |
| SA147 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0930000-093FFFF |
| SA148 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0940000-094FFFF |
| SA149 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0950000-095FFFF |
| SA150 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0960000-096FFFF |
| SA151 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0970000-097FFFF |
| SA152 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0980000-098FFFF |
| SA153 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0990000-099FFFF |
| SA154 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 09A0000-09AFFFF |
| SA155 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 09B0000-09BFFFF |
| SA156 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 09C0000-09CFFFF |
| SA157 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 09D0000-09DFFFF |
| SA158 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 09E0000-09EFFFF |
| SA159 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 09F0000-09FFFFF |
| SA160 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0A00000-0A0FFFF |
| SA161 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0A10000-0A1FFFF |
| SA162 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0A20000-0A2FFFF |
| SA163 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0A30000-0A3FFFF |
| SA164 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0A40000-0A4FFFF |
| SA165 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0A50000-0A5FFFF |
| SA166 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0A60000-0A6FFFF |
| SA167 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0A70000-0A7FFFF |
| SA168 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0A80000-0A8FFFF |
| SA169 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0A90000-0A9FFFF |
| SA170 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 0AA0000-0AAFFFF |
| SA171 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 0AB0000-0ABFFFF |
| SA172 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 0AC0000-0ACFFFF |
| SA173 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 0AD0000-0ADFFFF |



Table 3. Sector Address Table-S29GL256N (Continued)

| | 1 | | | | | | | | | |
|--------|---|---|---|------|------|---|---|---|------------------------------------|-----------------------------------|
| Sector | | | | A23- | -A16 | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
| SA174 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | OAE0000-OAEFFFF |
| SA175 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | OAF0000-0AFFFFF |
| SA176 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0B00000-0B0FFFF |
| SA177 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0B10000-0B1FFFF |
| SA178 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0B20000-0B2FFFF |
| SA179 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0B30000-0B3FFFF |
| SA180 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0B40000-0B4FFFF |
| SA181 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0B50000-0B5FFFF |
| SA182 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0B60000-0B6FFFF |
| SA183 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0B70000-0B7FFFF |
| SA184 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0B80000-0B8FFFF |
| SA185 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0B90000-0B9FFFF |
| SA186 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 0BA0000-0BAFFFF |
| SA187 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 0BB0000-0BBFFFF |
| SA188 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 0BC0000-0BCFFFF |
| SA189 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 0BD0000–0BDFFFF |
| SA190 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | OBE0000-OBEFFFF |
| SA191 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | OBF0000-OBFFFFF |
| SA192 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0C00000-0C0FFFF |
| SA193 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0C10000-0C1FFFF |
| SA194 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0C20000-0C2FFFF |
| SA195 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0C30000-0C3FFFF |
| SA196 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0C40000-0C4FFFF |
| SA197 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0C50000-0C5FFFF |
| SA198 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0C60000-0C6FFFF |
| SA199 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0C70000-0C7FFFF |
| SA200 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0C80000-0C8FFFF |
| SA201 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0C90000-0C9FFFF |
| SA202 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | OCA0000-0CAFFFF |
| SA203 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | OCB0000-OCBFFFF |
| SA204 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | OCCOOOO-OCCFFFF |
| SA205 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 0CD0000-0CDFFFF |
| SA206 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | OCEO000-OCEFFFF |
| SA207 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | OCF0000-0CFFFFF |
| SA208 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0D00000-0D0FFFF |



Table 3. Sector Address Table-S29GL256N (Continued)

| Sector | | | | A23- | -A16 | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | |
|--------|---|---|---|------|------|---|------------------------------------|-----------------------------------|--------|-----------------|
| SA209 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0D10000-0D1FFFF |
| SA210 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0D20000-0D2FFFF |
| SA211 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0D30000-0D3FFFF |
| SA212 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0D40000-0D4FFFF |
| SA213 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0D50000-0D5FFFF |
| SA214 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0D60000-0D6FFFF |
| SA215 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0D70000-0D7FFFF |
| SA216 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0D80000-0D8FFFF |
| SA217 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0D90000-0D9FFFF |
| SA218 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 0DA0000-0DAFFFF |
| SA219 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 0DB0000-0DBFFFF |
| SA220 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 0DC0000-0DCFFFF |
| SA221 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 0DD0000-0DDFFFF |
| SA222 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 0DE0000-0DEFFFF |
| SA223 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 0DF0000-0DFFFFF |
| SA224 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0E00000-0E0FFFF |
| SA225 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0E10000-0E1FFFF |
| SA226 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0E20000-0E2FFFF |
| SA227 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0E30000-0E3FFFF |
| SA228 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0E40000-0E4FFFF |
| SA229 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0E50000-0E5FFFF |
| SA230 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0E60000-0E6FFFF |
| SA231 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0E70000-0E7FFFF |
| SA232 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0E80000-0E8FFFF |
| SA233 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0E90000-0E9FFFF |
| SA234 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 0EA0000-0EAFFFF |
| SA235 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 0EB0000-0EBFFFF |
| SA236 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 0EC0000-0ECFFFF |
| SA237 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 0ED0000-0EDFFFF |
| SA238 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 0EE0000-0EEFFFF |
| SA239 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 0EF0000-0EFFFFF |
| SA240 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | OF00000-OF0FFFF |
| SA241 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | OF10000-OF1FFFF |
| SA242 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0F20000-0F2FFFF |
| SA243 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | OF30000-OF3FFFF |



| Sector | | | | A23- | -A16 | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) | | |
|--------|---|---|---|------|------|---|------------------------------------|-----------------------------------|--------|-----------------|
| SA244 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | OF40000-OF4FFFF |
| SA245 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | OF50000-OF5FFFF |
| SA246 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0F60000–0F6FFFF |
| SA247 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | OF70000-OF7FFFF |
| SA248 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0F80000-0F8FFFF |
| SA249 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0F90000-0F9FFFF |
| SA250 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | OFA0000-OFAFFFF |
| SA251 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | OFB0000-OFBFFFF |
| SA252 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | OFC0000-OFCFFFF |
| SA253 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 0FD0000–0FDFFFF |
| SA254 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | OFE0000-OFEFFFF |
| SA255 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | OFF0000-OFFFFF |

Table 3. Sector Address Table-S29GL256N (Continued)

Table 4. Sector Address Table-S29GLI28N

| 1 | 1 | | | | | | | |
|--------|---|---|------|------|---|---|------------------------------------|-----------------------------------|
| Sector | | | A22- | -A16 | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
| SA0 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0000000-000FFFF |
| SA1 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0010000-001FFFF |
| SA2 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0020000-002FFFF |
| SA3 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0030000-003FFFF |
| SA4 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0040000-004FFFF |
| SA5 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0050000-005FFFF |
| SA6 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0060000-006FFFF |
| SA7 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0070000-007FFFF |
| SA8 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0080000-008FFFF |
| SA9 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0090000-009FFFF |
| SA10 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 00A0000-00AFFFF |
| SA11 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 00B0000-00BFFFF |
| SA12 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 00C0000-00CFFFF |
| SA13 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 00D0000-00DFFFF |
| SA14 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 00E0000-00EFFFF |
| SA15 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 00F0000-00FFFFF |
| SA16 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0100000-010FFFF |
| SA17 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0110000-011FFFF |



Table 4. Sector Address Table–S29GLI28N (Continued)

| Sector | | | A22- | -A16 | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|------|------|---|---|------------------------------------|-----------------------------------|
| SA18 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0120000-012FFFF |
| SA19 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0130000-013FFFF |
| SA20 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0140000-014FFFF |
| SA21 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0150000-015FFFF |
| SA22 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0160000-016FFFF |
| SA23 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0170000-017FFFF |
| SA24 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0180000-018FFFF |
| SA25 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0190000-019FFFF |
| SA26 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 01A0000-01AFFFF |
| SA27 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 01B0000-01BFFFF |
| SA28 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 01C0000-01CFFFF |
| SA29 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 01D0000-01DFFFF |
| SA30 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 01E0000-01EFFFF |
| SA31 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 01F0000-01FFFFF |
| SA32 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0200000-020FFFF |
| SA33 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0210000-021FFFF |
| SA34 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0220000-022FFFF |
| SA35 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0230000-023FFFF |
| SA36 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0240000-024FFFF |
| SA37 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0250000-025FFFF |
| SA38 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0260000-026FFFF |
| SA39 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0270000-027FFFF |
| SA40 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0280000-028FFFF |
| SA41 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0290000-029FFFF |
| SA42 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 02A0000-02AFFFF |
| SA43 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 02B0000-02BFFFF |
| SA44 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 02C0000-02CFFFF |
| SA45 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 02D0000-02DFFFF |
| SA46 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 02E0000-02EFFFF |
| SA47 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 02F0000-02FFFFF |
| SA48 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0300000-030FFFF |
| SA49 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0310000-031FFFF |
| SA50 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0320000-032FFFF |
| SA51 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0330000-033FFFF |
| SA52 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0340000-034FFFF |



Table 4. Sector Address Table–S29GLI28N (Continued)

| Sector | | | A22- | -A16 | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|------|------|---|---|------------------------------------|-----------------------------------|
| SA53 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0350000-035FFFF |
| SA54 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0360000-036FFFF |
| SA55 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0370000-037FFFF |
| SA56 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0380000-038FFFF |
| SA57 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0390000-039FFFF |
| SA58 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 03A0000-03AFFFF |
| SA59 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 03B0000-03BFFFF |
| SA60 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 03C0000-03CFFFF |
| SA61 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 03D0000-03DFFFF |
| SA62 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 03E0000-03EFFFF |
| SA63 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 03F0000-03FFFFF |
| SA64 | 0 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0400000-040FFFF |
| SA65 | 0 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0410000-041FFFF |
| SA66 | 0 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0420000-042FFFF |
| SA67 | 0 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0430000-043FFFF |
| SA68 | 0 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0440000-044FFFF |
| SA69 | 0 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0450000-045FFFF |
| SA70 | 0 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0460000-046FFFF |
| SA71 | 0 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0470000-047FFFF |
| SA72 | 0 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0480000-048FFFF |
| SA73 | 0 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0490000-049FFFF |
| SA74 | 0 | 0 | 1 | 0 | 1 | 0 | 128/64 | 04A0000-04AFFFF |
| SA75 | 0 | 0 | 1 | 0 | 1 | 1 | 128/64 | 04B0000-04BFFFF |
| SA76 | 0 | 0 | 1 | 1 | 0 | 0 | 128/64 | 04C0000-04CFFFF |
| SA77 | 0 | 0 | 1 | 1 | 0 | 1 | 128/64 | 04D0000-04DFFFF |
| SA78 | 0 | 0 | 1 | 1 | 1 | 0 | 128/64 | 04E0000-04EFFFF |
| SA79 | 0 | 0 | 1 | 1 | 1 | 1 | 128/64 | 04F0000-04FFFFF |
| SA80 | 0 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0500000-050FFFF |
| SA81 | 0 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0510000-051FFFF |
| SA82 | 0 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0520000-052FFFF |
| SA83 | 0 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0530000-053FFFF |
| SA84 | 0 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0540000-054FFFF |
| SA85 | 0 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0550000-055FFFF |
| SA86 | 0 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0560000-056FFFF |
| SA87 | 0 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0570000-057FFFF |



Table 4. Sector Address Table–S29GLI28N (Continued)

| Sector | A22-A16 | | | | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---------|---|---|---|---|---|------------------------------------|-----------------------------------|
| SA88 | 0 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0580000-058FFFF |
| SA89 | 0 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0590000-059FFFF |
| SA90 | 0 | 1 | 1 | 0 | 1 | 0 | 128/64 | 05A0000-05AFFFF |
| SA91 | 0 | 1 | 1 | 0 | 1 | 1 | 128/64 | 05B0000-05BFFFF |
| SA92 | 0 | 1 | 1 | 1 | 0 | 0 | 128/64 | 05C0000-05CFFFF |
| SA93 | 0 | 1 | 1 | 1 | 0 | 1 | 128/64 | 05D0000-05DFFFF |
| SA94 | 0 | 1 | 1 | 1 | 1 | 0 | 128/64 | 05E0000-05EFFFF |
| SA95 | 0 | 1 | 1 | 1 | 1 | 1 | 128/64 | 05F0000-05FFFFF |
| SA96 | 1 | 0 | 0 | 0 | 0 | 0 | 128/64 | 0600000-060FFFF |
| SA97 | 1 | 0 | 0 | 0 | 0 | 1 | 128/64 | 0610000-061FFFF |
| SA98 | 1 | 0 | 0 | 0 | 1 | 0 | 128/64 | 0620000-062FFFF |
| SA99 | 1 | 0 | 0 | 0 | 1 | 1 | 128/64 | 0630000-063FFFF |
| SA100 | 1 | 0 | 0 | 1 | 0 | 0 | 128/64 | 0640000-064FFFF |
| SA101 | 1 | 0 | 0 | 1 | 0 | 1 | 128/64 | 0650000-065FFFF |
| SA102 | 1 | 0 | 0 | 1 | 1 | 0 | 128/64 | 0660000-066FFFF |
| SA103 | 1 | 0 | 0 | 1 | 1 | 1 | 128/64 | 0670000-067FFFF |
| SA104 | 1 | 0 | 1 | 0 | 0 | 0 | 128/64 | 0680000-068FFFF |
| SA105 | 1 | 0 | 1 | 0 | 0 | 1 | 128/64 | 0690000-069FFFF |
| SA106 | 1 | 0 | 1 | 0 | 1 | 0 | 128/64 | 06A0000-06AFFFF |
| SA107 | 1 | 0 | 1 | 0 | 1 | 1 | 128/64 | 06B0000-06BFFFF |
| SA108 | 1 | 0 | 1 | 1 | 0 | 0 | 128/64 | 06C0000-06CFFFF |
| SA109 | 1 | 0 | 1 | 1 | 0 | 1 | 128/64 | 06D0000-06DFFFF |
| SA110 | 1 | 0 | 1 | 1 | 1 | 0 | 128/64 | 06E0000-06EFFFF |
| SA111 | 1 | 0 | 1 | 1 | 1 | 1 | 128/64 | 06F0000-06FFFFF |
| SA112 | 1 | 1 | 0 | 0 | 0 | 0 | 128/64 | 0700000-070FFFF |
| SA113 | 1 | 1 | 0 | 0 | 0 | 1 | 128/64 | 0710000-071FFFF |
| SA114 | 1 | 1 | 0 | 0 | 1 | 0 | 128/64 | 0720000-072FFFF |
| SA115 | 1 | 1 | 0 | 0 | 1 | 1 | 128/64 | 0730000-073FFFF |
| SA116 | 1 | 1 | 0 | 1 | 0 | 0 | 128/64 | 0740000-074FFFF |
| SA117 | 1 | 1 | 0 | 1 | 0 | 1 | 128/64 | 0750000-075FFFF |
| SA118 | 1 | 1 | 0 | 1 | 1 | 0 | 128/64 | 0760000-076FFFF |
| SA119 | 1 | 1 | 0 | 1 | 1 | 1 | 128/64 | 0770000-077FFFF |
| SA120 | 1 | 1 | 1 | 0 | 0 | 0 | 128/64 | 0780000-078FFFF |
| SA121 | 1 | 1 | 1 | 0 | 0 | 1 | 128/64 | 0790000-079FFFF |
| SA122 | 1 | 1 | 1 | 0 | 1 | 0 | 128/64 | 07A0000–07AFFFF |



| Sector | | | A22- | -A16 | | | Sector Size (Kbytes/ Kwords) | Address Range (in hexadecimal) |
|--------|---|---|------|------|---|---|------------------------------------|-----------------------------------|
| SA123 | 1 | 1 | 1 | 0 | 1 | 1 | 128/64 | 07B0000-07BFFFF |
| SA124 | 1 | 1 | 1 | 1 | 0 | 0 | 128/64 | 07C0000-07CFFFF |
| SA125 | 1 | 1 | 1 | 1 | 0 | 1 | 128/64 | 07D0000-07DFFFF |
| SA126 | 1 | 1 | 1 | 1 | 1 | 0 | 128/64 | 07E0000-07EFFFF |
| SA127 | 1 | 1 | 1 | 1 | 1 | 1 | 128/64 | 07F0000-07FFFFF |

Table 4. Sector Address Table-S29GLI28N (Continued)

Autoselect Mode

The autoselect mode provides manufacturer and device identification, and sector group protection verification, through identifier codes output on DQ7–DQ0. This mode is primarily intended for programming equipment to automatically match a device to be programmed with its corresponding programming algorithm. However, the autoselect codes can also be accessed in-system through the command register.

When using programming equipment, the autoselect mode requires VID on address pin A9. Address pins A6, A3, A2, A1, and A0 must be as shown in Table 5. In addition, when verifying sector protection, the sector address must appear on the appropriate highest order address bits (see Table 2). Table 5 shows the remaining address bits that are don't care. When all necessary bits have been set as required, the programming equipment may then read the corresponding identifier code on DQ7–DQ0.

To access the autoselect codes in-system, the host system can issue the autoselect command via the command register, as shown in Table 12. This method does not require V_{ID} . Refer to the Autoselect Command Sequence section for more information.

| D | escription | CE# | OE# | WE # | A22 to A15 | A14 to A10 | Α9 | A8 to A7 | A6 | A5 to A4 | A3 to A2 | A1 | A0 | DQ8 to DQ15 | DQ7 to DQ0 |
|------------------------|--|-----|-----|---------|------------------|------------------|-----------------|----------------|----|----------------|----------------|----|----|----------------|---|
| | acturer ID: on Product | L | L | Н | х | х | V_{ID} | х | L | х | L | L | L | 00 | 01h |
| ID I2N | Cycle 1 | | | | | | | | | | L | L | Н | 22 | 7Eh |
| Device ID S29GL512N | Cycle 2 | L | L | Н | х | х | V_{ID} | х | L | х | Н | Н | L | 22 | 23h |
| De S29 | Cycle 3 | | | | | | | | | | Н | Н | Н | 22 | 01h |
| 1D 56N | Cycle 1 | | | | | | | | | | L | L | Н | 22 | 7Eh |
| Device ID S29GL256N | Cycle 2 | L | L | Н | х | х | V_{ID} | х | L | х | Н | Н | L | 22 | 22h |
| De S29 | Cycle 3 | | | | | | | | | | Н | Н | Н | 22 | 01h |
| ID 28N | Cycle 1 | | | | | | | | | | L | L | Н | 22 | 7Eh |
| Device ID 329GL128N | Cycle 2 | L | L | Н | х | х | V_{ID} | х | L | х | Н | Н | L | 22 | 21h |
| De S29 | Cycle 3 | | | | | | | | | | Н | Н | Н | 22 | 01h |
| Sector Protect | Group tion Verification | L | L | Н | SA | х | VID | х | L | х | L | н | L | х | 01h (protected), 00h (unprotected) |
| Indicat WP# p | ed Silicon Sector for Bit (DQ7), rotects highest s sector | L | L | Н | x | х | V _{ID} | x | L | x | L | н | н | x | 98h (factory locked), 18h (not factory locked) |
| Indicat WP# p | ed Silicon Sector or Bit (DQ7), rotects lowest s sector | L | L | Н | x | х | V _{ID} | x | L | х | L | Н | Н | x | 88h (factory locked), 08h (not factory locked) |

| Table 5. Autoselect Code | s, (High Voltage Method) |
|--------------------------|--------------------------|
|--------------------------|--------------------------|

Legend: $L = Logic Low = V_{IL}$, $H = Logic High = V_{IH}$, SA = Sector Address, X = Don't care.

Sector Protection

The device features several levels of sector protection, which can disable both the program and erase operations in certain sectors or sector groups:

Persistent Sector Protection

A command sector protection method that replaces the old 12 V controlled protection method.

Password Sector Protection

A highly sophisticated protection method that requires a password before changes to certain sectors or sector groups are permitted

WP# Hardware Protection

A write protect pin that can prevent program or erase operations in the outermost sectors.

The WP# Hardware Protection feature is always available, independent of the software managed protection method chosen.

Selecting a Sector Protection Mode

All parts default to operate in the Persistent Sector Protection mode. The customer must then choose if the Persistent or Password Protection method is most desirable. There are two one-time programmable non-volatile bits that define which sector protection method will be used. If the customer decides to continue



using the Persistent Sector Protection method, they must set the **Persistent Sector Protection Mode Locking Bit**. This will permanently set the part to operate only using Persistent Sector Protection. If the customer decides to use the password method, they must set the **Password Mode Locking Bit**. This will permanently set the part to operate only using password sector protection.

It is important to remember that setting either the **Persistent Sector Protec**tion Mode Locking Bit or the **Password Mode Locking Bit** permanently selects the protection mode. It is not possible to switch between the two methods once a locking bit has been set. It is important that one mode is explicitly selected when the device is first programmed, rather than relying on the default mode alone. This is so that it is not possible for a system program or virus to later set the Password Mode Locking Bit, which would cause an unexpected shift from the default Persistent Sector Protection Mode into the Password Protection Mode.

The device is shipped with all sectors unprotected. The factory offers the option of programming and protecting sectors at the factory prior to shipping the device through the ExpressFlash[™] Service. Contact your sales representative for details.

It is possible to determine whether a sector is protected or unprotected. See "Autoselect Command Sequence" section on page 67 for details.

Advanced Sector Protection

Advanced Sector Protection features several levels of sector protection, which can disable both the program and erase operations in certain sectors.

Persistent Sector Protection is a method that replaces the old 12V controlled protection method.

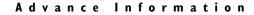
Password Sector Protection is a highly sophisticated protection method that requires a password before changes to certain sectors are permitted.

Lock Register

The Lock Register consists of 3 bits (DQ2, DQ1, and DQ0). These DQ2, DQ1, DQ0 bits of the Lock Register are programmable by the user. Users are not allowed to program both DQ2 and DQ1 bits of the Lock Register to the 00 state. If the user tries to program DQ2 and DQ1 bits of the Lock Register to the 00 state, the device will abort the Lock Register back to the default 11 state. The programming time of the Lock Register is same as the typical word programming time without utilizing the Write Buffer of the device. During a Lock Register programming of the Lock Register has completed to indicate programming status. All Lock Register bits are readable to allow users to verify Lock Register statuses.

The Customer Secured Silicon Sector Protection Bit is DQ0, Persistent Protection Mode Lock Bit is DQ1, and Password Protection Mode Lock Bit is DQ2 are accessible by all users. Each of these bits are non-volatile. DQ15-DQ3 are reserved and must be 1's when the user tries to program the DQ2, DQ1, and DQ0 bits of the Lock Register. The user is not required to program DQ2, DQ1 and DQ0 bits of the Lock Register at the same time. This allows users to lock the Secured Silicon Sector and then set the device either permanently into Password Protection Mode or Persistent Protection Mode and then lock the Secured Silicon Sector at separate instances and time frames.

 Secured Silicon Sector Protection allows the user to lock the Secured Silicon Sector area





- Persistent Protection Mode Lock Bit allows the user to set the device permanently to operate in the Persistent Protection Mode
- Password Protection Mode Lock Bit allows the user to set the device permanently to operate in the Password Protection Mode

| DQ15-3 | DQ2 | DQ1 | DQ0 |
|------------|--------------------------------------|--|---|
| Don't Care | Password Protection Mode Lock Bit | Persistent Protection Mode Lock Bit | Secured Silicon Sector Protection Bit |

Table 6. Lock Register

Persistent Sector Protection

The Persistent Sector Protection method replaces the old 12 V controlled protection method while at the same time enhancing flexibility by providing three different sector protection states:

- Dynamically Locked-The sector is protected and can be changed by a simple command
- Persistently Locked-A sector is protected and cannot be changed
- Unlocked-The sector is unprotected and can be changed by a simple command

In order to achieve these states, three types of "bits" are going to be used:

Dynamic Protection Bit (DYB)

A volatile protection bit is assigned for each sector. After power-up or hardware reset, the contents of all DYB bits are in the "unprotected state". Each DYB is individually modifiable through the DYB Set Command and DYB Clear Command. When the parts are first shipped, all of the Persistent Protect Bits (PPB) are cleared into the unprotected state. The DYB bits and PPB Lock bit are defaulted to power up in the cleared state or unprotected state - meaning the all PPB bits are changeable.

The Protection State for each sector is determined by the logical OR of the PPB and the DYB related to that sector. For the sectors that have the PPB bits cleared, the DYB bits control whether or not the sector is protected or unprotected. By issuing the DYB Set and DYB Clear command sequences, the DYB bits will be protected or unprotected, thus placing each sector in the protected or unprotected state. These are the so-called Dynamic Locked or Unlocked states. They are called dynamic states because it is very easy to switch back and forth between the protected and un-protected conditions. This allows software to easily protect sectors against inadvertent changes yet does not prevent the easy removal of protection when changes are needed.

The DYB bits maybe set or cleared as often as needed. The PPB bits allow for a more static, and difficult to change, level of protection. The PPB bits retain their state across power cycles because they are Non-Volatile. Individual PPB bits are set with a program command but must all be cleared as a group through an erase command.

The PPB Lock Bit adds an additional level of protection. Once all PPB bits are programmed to the desired settings, the PPB Lock Bit may be set to the "freeze state". Setting the PPB Lock Bit to the "freeze state" disables all program and erase commands to the Non-Volatile PPB bits. In effect, the PPB Lock Bit locks the PPB bits into their current state. The only way to clear the PPB Lock Bit to the



"unfreeze state" is to go through a power cycle, or hardware reset. The Software Reset command will not clear the PPB Lock Bit to the "unfreeze state". System boot code can determine if any changes to the PPB bits are needed e.g. to allow new system code to be downloaded. If no changes are needed then the boot code can set the PPB Lock Bit to disable any further changes to the PPB bits during system operation.

The WP# write protect pin adds a final level of hardware protection. When this pin is low it is not possible to change the contents of the WP# protected sectors. These sectors generally hold system boot code. So, the WP# pin can prevent any changes to the boot code that could override the choices made while setting up sector protection during system initialization.

It is possible to have sectors that have been persistently locked, and sectors that are left in the dynamic state. The sectors in the dynamic state are all unprotected. If there is a need to protect some of them, a simple DYB Set command sequence is all that is necessary. The DYB Set and DYB Clear commands for the dynamic sectors switch the DYB bits to signify protected and unprotected, respectively. If there is a need to change the status of the persistently locked sectors, a few more steps are required. First, the PPB Lock Bit must be disabled to the "unfreeze state" by either putting the device through a power-cycle, or hardware reset. The PPB bits can then be changed to reflect the desired settings. Setting the PPB Lock Bit once again to the "freeze state" will lock the PPB bits, and the device operates normally again.

Note: to achieve the best protection, it's recommended to execute the PPB Lock Bit Set command early in the boot code, and protect the boot code by holding $WP\# = V_{1L}$.

Persistent Protection Bit (PPB)

A single Persistent (non-volatile) Protection Bit is assigned to each sector. If a PPB is programmed to the protected state through the "PPB Program" command, that sector will be protected from program or erase operations will be read-only. If a PPB requires erasure, all of the sector PPB bits must first be erased in parallel through the "All PPB Erase" command. The "All PPB Erase" command will preprogrammed all PPB bits prior to PPB erasing. All PPB bits erase in parallel, unlike programming where individual PPB bits are programmable. The PPB bits have the same endurance as the flash memory.

Programming the PPB bit requires the typical word programming time without utilizing the Write Buffer. During a PPB bit programming and A11 PPB bit erasing sequence execution, the DQ6 Toggle Bit I will toggle until the programming of the PPB bit or erasing of all PPB bits has completed to indicate programming and erasing status. Erasing all of the PPB bits at once requires typical sector erase time. During the erasing of all PPB bits, the DQ3 Sector Erase Timer bit will output a 1 to indicate the erasure of all PPB bits are in progress. When the erasure of all PPB bits has completed, the DQ3 Sector Erase Timer bit will output a 0 to indicate that all PPB bits have been erased. Reading the PPB Status bit requires the initial access time of the device.

Persistent Protection Bit Lock (PPB Lock Bit)

A global volatile bit. When set to the "freeze state", the PPB bits cannot be changed. When cleared to the "unfreeze state", the PPB bits are changeable. There is only one PPB Lock Bit per device. The PPB Lock Bit is cleared to the "un-



freeze state" after power-up or hardware reset. There is no command sequence to unlock or "unfreeze" the PPB Lock Bit.

Configuring the PPB Lock Bit to the freeze state requires approximately 100ns. Reading the PPB Lock Status bit requires the initial access time of the device.

| | Protection States | 5 | Sector State |
|-----------|-------------------|--------------|---|
| DYB Bit | PPB Bit | PPB Lock Bit | Sector State |
| Unprotect | Unprotect | Unfreeze | Unprotected – PPB and DYB are changeable |
| Unprotect | Unprotect | Freeze | Unprotected – PPB not changeable, DYB is changeable |
| Unprotect | Protect | Unfreeze | Protected – PPB and DYB are changeable |
| Unprotect | Protect | Freeze | Protected – PPB not changeable, DYB is changeable |
| Protect | Unprotect | Unfreeze | Protected – PPB and DYB are changeable |
| Protect | Unprotect | Freeze | Protected – PPB not changeable, DYB is changeable |
| Protect | Protect | Unfreeze | Protected – PPB and DYB are changeable |
| Protect | Protect | Freeze | Protected – PPB not changeable, DYB is changeable |

Table 7. Sector Protection Schemes

Table 7 contains all possible combinations of the DYB bit, PPB bit, and PPB Lock Bit relating to the status of the sector. In summary, if the PPB bit is set, and the PPB Lock Bit is set, the sector is protected and the protection cannot be removed until the next power cycle or hardware reset clears the PPB Lock Bit to "unfreeze state". If the PPB bit is cleared, the sector can be dynamically locked or unlocked. The DYB bit then controls whether or not the sector is protected or unprotected. If the user attempts to program or erase a protected sector, the device ignores the command and returns to read mode. A program command to a protected sector enables status polling for approximately 1 µs before the device returns to read mode without having modified the contents of the protected sector. An erase command to a protected sector enables status polling for approximately 50 µs after which the device returns to read mode without having erased the protected sector. The programming of the DYB bit, PPB bit, and PPB Lock Bit for a given sector can be verified by writing a DYB Status Read, PPB Status Read, and PPB Lock Status Read commands to the device.

The Autoselect Sector Protection Verification outputs the OR function of the DYB bit and PPB bit per sector basis. When the OR function of the DYB bit and PPB bit is a 1, the sector is either protected by DYB or PPB or both. When the OR function of the DYB bit and PPB bit is a 0, the sector is unprotected through both the DYB and PPB.

Persistent Protection Mode Lock Bit

Like the Password Protection Mode Lock Bit, a Persistent Protection Mode Lock Bit exists to guarantee that the device remain in software sector protection. Once programmed, the Persistent Protection Mode Lock Bit prevents programming of the Password Protection Mode Lock Bit. This guarantees that a hacker could not place the device in Password Protection Mode. The Password Protection Mode Lock Bit resides in the "Lock Register".



Password Sector Protection

The Password Sector Protection method allows an even higher level of security than the Persistent Sector Protection method. There are two main differences between the Persistent Sector Protection and the Password Sector Protection methods:

- When the device is first powered on, or comes out of a reset cycle, the PPB Lock Bit is set to the locked state, or the freeze state, rather than cleared to the unlocked state, or the unfreeze state.
- The only means to clear and unfreeze the PPB Lock Bit is by writing a unique 64-bit Password to the device.

The Password Sector Protection method is otherwise identical to the Persistent Sector Protection method.

A 64-bit password is the only additional tool utilized in this method.

The password is stored in a one-time programmable (OTP) region outside of the flash memory. Once the Password Protection Mode Lock Bit is set, the password is permanently set with no means to read, program, or erase it. The password is used to clear and unfreeze the PPB Lock Bit. The Password Unlock command must be written to the flash, along with a password. The flash device internally compares the given password with the pre-programmed password. If they match, the PPB Lock Bit is cleared to the "unfreezed state", and the PPB bits can be altered. If they do not match, the flash device does nothing. There is a built-in 2 µs delay for each "password check" after the valid 64-bit password has been entered for the PPB Lock Bit to be cleared to the "unfreezed state". This delay is intended to thwart any efforts to run a program that tries all possible combinations in order to crack the password.

Password and Password Protection Mode Lock Bit

In order to select the Password Sector Protection method, the customer must first program the password. The factory recommends that the password be somehow correlated to the unique Electronic Serial Number (ESN) of the particular flash device. Each ESN is different for every flash device; therefore each password should be different for every flash device. While programming in the password region, the customer may perform Password Read operations. Once the desired password is programmed in, the customer must then set the Password Protection Mode Lock Bit. This operation achieves two objectives:

- 1. It permanently sets the device to operate using the Password Protection Mode. It is not possible to reverse this function.
- 2. It also disables all further commands to the password region. All program, and read operations are ignored.

Both of these objectives are important, and if not carefully considered, may lead to unrecoverable errors. The user must be sure that the Password Sector Protection method is desired when programming the Password Protection Mode Lock Bit. More importantly, the user must be sure that the password is correct when the Password Protection Mode Lock Bit is programmed. Due to the fact that read operations are disabled, there is no means to read what the password is afterwards. If the password is lost after programming the Password Protection Mode Lock Bit, there will be no way to clear and unfreeze the PPB Lock Bit. The Password Protection Mode Lock Bit, once programmed, prevents reading the 64-bit password on the DQ bus and further password protection Mode Lock Bit is not erasable. Once Password Protection Mode Lock Bit is



programmed, the Persistent Protection Mode Lock Bit is disabled from programming, guaranteeing that no changes to the protection scheme are allowed.

64-bit Password

The 64-bit Password is located in its own memory space and is accessible through the use of the Password Program and Password Read commands. The password function works in conjunction with the Password Protection Mode Lock Bit, which when programmed, prevents the Password Read command from reading the contents of the password on the pins of the device.

Persistent Protection Bit Lock (PPB Lock Bit)

A global volatile bit. The PPB Lock Bit is a volatile bit that reflects the state of the Password Protection Mode Lock Bit after power-up reset. If the Password Protection Mode Lock Bit is also programmed after programming the Password, the Password Unlock command must be issued to clear and unfreeze the PPB Lock Bit after a hardware reset (RESET# asserted) or a power-up reset. Successful execution of the Password Unlock command clears and unfreezes the PPB Lock Bit, allowing for sector PPB bits to be modified. Without issuing the Password Unlock command, while asserting RESET#, taking the device through a power-on reset, or issuing the PPB Lock Bit Set command sets the PPB Lock Bit to a the "freeze state".

If the Password Protection Mode Lock Bit is not programmed, the device defaults to Persistent Protection Mode. In the Persistent Protection Mode, the PPB Lock Bit is cleared to the "unfreeze state" after power-up or hardware reset. The PPB Lock Bit is set to the "freeze state" by issuing the PPB Lock Bit Set command. Once set to the "freeze state" the only means for clearing the PPB Lock Bit to the "unfreeze state" is by issuing a hardware or power-up reset. The Password Unlock command is ignored in Persistent Protection Mode.

Reading the PPB Lock Bit requires a 200ns access time.

Secured Silicon Sector Flash Memory Region

The Secured Silicon Sector feature provides a Flash memory region that enables permanent part identification through an Electronic Serial Number (ESN). The Secured Silicon Sector is 256 bytes in length, and uses a Secured Silicon Sector Indicator Bit (DQ7) to indicate whether or not the Secured Silicon Sector is locked when shipped from the factory. This bit is permanently set at the factory and cannot be changed, which prevents cloning of a factory locked part. This ensures the security of the ESN once the product is shipped to the field.

The factory offers the device with the Secured Silicon Sector either customer lockable (standard shipping option) or factory locked (contact an AMD sales representative for ordering information). The customer-lockable version is shipped with the Secured Silicon Sector unprotected, allowing customers to program the sector after receiving the device. The customer-lockable version also has the Secured Silicon Sector Indicator Bit permanently set to a "0." The factory-locked version is always protected when shipped from the factory, and has the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a Secure Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a Secure Se



The Secured Silicon sector address space in this device is allocated as follows:

| Secured Silicon Sector Address Range | Customer Lockable | ESN Factory Locked | ExpressFlash Factory Locked |
|---|------------------------|--------------------|----------------------------------|
| 000000h-000007h | Determined by customer | ESN | ESN or determined by customer |
| 000008h–00007Fh | | Unavailable | Determined by customer |

The system accesses the Secured Silicon Sector through a command sequence (see "Write Protect (WP#)"). After the system has written the Enter Secured Silicon Sector command sequence, it may read the Secured Silicon Sector by using the addresses normally occupied by the first sector (SA0). This mode of operation continues until the system issues the Exit Secured Silicon Sector command sequence, or until power is removed from the device. On power-up, or following a hardware reset, the device reverts to sending commands to sector SA0.

Customer Lockable: Secured Silicon Sector NOT Programmed or Protected At the Factory

Unless otherwise specified, the device is shipped such that the customer may program and protect the 256-byte Secured Silicon sector.

The system may program the Secured Silicon Sector using the write-buffer, accelerated and/or unlock bypass methods, in addition to the standard programming command sequence. See "Command Definitions" .

Programming and protecting the Secured Silicon Sector must be used with caution since, once protected, there is no procedure available for unprotecting the Secured Silicon Sector area and none of the bits in the Secured Silicon Sector memory space can be modified in any way.

The Secured Silicon Sector area can be protected using one of the following procedures:

- Write the three-cycle Enter Secured Silicon Sector Region command sequence, and then follow the in-system sector protect algorithm, except that *RESET# may be at either* V_{IH} or V_{ID} . This allows in-system protection of the Secured Silicon Sector without raising any device pin to a high voltage. Note that this method is only applicable to the Secured Silicon Sector.
- To verify the protect/unprotect status of the Secured Silicon Sector, follow the algorithm.

Once the Secured Silicon Sector is programmed, locked and verified, the system must write the Exit Secured Silicon Sector Region command sequence to return to reading and writing within the remainder of the array.

Factory Locked: Secured Silicon Sector Programmed and Protected At the Factory

In devices with an ESN, the Secured Silicon Sector is protected when the device is shipped from the factory. The Secured Silicon Sector cannot be modified in any way. An ESN Factory Locked device has an 16-byte random ESN at addresses 000000h–000007h. Please contact your sales representative for details on ordering ESN Factory Locked devices.

Customers may opt to have their code programmed by the factory through the ExpressFlash service (Express Flash Factory Locked). The devices are then shipped from the factory with the Secured Silicon Sector permanently locked. Contact your sales representative for details on using the ExpressFlash service.



Write Protect (WP#)

The Write Protect function provides a hardware method of protecting the first or last sector group without using V_{ID} . Write Protect is one of two functions provided by the WP#/ACC input.

If the system asserts V_{IL} on the WP#/ACC pin, the device disables program and erase functions in the first or last sector group independently of whether those sector groups were protected or unprotected using the method described in"Advanced Sector Protection" section on page 55. Note that if WP#/ACC is at V_{IL} when the device is in the standby mode, the maximum input load current is increased. See the table in "DC Characteristics" section on page 91.

If the system asserts V_{IH} on the WP#/ACC pin, the device reverts to whether the first or last sector was previously set to be protected or unprotected using the method described in "Sector Group Protection and Unprotection". Note that WP# has an internal pullup; when unconnected, WP# is at V_{IH} .

Hardware Data Protection

The command sequence requirement of unlock cycles for programming or erasing provides data protection against inadvertent writes (refer to Table 12 for command definitions). In addition, the following hardware data protection measures prevent accidental erasure or programming, which might otherwise be caused by spurious system level signals during V_{CC} power-up and power-down transitions, or from system noise.

Low V_{CC} Write Inhibit

When V_{CC} is less than V_{LKO} , the device does not accept any write cycles. This protects data during V_{CC} power-up and power-down. The command register and all internal program/erase circuits are disabled, and the device resets to the read mode. Subsequent writes are ignored until V_{CC} is greater than V_{LKO} . The system must provide the proper signals to the control pins to prevent unintentional writes when V_{CC} is greater than V_{LKO} .

Write Pulse "Glitch" Protection

Noise pulses of less than 5 ns (typical) on OE#, CE# or WE# do not initiate a write cycle.

Logical Inhibit

Write cycles are inhibited by holding any one of $OE\# = V_{IL}$, $CE\# = V_{IH}$ or $WE\# = V_{IH}$. To initiate a write cycle, CE# and WE# must be a logical zero while OE# is a logical one.

Power-Up Write Inhibit

If WE# = CE# = V_{IL} and OE# = V_{IH} during power up, the device does not accept commands on the rising edge of WE#. The internal state machine is automatically reset to the read mode on power-up.

Common Flash Memory Interface (CFI)

The Common Flash Interface (CFI) specification outlines device and host system software interrogation handshake, which allows specific vendor-specified software algorithms to be used for entire families of devices. Software support can



then be device-independent, JEDEC ID-independent, and forward- and backward-compatible for the specified flash device families. Flash vendors can standardize their existing interfaces for long-term compatibility.

This device enters the CFI Query mode when the system writes the CFI Query command, 98h, to address 55h, any time the device is ready to read array data. The system can read CFI information at the addresses given in Tables 8-11. To terminate reading CFI data, the system must write the reset command.

The system can also write the CFI query command when the device is in the autoselect mode. The device enters the CFI query mode, and the system can read CFI data at the addresses given in Tables 8–11. The system must write the reset command to return the device to reading array data.

For further information, please refer to the CFI Specification and CFI Publication 100, available via the World Wide Web at http://www.amd.com/flash/cfi. Alternatively, contact your sales representative for copies of these documents.

| Addresses (x16) | Data | Description |
|--------------------|-------------------------|--|
| 10h 11h 12h | 0051h 0052h 0059h | Query Unique ASCII string "QRY" |
| 13h 14h | 0002h 0000h | Primary OEM Command Set |
| 15h 16h | 0040h 0000h | Address for Primary Extended Table |
| 17h 18h | 0000h 0000h | Alternate OEM Command Set (00h = none exists) |
| 19h 1Ah | 0000h 0000h | Address for Alternate OEM Extended Table (00h = none exists) |

Table 8. CFI Query Identification String

| Addresses (x16) | Data | Description |
|--------------------|-------|--|
| 1Bh | 0027h | V _{CC} Min. (write/erase) D7–D4: volt, D3–D0: 100 millivolt |
| 1Ch | 0036h | V _{CC} Max. (write/erase) D7–D4: volt, D3–D0: 100 millivolt |
| 1Dh | 0000h | V _{pp} Min. voltage (00h = no V _{pp} pin present) |
| 1Eh | 0000h | V_{PP} Max. voltage (00h = no V_{PP} pin present) |
| 1Fh | 0007h | Typical timeout per single byte/word write 2 [№] µs |
| 20h | 0007h | Typical timeout for Min. size buffer write $2^{N} \mu s$ (00h = not supported) |
| 21h | 000Ah | Typical timeout per individual block erase 2 [№] ms |
| 22h | 0000h | Typical timeout for full chip erase 2^{N} ms (00h = not supported) |
| 23h | 0001h | Max. timeout for byte/word write 2 ^N times typical |
| 24h | 0005h | Max. timeout for buffer write 2 ^N times typical |
| 25h | 0004h | Max. timeout per individual block erase 2 ^N times typical |
| 26h | 0000h | Max. timeout for full chip erase 2^{N} times typical (00h = not supported) |

Table 9. System Interface String



| Addresses (x16) | Data | Description |
|--------------------------|----------------------------------|---|
| 27h | 001Ah 0019h 0018h | Device Size = 2 ^N byte 1A = 512 Mb, 19 = 256 Mb, 18 = 128 Mb |
| 28h 29h | 0002h 0000h | Flash Device Interface description (refer to CFI publication 100) |
| 2Ah 2Bh | 0005h 0000h | Max. number of byte in multi-byte write = 2^{N} (00h = not supported) |
| 2Ch | 0001h | Number of Erase Block Regions within device (01h = uniform device, 02h = boot device) |
| 2Dh 2Eh 2Fh 30h | 00xxh 000xh 0000h 000xh | Erase Block Region 1 Information (refer to the CFI specification or CFI publication 100) 00FFh, 001h, 0000h, 0002h = 512 Mb 00FFh, 0000h, 0000h, 0002h = 256 Mb 007Fh, 0000h, 0000h, 0002h = 128 Mb |
| 31h 32h 33h 34h | 0000h 0000h 0000h 0000h | Erase Block Region 2 Information (refer to CFI publication 100) |
| 35h 36h 37h 38h | 0000h 0000h 0000h 0000h | Erase Block Region 3 Information (refer to CFI publication 100) |
| 39h 3Ah 3Bh 3Ch | 0000h 0000h 0000h 0000h | Erase Block Region 4 Information (refer to CFI publication 100) |

Table I0. Device Geometry Definition

| Addresses | | |
|-------------------|-------------------------|---|
| (x16) | Data | Description |
| 40h 41h 42h | 0050h 0052h 0049h | Query-unique ASCII string "PRI" |
| 43h | 0031h | Major version number, ASCII |
| 44h | 0033h | Minor version number, ASCII |
| 45h | 0010h | Address Sensitive Unlock (Bits 1-0) 0 = Required, 1 = Not Required Process Technology (Bits 7-2) 0100b = 110 nm MirrorBit |
| 46h | 0002h | Erase Suspend 0 = Not Supported, 1 = To Read Only, 2 = To Read & Write |
| 47h | 0001h | Sector Protect 0 = Not Supported, X = Number of sectors in per group |
| 48h | 0000h | Sector Temporary Unprotect 00 = Not Supported, 01 = Supported |
| 49h | 0008h | Sector Protect/Unprotect scheme 0008h = Advanced Sector Protection |
| 4Ah | 0000h | Simultaneous Operation 00 = Not Supported, X = Number of Sectors in Bank |
| 4Bh | 0000h | Burst Mode Type 00 = Not Supported, 01 = Supported |
| 4Ch | 0002h | Page Mode Type 00 = Not Supported, 01 = 4 Word Page, 02 = 8 Word Page |
| 4Dh | 00B5h | ACC (Acceleration) Supply Minimum 00h = Not Supported, D7-D4: Volt, D3-D0: 100 mV |
| 4Eh | 00C5h | ACC (Acceleration) Supply Maximum 00h = Not Supported, D7-D4: Volt, D3-D0: 100 mV |
| 4Fh | 00xxh | WP# Protection 04h = Uniform sectors bottom WP# protect, 05h = Uniform sectors top WP# protect |
| 50h | 0001h | Program Suspend 00h = Not Supported, 01h = Supported |

Table II. Primary Vendor-Specific Extended Query

Command Definitions

Writing specific address and data commands or sequences into the command register initiates device operations. Table 12 defines the valid register command sequences. *Writing incorrect address and data values or writing them in the improper sequence may place the device in an unknown state.* A reset command is then required to return the device to reading array data.

All addresses are latched on the falling edge of WE# or CE#, whichever happens later. All data is latched on the rising edge of WE# or CE#, whichever happens first. Refer to the AC Characteristics section for timing diagrams.



Reading Array Data

The device is automatically set to reading array data after device power-up. No commands are required to retrieve data. The device is ready to read array data after completing an Embedded Program or Embedded Erase algorithm.

After the device accepts an Erase Suspend command, the device enters the erase-suspend-read mode, after which the system can read data from any nonerase-suspended sector. After completing a programming operation in the Erase Suspend mode, the system may once again read array data with the same exception. See the Erase Suspend/Erase Resume Commands section for more information.

The system *must* issue the reset command to return the device to the read (or erase-suspend-read) mode if DQ5 goes high during an active program or erase operation, or if the device is in the autoselect mode. See the next section, Reset Command, for more information.

See also Requirements for Reading Array Data in the Device Bus Operations section for more information. The Read-Only Operations–"AC Characteristics" section provides the read parameters, and Figure 11 shows the timing diagram.

Reset Command

Writing the reset command resets the device to the read or erase-suspend-read mode. Address bits are don't cares for this command.

The reset command may be written between the sequence cycles in an erase command sequence before erasing begins. This resets the device to the read mode. Once erasure begins, however, the device ignores reset commands until the operation is complete.

The reset command may be written between the sequence cycles in a program command sequence before programming begins. This resets the device to the read mode. If the program command sequence is written while the device is in the Erase Suspend mode, writing the reset command returns the device to the erase-suspend-read mode. Once programming begins, however, the device ignores reset commands until the operation is complete.

The reset command may be written between the sequence cycles in an autoselect command sequence. Once in the autoselect mode, the reset command must be written to return to the read mode. If the device entered the autoselect mode while in the Erase Suspend mode, writing the reset command returns the device to the erase-suspend-read mode.

If DQ5 goes high during a program or erase operation, writing the reset command returns the device to the read mode (or erase-suspend-read mode if the device was in Erase Suspend).

Note that if DQ1 goes high during a Write Buffer Programming operation, the system must write the Write-to-Buffer-Abort Reset command sequence to reset the device for the next operation.

Autoselect Command Sequence

The autoselect command sequence allows the host system to access the manufacturer and device codes, and determine whether or not a sector is protected. Table 12 shows the address and data requirements. This method is an alternative to that shown in Table 5, which is intended for PROM programmers and requires V_{ID} on address pin A9. The autoselect command sequence may be written to an



address that is either in the read or erase-suspend-read mode. The autoselect command may not be written while the device is actively programming or erasing.

The autoselect command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle that contains the autoselect command. The device then enters the autoselect mode. The system may read at any address any number of times without initiating another autoselect command sequence:

- A read cycle at address XX00h returns the manufacturer code.
- Three read cycles at addresses 01h, 0Eh, and 0Fh return the device code.
- A read cycle to an address containing a sector address (SA), and the address 02h on A7–A0 in word mode returns 01h if the sector is protected, or 00h if it is unprotected.

The system must write the reset command to return to the read mode (or erasesuspend-read mode if the device was previously in Erase Suspend).

Enter Secured Silicon Sector/Exit Secured Silicon Sector Command Sequence

The Secured Silicon Sector region provides a secured data area containing an 8word/16-byte random Electronic Serial Number (ESN). The system can access the Secured Silicon Sector region by issuing the three-cycle Enter Secured Silicon Sector command sequence. The device continues to access the Secured Silicon Sector region until the system issues the four-cycle Exit Secured Silicon Sector command sequence. The Exit Secured Silicon Sector command sequence returns the device to normal operation. Table 12 shows the address and data requirements for both command sequences. See also "Secured Silicon Sector Flash Memory Region" for further information. Note that the ACC function and unlock bypass modes are not available when the Secured Silicon Sector is enabled.

Word Program Command Sequence

Programming is a four-bus-cycle operation. The program command sequence is initiated by writing two unlock write cycles, followed by the program set-up command. The program address and data are written next, which in turn initiate the Embedded Program algorithm. The system is *not* required to provide further controls or timings. The device automatically provides internally generated program pulses and verifies the programmed cell margin. Table 12 shows the address and data requirements for the word program command sequence.

When the Embedded Program algorithm is complete, the device then returns to the read mode and addresses are no longer latched. The system can determine the status of the program operation by using DQ7 or DQ6. Refer to the Write Operation Status section for information on these status bits.

Any commands written to the device during the Embedded Program Algorithm are ignored. **Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when a program operation is in progress.** Note that a **hardware reset** immediately terminates the program operation. The program command sequence should be reinitiated once the device has returned to the read mode, to ensure data integrity.

Programming is allowed in any sequence of address locations and across sector boundaries. Programming to the same word address multiple times without intervening erases (incremental bit programming) requires a modified programming method. For such application requirements, please contact your



local Spansion representative. Word programming is supported for backward compatibility with existing Flash driver software and for occasional writing of individual words. Use of Write Buffer Programming is strongly recommended for general programming use when more than a few words are to be programmed. The effective word programming time using Write Buffer Programming is much shorter than the single word programming time. **Any word cannot be pro-grammed from "0" back to a "1."** Attempting to do so may cause the device to set DQ5 = 1, or cause the DQ7 and DQ6 status bits to indicate the operation was successful. However, a succeeding read will show that the data is still "0." Only erase operations can convert a "0" to a "1."

Unlock Bypass Command Sequence

The unlock bypass feature allows the system to program words to the device faster than using the standard program command sequence. The unlock bypass command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle containing the unlock bypass command, 20h. The device then enters the unlock bypass mode. A two-cycle unlock bypass program command sequence is all that is required to program in this mode. The first cycle in this sequence contains the unlock bypass program command, A0h; the second cycle contains the program address and data. Additional data is programmed in the same manner. This mode dispenses with the initial two unlock cycles required in the standard program command sequence, resulting in faster total programming time. Table 12 shows the requirements for the command sequence.

During the unlock bypass mode, only the Unlock Bypass Program and Unlock Bypass Reset commands are valid. To exit the unlock bypass mode, the system must issue the two-cycle unlock bypass reset command sequence. (See Table 12).

Write Buffer Programming

Write Buffer Programming allows the system write to a maximum of 16 words/32 bytes in one programming operation. This results in faster effective programming time than the standard programming algorithms. The Write Buffer Programming command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle containing the Write Buffer Load command written at the Sector Address in which programming will occur. The fourth cycle writes the sector address and the number of word locations, minus one, to be programmed. For example, if the system will program 6 unique address locations, then 05h should be written to the device. This tells the device how many write buffer addresses will be loaded with data and therefore when to expect the Program Buffer to Flash command. The number of locations to program cannot exceed the size of the write buffer or the operation will abort.

The fifth cycle writes the first address location and data to be programmed. The write-buffer-page is selected by address bits A_{MAX} -A₄. All subsequent address/ data pairs must fall within the selected-write-buffer-page. The system then writes the remaining address/data pairs into the write buffer. Write buffer locations may be loaded in any order.

The write-buffer-page address must be the same for all address/data pairs loaded into the write buffer. (This means Write Buffer Programming cannot be performed across multiple write-buffer pages. This also means that Write Buffer Programming cannot be performed across multiple sectors. If the system attempts to load programming data outside of the selected write-buffer page, the operation will abort.)



Note that if a Write Buffer address location is loaded multiple times, the address/ data pair counter will be decremented for every data load operation. The host system must therefore account for loading a write-buffer location more than once. The counter decrements for each data load operation, not for each unique write-buffer-address location. Note also that if an address location is loaded more than once into the buffer, the final data loaded for that address will be programmed.

Once the specified number of write buffer locations have been loaded, the system must then write the Program Buffer to Flash command at the sector address. Any other address and data combination aborts the Write Buffer Programming operation. The device then begins programming. Data polling should be used while monitoring the last address location loaded into the write buffer. DQ7, DQ6, DQ5, and DQ1 should be monitored to determine the device status during Write Buffer Programming.

The write-buffer programming operation can be suspended using the standard program suspend/resume commands. Upon successful completion of the Write Buffer Programming operation, the device is ready to execute the next command.

The Write Buffer Programming Sequence can be aborted in the following ways:

- Load a value that is greater than the page buffer size during the Number of Locations to Program step.
- Write to an address in a sector different than the one specified during the Write-Buffer-Load command.
- Write an Address/Data pair to a different write-buffer-page than the one selected by the Starting Address during the write buffer data loading stage of the operation.
- Write data other than the Confirm Command after the specified number of data load cycles.

The abort condition is indicated by DQ1 = 1, DQ7 = DATA# (for the last address location loaded), DQ6 = toggle, and DQ5=0. A Write-to-Buffer-Abort Reset command sequence must be written to reset the device for the next operation. Note that the full 3-cycle Write-to-Buffer-Abort Reset command sequence is required when using Write-Buffer-Programming features in Unlock Bypass mode.

Write buffer programming is allowed in any sequence. Note that the Secured Silicon sector, autoselect, and CFI functions are unavailable when a program operation is in progress. This flash device is capable of handling multiple write buffer programming operations on the same write buffer address range without intervening erases. For applications requiring incremental bit programming, a modified programming method is required, please contact your local Spansion representative. **Any bit in a write buffer address range cannot be programmed from "0" back to a "1."** Attempting to do so may cause the device to set DQ5 = 1, or cause the DQ7 and DQ6 status bits to indicate the operation was successful. However, a succeeding read will show that the data is still "0." Only erase operations can convert a "0" to a "1."

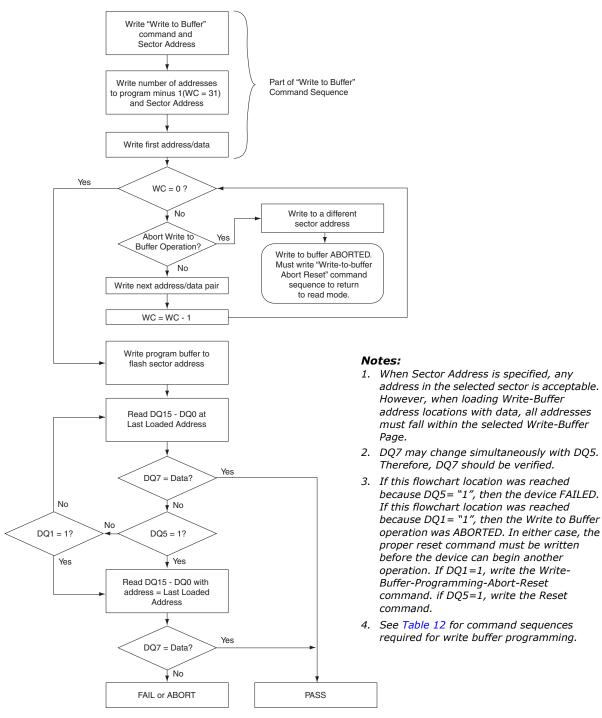
Accelerated Program

The device offers accelerated program operations through the WP#/ACC pin. When the system asserts V_{HH} on the WP#/ACC pin, the device automatically enters the Unlock Bypass mode. The system may then write the two-cycle Unlock Bypass program command sequence. The device uses the higher voltage on the WP#/ACC pin to accelerate the operation. *Note that the* WP#/ACC pin must not



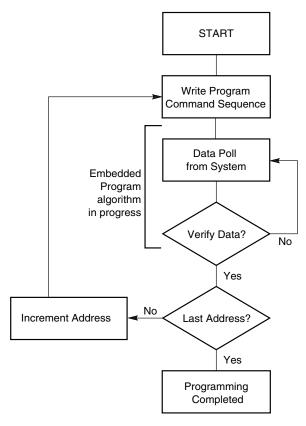
be at V_{HH} for operations other than accelerated programming, or device damage may result. WP# has an internal pullup; when unconnected, WP# is at V_{TH} .

Figure 2 illustrates the algorithm for the program operation. Refer to the Erase and Program Operations—"AC Characteristics" section for parameters, and Figure 14 for timing diagrams.

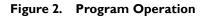








Note: See Table 12 for program command sequence.



Program Suspend/Program Resume Command Sequence

The Program Suspend command allows the system to interrupt a programming operation or a Write to Buffer programming operation so that data can be read from any non-suspended sector. When the Program Suspend command is written during a programming process, the device halts the program operation within 15 μ s maximum (5 μ s typical) and updates the status bits. Addresses are not required when writing the Program Suspend command.

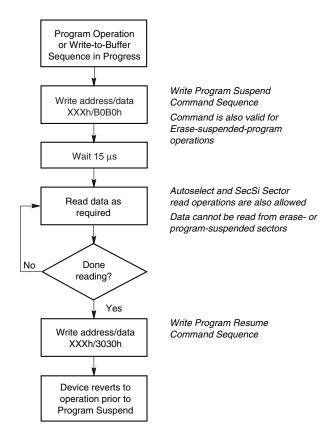
After the programming operation has been suspended, the system can read array data from any non-suspended sector. The Program Suspend command may also be issued during a programming operation while an erase is suspended. In this case, data may be read from any addresses not in Erase Suspend or Program Suspend. If a read is needed from the Secured Silicon Sector area (One-time Program area), then user must use the proper command sequences to enter and exit this region. *Note that the Secured Silicon Sector autoselect, and CFI functions are unavailable when program operation is in progress.*

The system may also write the autoselect command sequence when the device is in the Program Suspend mode. The system can read as many autoselect codes as required. When the device exits the autoselect mode, the device reverts to the Program Suspend mode, and is ready for another valid operation. See Autoselect Command Sequence for more information.



After the Program Resume command is written, the device reverts to programming. The system can determine the status of the program operation using the DQ7 or DQ6 status bits, just as in the standard program operation. See Write Operation Status for more information.

The system must write the Program Resume command (address bits are don't care) to exit the Program Suspend mode and continue the programming operation. Further writes of the Resume command are ignored. Another Program Suspend command can be written after the device has resume programming.





Chip Erase Command Sequence

Chip erase is a six bus cycle operation. The chip erase command sequence is initiated by writing two unlock cycles, followed by a set-up command. Two additional unlock write cycles are then followed by the chip erase command, which in turn invokes the Embedded Erase algorithm. The device does *not* require the system to preprogram prior to erase. The Embedded Erase algorithm automatically preprograms and verifies the entire memory for an all zero data pattern prior to electrical erase. The system is not required to provide any controls or timings during these operations. Table 12 shows the address and data requirements for the chip erase command sequence.

When the Embedded Erase algorithm is complete, the device returns to the read mode and addresses are no longer latched. The system can determine the status of the erase operation by using DQ7, DQ6, or DQ2. Refer to the Write Operation Status section for information on these status bits.



Any commands written during the chip erase operation are ignored, including erase suspend commands. However, note that a **hardware reset** immediately terminates the erase operation. If that occurs, the chip erase command sequence should be reinitiated once the device has returned to reading array data, to ensure data integrity.

Figure 4 illustrates the algorithm for the erase operation. **Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when an erase operation in is progress.** Refer to the "Erase And Programming Performance" section on page 103 in the AC Characteristics section for parameters, and Figure 16 section for timing diagrams.

Sector Erase Command Sequence

Sector erase is a six bus cycle operation. The sector erase command sequence is initiated by writing two unlock cycles, followed by a set-up command. Two additional unlock cycles are written, and are then followed by the address of the sector to be erased, and the sector erase command. Table 12 shows the address and data requirements for the sector erase command sequence.

The device does *not* require the system to preprogram prior to erase. The Embedded Erase algorithm automatically programs and verifies the entire memory for an all zero data pattern prior to electrical erase. The system is not required to provide any controls or timings during these operations.

After the command sequence is written, a sector erase time-out of 50 µs occurs. During the time-out period, additional sector addresses and sector erase commands may be written. Loading the sector erase buffer may be done in any sequence, and the number of sectors may be from one sector to all sectors. The time between these additional cycles must be less than 50 µs, otherwise erasure may begin. Any sector erase address and command following the exceeded time-out may or may not be accepted. It is recommended that processor interrupts be disabled during this time to ensure all commands are accepted. The interrupts can be re-enabled after the last Sector Erase Suspend during the time-out period resets the device to the read mode. Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when an erase operation in is progress. The system must rewrite the command sequence and any additional addresses and commands.

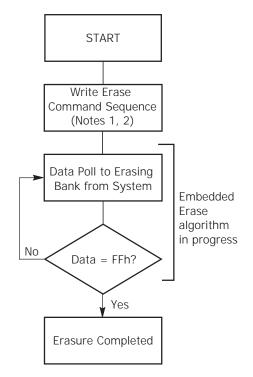
The system can monitor DQ3 to determine if the sector erase timer has timed out (See the section on DQ3: Sector Erase Timer.). The time-out begins from the rising edge of the final WE# pulse in the command sequence.

When the Embedded Erase algorithm is complete, the device returns to reading array data and addresses are no longer latched. The system can determine the status of the erase operation by reading DQ7, DQ6, or DQ2 in the erasing sector. Refer to the Write Operation Status section for information on these status bits.

Once the sector erase operation has begun, only the Erase Suspend command is valid. All other commands are ignored. However, note that a **hardware reset** immediately terminates the erase operation. If that occurs, the sector erase command sequence should be reinitiated once the device has returned to reading array data, to ensure data integrity.

Figure 4 illustrates the algorithm for the erase operation. Refer to the Erase and Program Operations table in the AC Characteristics section for parameters, and Figure 16 section for timing diagrams.





Notes:

- 1. See Table 12 for program command sequence.
- 2. See the section on DQ3 for information on the sector erase timer.

Figure 4. Erase Operation

Erase Suspend/Erase Resume Commands

The Erase Suspend command, B0h, allows the system to interrupt a sector erase operation and then read data from, or program data to, any sector not selected for erasure. This command is valid only during the sector erase operation, including the 50 µs time-out period during the sector erase command sequence. The Erase Suspend command is ignored if written during the chip erase operation or Embedded Program algorithm.

When the Erase Suspend command is written during the sector erase operation, the device requires a typical of 5 μ s (maximum of 20 μ s) to suspend the erase operation. However, when the Erase Suspend command is written during the sector erase time-out, the device immediately terminates the time-out period and suspends the erase operation.

After the erase operation has been suspended, the device enters the erase-suspend-read mode. The system can read data from or program data to any sector not selected for erasure. (The device "erase suspends" all sectors selected for erasure.) Reading at any address within erase-suspended sectors produces status information on DQ7–DQ0. The system can use DQ7, or DQ6 and DQ2 together, to determine if a sector is actively erasing or is erase-suspended. Refer to the Write Operation Status section for information on these status bits.

After an erase-suspended program operation is complete, the device returns to the erase-suspend-read mode. The system can determine the status of the pro-



gram operation using the DQ7 or DQ6 status bits, just as in the standard word program operation. Refer to the Write Operation Status section for more information.

In the erase-suspend-read mode, the system can also issue the autoselect command sequence. Refer to the "Autoselect Mode" section and "Autoselect Command Sequence" section on page 67 sections for details.

To resume the sector erase operation, the system must write the Erase Resume command. The address of the erase-suspended sector is required when writing this command. Further writes of the Resume command are ignored. Another Erase Suspend command can be written after the chip has resumed erasing. It is important to allow an interval of at least 5 ms between Erase Resume and Erase Suspend.

Lock Register Command Set Definitions

The Lock Register Command Set permits the user to one-time program the Secured Silicon Sector Protection Bit, Persistent Protection Mode Lock Bit, and Password Protection Mode Lock Bit. The Lock Register bits are all readable after an initial access delay.

The **Lock Register Command Set Entry** command sequence must be issued prior to any of the following commands listed, to enable proper command execution.

Note that issuing the Lock Register Command Set Entry command disables reads and writes for the flash memory.

- Lock Register Program Command
- Lock Register Read Command

The **Lock Register Command Set Exit** command must be issued after the execution of the commands to reset the device to read mode. Otherwise the device will hang. If this happens, the flash device must be reset. Please refer to RESET# for more information. It is important to note that the device will be in either Persistent Protection mode or Password Protection mode depending on the mode selected prior to the device hang.

For either the Secured Silicon Sector to be locked, or the device to be permanently set to the Persistent Protection Mode or the Password Protection Mode, the associated Lock Register bits must be programmed. **Note that the Persistent Protection Mode Lock Bit and Password Protection Mode Lock Bit can never be programmed together at the same time. If so, the Lock Register Program operation will abort**.

The Lock Register Command Set Exit command must be initiated to reenable reads and writes to the main memory.

Password Protection Command Set Definitions

The Password Protection Command Set permits the user to program the 64-bit password, verify the programming of the 64-bit password, and then later unlock the device by issuing the valid 64-bit password.

The **Password Protection Command Set Entry** command sequence must be issued prior to any of the commands listed following to enable proper command execution.

Note that issuing the **Password Protection Command Set Entry** command **disabled reads and writes the main memory.**



- Password Program Command
- Password Read Command
- Password Unlock Command

The Password Program command permits programming the password that is used as part of the hardware protection scheme. The actual password is 64-bits long. There is no special addressing order required for programming the password. **The password is programmed in 8-bit or 16-bit portions. Each portion requires a Password Program Command.**

Once the Password is written and verified, the Password Protection Mode Lock Bit in the "Lock Register" must be programmed in order to prevent verification. The Password Program command is only capable of programming "0"s. Programming a "1" after a cell is programmed as a "0" results in a time-out by the Embedded Program Algorithm[™] with the cell remaining as a "0". The password is all F's when shipped from the factory. All 64-bit password combinations are valid as a password.

The Password Read command is used to verify the Password. The Password is verifiable only when the Password Protection Mode Lock Bit in the "Lock Register" is not programmed. If the Password Protection Mode Lock Bit in the "Lock Register" is programmed and the user attempts to read the Password, the device will always drive all F's onto the DQ databus.

The lower two address bits (A1–A0) for word mode and (A1–A-1) for by byte mode are valid during the Password Read, Password Program, and Password Unlock commands. Writing a "1" to any other address bits (A_{MAX} -A2) will abort the Password Read and Password Program commands.

The Password Unlock command is used to clear the PPB Lock Bit to the "unfreeze state" so that the PPB bits can be modified. The exact password must be entered in order for the unlocking function to occur. **This 64-bit Password Unlock command sequence will take at least 2 µs to process each time to prevent a hacker from running through the all 64-bit combinations in an attempt to correctly match the password. If another password unlock is issued before the 64-bit password check execution window is completed, the command will be ignored. If the wrong address or data is given during password unlock command cycle, the device may enter the write-to-buffer abort state. In order to exit the write-to-abort state, the write-to-buffer-abort-reset command must be given. Otherwise the device will hang.**

The Password Unlock function is accomplished by writing Password Unlock command and data to the device to perform the clearing of the PPB Lock Bit to the "unfreeze state". The password is 64 bits long. A1 and A0 are used for matching. Writing the Password Unlock command does not need to be address order specific. An example sequence is starting with the lower address A1-A0=00, followed by A1-A0=01, A1-A0=10, and A1-A0=11 if the device is configured to operate in word mode.

Approximately 2 µs is required for unlocking the device after the valid 64-bit password is given to the device. It is the responsibility of the microprocessor to keep track of the entering the portions of the 64-bit password with the Password Unlock command, the order, and when to read the PPB Lock bit to confirm successful password unlock. In order to re-lock the device into the Password Protection Mode, the PPB Lock Bit Set command can be re-issued.



The **Password Protection Command Set Exit** command must be issued after the execution of the commands listed previously to reset the device to read mode. Otherwise the device will hang.

Note that issuing the **Password Protection Command Set Exit command re**enables reads and writes for the main memory.

Non-Volatile Sector Protection Command Set Definitions

The Non-Volatile Sector Protection Command Set permits the user to program the Persistent Protection Bits (PPB bits), erase all of the Persistent Protection Bits (PPB bits), and read the logic state of the Persistent Protection Bits (PPB bits).

The **Non-Volatile Sector Protection Command Set Entry** command sequence must be issued prior to any of the commands listed following to enable proper command execution.

Note that issuing the **Non-Volatile Sector Protection Command Set Entry** command **disables reads and writes for the main memory**.

PPB Program Command

The PPB Program command is used to program, or set, a given PPB bit. Each PPB bit is individually programmed (but is bulk erased with the other PPB bits). The specific sector address (A24-A16 for S29GL512N, A23-A16 for S29GL256N, A22-A16 for S29GL128N) is written at the same time as the program command. If the PPB Lock Bit is set to the "freeze state", the PPB Program command will not execute and the command will time-out without programming the PPB bit.

■ All PPB Erase Command

The All PPB Erase command is used to erase all PPB bits in bulk. There is no means for individually erasing a specific PPB bit. Unlike the PPB program, no specific sector address is required. However, when the All PPB Erase command is issued, all Sector PPB bits are erased in parallel. If the PPB Lock Bit is set to "freeze state", the ALL PPB Erase command will not execute and the command will time-out without erasing the PPB bits.

The device will preprogram all PPB bits prior to erasing when issuing the All PPB Erase command. Also note that the total number of PPB program/erase cycles has the same endurance as the flash memory array.

PPB Status Read Command

The programming state of the PPB for a given sector can be verified by writing a PPB Status Read Command to the device. This requires an initial access time latency.

The **Non-Volatile Sector Protection Command Set Exit** command must be issued after the execution of the commands listed previously to reset the device to read mode.

Note that issuing the **Non-Volatile Sector Protection Command Set Exit** command **re-enables reads and writes for the main memory**.

Global Volatile Sector Protection Freeze Command Set

The Global Volatile Sector Protection Freeze Command Set permits the user to set the PPB Lock Bit and reading the logic state of the PPB Lock Bit.

The **Global Volatile Sector Protection Freeze Command Set Entry** command sequence must be issued prior to any of the commands listed following to enable proper command execution.



Reads and writes from the main memory are not allowed.

PPB Lock Bit Set Command

The PPB Lock Bit Set command is used to set the PPB Lock Bit to the "freeze state" if it is cleared either at reset or if the Password Unlock command was successfully executed. There is no PPB Lock Bit Clear command. Once the PPB Lock Bit is set to the "freeze state", it cannot be cleared unless the device is taken through a power-on clear (for Persistent Protection Mode) or the Password Unlock command is executed (for Password Protection Mode). If the Password Protection Mode Lock Bit is programmed, the PPB Lock Bit status is reflected as set to the "freeze state", even after a power-on reset cycle.

PPB Lock Bit Status Read Command

The programming state of the PPB Lock Bit can be verified by executing a PPB Lock Bit Status Read command to the device.

The **Global Volatile Sector Protection Freeze Command Set Exit** command must be issued after the execution of the commands listed previously to reset the device to read mode.

Volatile Sector Protection Command Set

The Volatile Sector Protection Command Set permits the user to set the Dynamic Protection Bit (DYB) to the "protected state", clear the Dynamic Protection Bit (DYB) to the "unprotected state", and read the logic state of the Dynamic Protection Bit (DYB).

The **Volatile Sector Protection Command Set Entry** command sequence must be issued prior to any of the commands listed following to enable proper command execution.

Note that issuing the Volatile Sector Protection Command Set Entry command disables reads and writes from main memory.

- DYB Set Command
- DYB Clear Command

The DYB Set and DYB Clear commands are used to protect or unprotect a DYB for a given sector. The high order address bits are issued at the same time as the code 00h or 01h on DQ7-DQ0. All other DQ data bus pins are ignored during the data write cycle. The DYB bits are modifiable at any time, regardless of the state of the PPB bit or PPB Lock Bit. The DYB bits are cleared to the "unprotected state" at power-up or hardware reset.

-DYB Status Read Command

The programming state of the DYB bit for a given sector can be verified by writing a DYB Status Read command to the device. This requires an initial access delay.

The **Volatile Sector Protection Command Set Exit** command must be issued after the execution of the commands listed previously to reset the device to read mode.

Note that issuing the Volatile Sector Protection Command Set Exit command re-enables reads and writes to the main memory.



Secured Silicon Sector Entry Command

The Secured Silicon Sector Entry command allows the following commands to be executed

- Read from Secured Silicon Sector
- Program to Secured Silicon Sector

Once the Secured Silicon Sector Entry Command is issued, the Secured Silicon Sector Exit command has to be issued to exit Secured Silicon Sector Mode.

Secured Silicon Sector Exit Command

The Secured Silicon Sector Exit command may be issued to exit the Secured Silicon Sector Mode.



Command Definitions

Table I2. S29GL5I2N, S29GL256N, S29GLI28N Command Definitions, xI6

| | | | | | | | Bus | Cycles | (Notes | 2-5) | | | | |
|---|---|--------|--------|--------|-------|---------|---------|--------|--------|------------|------|------------|------|--|
| Command (Notes) Read (6) Reset (7) Manufacturer ID Device ID Sector Protect Verif Secure Device Verif CFI Query (11) Program Write to Buffer | ımand (Notes) | Cycles | Fi | rst | Sec | ond | Th | ird | Fou | urth | Fif | ťth | Six | ĸth |
| | | σ | Addr | Data | Addr | Data | Addr | Data | Addr | Data | Addr | Data | Addr | Data |
| Read | d (6) | 1 | RA | RD | | | | | | | | | | |
| Rese | et (7) | 1 | ххх | FO | | | | | | | | | | |
| | Manufacturer ID | 4 | 555 | AA | 2AA | 55 | 555 | 90 | X00 | 01 | | | | |
| | Device ID | 4 | 555 | AA | 2AA | 55 | 555 | 90 | X01 | 227E | XOE | Note 17 | XOF | Note 17 |
| ect (| Sactor Protact Varify | 4 | 555 | AA | 2AA | 55 | 555 | 90 | (SA) | XX00 | | | | |
| tosel | | 4 | 555 | AA | 244 | 55 | 555 | 90 | X02 | XX01 | | | | |
| Aut | Secure Device Verify (9) | 4 | 555 | AA | 2AA | 55 | 555 | 90 | X03 | Note 10 | | | | |
| CFI | Query (11) | 1 | 55 | 98 | | | | | | | | | | |
| Prog | Iram | 4 | 555 | AA | 2AA | 55 | 555 | AO | PA | PD | | | | |
| Writ | e to Buffer | 3 | 555 | AA | 2AA | 55 | SA | 25 | SA | WC | PA | PD | WBL | PD |
| Prog | ram Buffer to Flash (confirm) | 1 | SA | 29 | | | | | | | | | | |
| Writ | e-to-Buffer-Abort Reset (16) | 3 | 555 | AA | 2AA | 55 | 555 | FO | | | | | | |
| Unic | ck Bypass | 3 | 555 | AA | 2AA | 55 | 555 | 20 | | | | | | |
| Unic | ck Bypass Program (12) | 2 | XXX | AO | PA | PD | | | | | | | | |
| Unlo | ck Bypass Sector Erase (12) | 2 | xxx | 80 | SA | 30 | | | | | | | | |
| Unlo | ck Bypass Chip Erase (12) | 2 | XXX | 80 | XXX | 10 | | | | | | | | |
| Unlo | ck Bypass Reset (13) | 2 | xxx | 90 | XXX | 00 | | | | | | | | |
| Chip | Erase | 6 | 555 | AA | 2AA | 55 | 555 | 80 | 555 | AA | 2AA | 55 | 555 | 10 |
| Sect | or Erase | 6 | 555 | AA | 2AA | 55 | 555 | 80 | 555 | AA | 2AA | 55 | SA | 30 |
| Eras | e Suspend/Program Suspend (14) | 1 | xxx | B0 | | | | | | | | | | |
| Eras | e Resume/Program Resume (15) | 1 | XXX | 30 | | | | | | | | | | |
| | | S | ector | Comm | and D | efiniti | ons | | | | | | | |
| tor | Secured Silicon Sector Entry | 3 | 555 | AA | 2AA | 55 | 555 | 88 | | | | | | |
| Secured Silicon SEctor | Secured Silicon Sector Exit (18) | 4 | 555 | AA | 284 | 55 | 555 | 90 | xx | 00 | | | | |
| | | | egiste | r Com | mand | Set D | efiniti | ons | | | | | | |
| эг | Lock Register Command Set Entry | 3 | 555 | AA | 2AA | 55 | 555 | 40 | | | | | | |
| Lock Register | Lock Register Bits Program (22) | 2 | ххх | AO | ххх | Data | | 1 | 1 | | | 1 | | 1 |
| sk Re | Lock Register Bits Read (22) | 1 | 00 | Data | | | | | | | | | | 1 |
| Loc | Lock Register Command Set Exit (18, 23) | 2 | ххх | 90 | ххх | 00 | | 1 | | | | 1 | | 1 |
| | Passwo | ord | Protec | tion (| Comma | and Se | t Defi | nition | s | | 1 | I | 1 | <u>. </u> |



| | | | | | | | Bus | Cycles | (Notes | ; 2-5) | | | | |
|--------------|---|--------|--------|-----------|----------|----------|--------|----------|---------|----------|------|----------|------|--|
| Con | nmand (Notes) | Cycles | Fii | st | Sec | ond | Th | ird | Fo | urth | Fif | ťh | Six | th |
| | | Ŭ | Addr | Data | Addr | Data | Addr | Data | Addr | Data | Addr | Data | Addr | Data |
| | Password Protection Command Set Entry | 3 | 555 | AA | 2AA | 55 | 555 | 60 | | | | | | |
| | Password Program (20) | 2 | ххх | AO | PWA x | PWD x | | | | | | | | |
| vord | Password Read (19) | 4 | xxx | PWD 0 | 01 | PWD 1 | 02 | PWD 2 | 03 | PWD 3 | | | | |
| Password | Password Unlock (19) | 7 | 00 | 25 | 00 | 03 | 00 | PWD 0 | 01 | PWD 1 | 02 | PWD 2 | _ | PWD 3 |
| | | | 00 | 29 | | | | | | | | | | |
| | Password Protection Command Set Exit (18, 23) | 2 | ххх | 90 | ххх | 00 | | | | | | | | |
| | Non-Volatile | e Se | ctor P | rotec | tion Co | ommai | nd Set | : Defir | nitions | 5 | | | | <u>. </u> |
| | Nonvolatile Sector Protection Command Set Entry | 3 | 555 | AA | 2AA | 55 | 555 | CO | | | | | | |
| | PPB Program (24, 25) | 2 | XXX | AO | SA | 00 | | | | | | | | |
| ррв | All PPB Erase | 2 | XXX | 80 | 00 | 30 | | | | | | | Addr | |
| 4 | PPB Status Read (25) | 1 | SA | RD (0) | | | | | | | | | | |
| | Non-Volatile Sector Protection Command Set Exit (18) | 2 | xxx | 90 | xxx | 00 | | | | | | | | |
| | Global Non-Volatile | Se | ctor P | rotect | tion Fr | eeze (| Comm | and S | et Def | initior | าร | | | |
| | Global Non-Volatile Sector Protection Freeze Command Set Entry | 3 | 555 | AA | 2AA | 55 | 555 | 50 | | | | | | |
| ik Bit | PPB Lock Bit Set (25) | 2 | ххх | AO | ххх | 00 | | | | | | | | |
| PPB Lock Bit | PPB Lock Status Read (25) | 1 | xxx | RD (0) | | | | | | | | | | |
| | Global Non-Volatile Sector Protection Freeze Command Set Exit (18) | 2 | xxx | 90 | xxx | 00 | | | | | | | | |
| | Volatile Sector Protection Command Set Definitions | | | | | | | | | | | | | |
| | Volatile Sector Protection Command Set Entry | 3 | 555 | AA | 2AA | 55 | 555 | EO | | | | | | |
| | DYB Set (24, 25) | 2 | XXX | AO | SA | 00 | | | | | | | | |
| DYB | DYB Clear (25) | 2 | XXX | AO | SA | 01 | | | | | | | | |
| G | DYB Status Read (25) | 1 | SA | RD (0) | | | | | | | | PWD 02 | | |
| | Volatile Sector Protection Command Set Exit (18) | 2 | xxx | 90 | xxx | 00 | | | | | | | | |

Legend:

X = Don't care

RA = Address of the memory to be read.

RD = Data read from location RA during read operation.

PA = Address of the memory location to be programmed. Addresses latch on the falling edge of the WE# or CE# pulse, whichever happens later.

PD = Data to be programmed at location PA. Data latches on the rising edge of the WE# or CE# pulse, whichever happens first.

SA = Address of the sector to be verified (in autoselect mode) or erased. Address bits A_{max} -A16 uniquely select any sector.

WBL = Write Buffer Location. The address must be within the same write buffer page as PA.



WC = Word Count is the number of write buffer locations to load minus 1.

PWD = Password

 $PWD_x = Password word0, word1, word2, and word3.$

DATA = Lock Register Contents: PD(0) = Secured Silicon Sector Protection Bit, PD(1) = Persistent Protection Mode Lock Bit, PD(2) = Password Protection Mode Lock Bit.

- 1. See Table 1 for description of bus operations.
- 2. All values are in hexadecimal.
- 3. Except for the read cycle, and the 4th, 5th, and 6th cycle of the autoselect command sequence, all bus cycles are write cycles.
- 4. Data bits DQ15-DQ8 are don't cares for unlock and command cycles.
- Address bits A_{MAX}:A16 are don't cares for unlock and command cycles, unless SA or PA required. (A_{MAX} is the Highest Address pin.).
- 6. No unlock or command cycles required when reading array data.
- 7. The Reset command is required to return to reading array data when device is in the autoselect mode, or if DQ5 goes high (while the device is providing status data).
- 8. The fourth, fifth, and sixth cycle of the autoselect command sequence is a read cycle.
- 9. The data is 00h for an unprotected sector and 01h for a protected sector. See "Autoselect Command Sequence" for more information. This is same as PPB Status Read except that the protect and unprotect statuses are inverted here.
- 10. The data value for DQ7 is "1" for a serialized and protected OTP region and "0" for an unserialized and unprotected Secured Silicon Sector region. See "Secured Silicon Sector Flash Memory Region" for more information. For S29GLxxxNH: XX18h/18h = Not Factory Locked. XX98h/98h = Factory Locked. For S29GLxxxNL: XX08h/08h = Not Factory Locked. XX88h/88h = Factory Locked.
- 11. Command is valid when device is ready to read array data or when device is in autoselect mode.
- 12. The Unlock-Bypass command is required prior to the Unlock-Bypass-Program command.
- *13. The Unlock-Bypass-Reset command is required to return to reading array data when the device is in the unlock bypass mode.*
- *14. The system may read and program/program suspend in non-erasing sectors, or enter the autoselect mode, when in the Erase Suspend mode. The Erase Suspend command is valid only during a sector erase operation.*
- 15. The Erase Resume/Program Resume command is valid only during the Erase Suspend/Program Suspend modes.
- 16. Issue this command sequence to return to READ mode after detecting device is in a Write-to-Buffer-Abort state. NOTE: the full command sequence is required if resetting out of ABORT while using Unlock Bypass Mode.
- 17. S29GL512NH/L = 2223h/23h, 2201h/01h; S29GL256NH/L = 2222h/22h, 2201h/01h; S29GL128NH/L = 2221h/21h, 2201h/ 01h.
- 18. The Exit command returns the device to reading the array.
- 19. Note that the password portion can be entered or read in any order as long as the entire 64-bit password is entered or read.
- 20. For PWDx, only one portion of the password can be programmed per each "A0" command.
- 21. The All PPB Erase command embeds programming of all PPB bits before erasure.
- 22. All Lock Register bits are one-time programmable. Note that the program state = "0" and the erase state = "1". Also note that of both the Persistent Protection Mode Lock Bit and the Password Protection Mode Lock Bit cannot be programmed at the same time or the Lock Register Bits Program operation will abort and return the device to read mode. Lock Register bits that are reserved for future use will default to "1's". The Lock Register is shipped out as "FFFF's" before Lock Register Bit program execution.
- 23. If any of the Entry command was initiated, an Exit command must be issued to reset the device into read mode. Otherwise the device will hang.
- 24. If ACC = V_{HH} , sector protection will match when ACC = V_{IH}
- 25. Protected State = "00h", Unprotected State = "01h".



Write Operation Status

The device provides several bits to determine the status of a program or erase operation: DQ2, DQ3, DQ5, DQ6, and DQ7. Table 13 and the following subsections describe the function of these bits. DQ7 and DQ6 each offer a method for determining whether a program or erase operation is complete or in progress. The device also provides a hardware-based output signal, RY/BY#, to determine whether an Embedded Program or Erase operation is in progress or has been completed.

Note that all Write Operation Status DQ bits are valid only after 4 µs delay.

DQ7: Data# Polling

The Data# Polling bit, DQ7, indicates to the host system whether an Embedded Program or Erase algorithm is in progress or completed, or whether the device is in Erase Suspend. Data# Polling is valid after the rising edge of the final WE# pulse in the command sequence.

During the Embedded Program algorithm, the device outputs on DQ7 the complement of the datum programmed to DQ7. This DQ7 status also applies to programming during Erase Suspend. When the Embedded Program algorithm is complete, the device outputs the datum programmed to DQ7. The system must provide the program address to read valid status information on DQ7. If a program address falls within a protected sector, Data# Polling on DQ7 is active for approximately 1 μ s, then the device returns to the read mode.

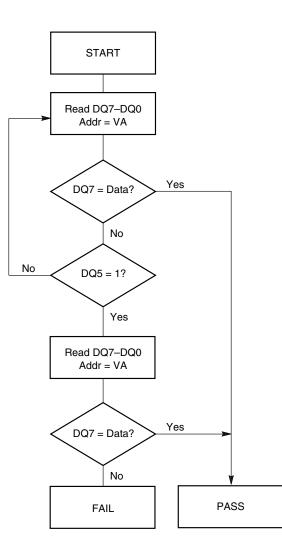
During the Embedded Erase algorithm, Data# Polling produces a "0" on DQ7. When the Embedded Erase algorithm is complete, or if the device enters the Erase Suspend mode, Data# Polling produces a "1" on DQ7. The system must provide an address within any of the sectors selected for erasure to read valid status information on DQ7.

After an erase command sequence is written, if all sectors selected for erasing are protected, Data# Polling on DQ7 is active for approximately 100 µs, then the device returns to the read mode. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected. However, if the system reads DQ7 at an address within a protected sector, the status may not be valid.

Just prior to the completion of an Embedded Program or Erase operation, DQ7 may change asynchronously with DQ0–DQ6 while Output Enable (OE#) is asserted low. That is, the device may change from providing status information to valid data on DQ7. Depending on when the system samples the DQ7 output, it may read the status or valid data. Even if the device has completed the program or erase operation and DQ7 has valid data, the data outputs on DQ0–DQ6 may be still invalid. Valid data on DQ0–DQ7 will appear on successive read cycles.

Table 13 shows the outputs for Data# Polling on DQ7. Figure 5 shows the Data#Polling algorithm. Figure 17 in the AC Characteristics section shows the Data#Polling timing diagram.





Notes:

- 1. VA = Valid address for programming. During a sector erase operation, a valid address is any sector address within the sector being erased. During chip erase, a valid address is any non-protected sector address.
- 2. DQ7 should be rechecked even if DQ5 = "1" because DQ7 may change simultaneously with DQ5.

Figure 5. Data# Polling Algorithm

RY/BY#: Ready/Busy#

The RY/BY# is a dedicated, open-drain output pin which indicates whether an Embedded Algorithm is in progress or complete. The RY/BY# status is valid after the rising edge of the final WE# pulse in the command sequence. Since RY/BY# is an open-drain output, several RY/BY# pins can be tied together in parallel with a pull-up resistor to V_{CC} .

If the output is low (Busy), the device is actively erasing or programming. (This includes programming in the Erase Suspend mode.) If the output is high (Ready), the device is in the read mode, the standby mode, or in the erase-suspend-read mode. Table 13 shows the outputs for RY/BY#.



DQ6: Toggle Bit I

Toggle Bit I on DQ6 indicates whether an Embedded Program or Erase algorithm is in progress or complete, or whether the device has entered the Erase Suspend mode. Toggle Bit I may be read at any address, and is valid after the rising edge of the final WE# pulse in the command sequence (prior to the program or erase operation), and during the sector erase time-out.

During an Embedded Program or Erase algorithm operation, successive read cycles to any address cause DQ6 to toggle. The system may use either OE# or CE# to control the read cycles. When the operation is complete, DQ6 stops toggling.

After an erase command sequence is written, if all sectors selected for erasing are protected, DQ6 toggles for approximately 100 μ s, then returns to reading array data. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected.

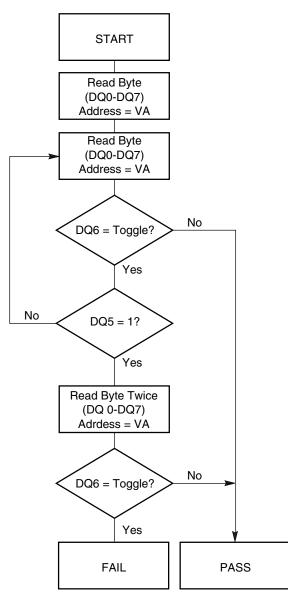
The system can use DQ6 and DQ2 together to determine whether a sector is actively erasing or is erase-suspended. When the device is actively erasing (that is, the Embedded Erase algorithm is in progress), DQ6 toggles. When the device enters the Erase Suspend mode, DQ6 stops toggling. However, the system must also use DQ2 to determine which sectors are erasing or erase-suspended. Alternatively, the system can use DQ7 (see the subsection on DQ7: Data# Polling).

If a program address falls within a protected sector, DQ6 toggles for approximately 1 μs after the program command sequence is written, then returns to reading array data.

DQ6 also toggles during the erase-suspend-program mode, and stops toggling once the Embedded Program algorithm is complete.

Table 13 shows the outputs for Toggle Bit I on DQ6. Figure 6 shows the toggle bit algorithm. Figure 18 in the "AC Characteristics" section shows the toggle bit timing diagrams. Figure 19 shows the differences between DQ2 and DQ6 in graphical form. See also the subsection on DQ2: Toggle Bit II.





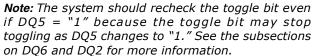


Figure 6. Toggle Bit Algorithm

DQ2: Toggle Bit II

The "Toggle Bit II" on DQ2, when used with DQ6, indicates whether a particular sector is actively erasing (that is, the Embedded Erase algorithm is in progress), or whether that sector is erase-suspended. Toggle Bit II is valid after the rising edge of the final WE# pulse in the command sequence.

DQ2 toggles when the system reads at addresses within those sectors that have been selected for erasure. (The system may use either OE# or CE# to control the



read cycles.) But DQ2 cannot distinguish whether the sector is actively erasing or is erase-suspended. DQ6, by comparison, indicates whether the device is actively erasing, or is in Erase Suspend, but cannot distinguish which sectors are selected for erasure. Thus, both status bits are required for sector and mode information. Refer to Table 13 to compare outputs for DQ2 and DQ6.

Figure 6 shows the toggle bit algorithm in flowchart form, and the section "DQ2: Toggle Bit II" explains the algorithm. See also the RY/BY#: Ready/Busy# subsection. Figure 18 shows the toggle bit timing diagram. Figure 19 shows the differences between DQ2 and DQ6 in graphical form.

Reading Toggle Bits DQ6/DQ2

Refer to Figure 6 and Figure 19 for the following discussion. Whenever the system initially begins reading toggle bit status, it must read DQ7–DQ0 at least twice in a row to determine whether a toggle bit is toggling. Typically, the system would note and store the value of the toggle bit after the first read. After the second read, the system would compare the new value of the toggle bit with the first. If the toggle bit is not toggling, the device has completed the program or erase operation. The system can read array data on DQ7–DQ0 on the following read cycle.

However, if after the initial two read cycles, the system determines that the toggle bit is still toggling, the system also should note whether the value of DQ5 is high (see the section on DQ5). If it is, the system should then determine again whether the toggle bit is toggling, since the toggle bit may have stopped toggling just as DQ5 went high. If the toggle bit is no longer toggling, the device has successfully completed the program or erase operation. If it is still toggling, the device did not completed the operation successfully, and the system must write the reset command to return to reading array data.

The remaining scenario is that the system initially determines that the toggle bit is toggling and DQ5 has not gone high. The system may continue to monitor the toggle bit and DQ5 through successive read cycles, determining the status as described in the previous paragraph. Alternatively, it may choose to perform other system tasks. In this case, the system must start at the beginning of the algorithm when it returns to determine the status of the operation (top of Figure 6).

DQ5: Exceeded Timing Limits

DQ5 indicates whether the program, erase, or write-to-buffer time has exceeded a specified internal pulse count limit. Under these conditions DQ5 produces a "1," indicating that the program or erase cycle was not successfully completed.

The device may output a "1" on DQ5 if the system tries to program a "1" to a location that was previously programmed to "0." **Only an erase operation can change a "0" back to a "1."** Under this condition, the device halts the operation, and when the timing limit has been exceeded, DQ5 produces a "1."

In all these cases, the system must write the reset command to return the device to the reading the array (or to erase-suspend-read if the device was previously in the erase-suspend-program mode).

DQ3: Sector Erase Timer

After writing a sector erase command sequence, the system may read DQ3 to determine whether or not erasure has begun. (The sector erase timer does not apply to the chip erase command.) If additional sectors are selected for erasure,



the entire time-out also applies after each additional sector erase command. When the time-out period is complete, DQ3 switches from a "0" to a "1." If the time between additional sector erase commands from the system can be assumed to be less than 50 μ s, the system need not monitor DQ3. See also the Sector Erase Command Sequence section.

After the sector erase command is written, the system should read the status of DQ7 (Data# Polling) or DQ6 (Toggle Bit I) to ensure that the device has accepted the command sequence, and then read DQ3. If DQ3 is "1," the Embedded Erase algorithm has begun; all further commands (except Erase Suspend) are ignored until the erase operation is complete. If DQ3 is "0," the device will accept additional sector erase commands. To ensure the command has been accepted, the system software should check the status of DQ3 prior to and following each subsequent sector erase command. If DQ3 is high on the second status check, the last command might not have been accepted.

Table 13 shows the status of DQ3 relative to the other status bits.

DQI: Write-to-Buffer Abort

DQ1 indicates whether a Write-to-Buffer operation was aborted. Under these conditions DQ1 produces a "1". The system must issue the Write-to-Buffer-Abort-Reset command sequence to return the device to reading array data. See Write Buffer section for more details.

| | Stat | us | DQ7 (Note 2) | DQ6 | DQ5 (Note 1) | DQ3 | DQ2 (Note 2) | DQ1 | RY/ BY# | | |
|--------------------------|-------------------------|---------------------------------|-----------------|-----------------------|-----------------|--------|-----------------|-----------------|------------|--|--|
| Standard | Embedded F | Program Algorithm | DQ7# | Toggle | 0 | N/A | No toggle | 0 | 0 | | |
| Mode | Embedded | 0 | Toggle | 0 | 1 | Toggle | N/A | 0 | | | |
| Program Suspend | Program- | Program-Suspended Sector | | Invalid (not allowed) | | | | | | | |
| Mode | Suspend Read | Non-Program Suspended Sector | Data | | | | | | | | |
| | Erase- | Erase-Suspended Sector | 1 | No toggle | 0 | N/A | Toggle | N/A | 1 | | |
| Erase Suspend Mode | Suspend Read | Non-Erase Suspended Sector | Data | | | | | | 1 | | |
| | Erase-Susp (Embedded | end-Program Program) | DQ7# | Toggle | 0 | N/A | N/A | N/A | 0 | | |
| Write-to- | Busy (Note | 3) | DQ7# | Toggle | 0 | N/A | N/A | O N/A N/A | 0 | | |
| Buffer | Abort (Note | 2 4) | DQ7# | Toggle | 0 | N/A | N/A | | 0 | | |

Table I3. Write Operation Status

Notes:

1. DQ5 switches to '1' when an Embedded Program, Embedded Erase, or Write-to-Buffer operation has exceeded the maximum timing limits. Refer to the section on DQ5 for more information.

2. DQ7 and DQ2 require a valid address when reading status information. Refer to the appropriate subsection for further details.

3. The Data# Polling algorithm should be used to monitor the last loaded write-buffer address location.

4. DQ1 switches to '1' when the device has aborted the write-to-buffer operation.



Absolute Maximum Ratings

| Storage Temperature, Plastic Packages65°C to +150°C |
|---|
| Ambient Temperature with Power Applied |
| Voltage with Respect to Ground: |
| V_{CC} (Note 1) |
| V_{10} |
| A9, OE#, and ACC (Note 2) |
| All other pins (Note 1) |
| Output Short Circuit Current (Note 3) |
| |

Notes:

- 1. Minimum DC voltage on input or I/Os is -0.5 V. During voltage transitions, inputs or I/Os may overshoot V_{SS} to -2.0 V for periods of up to 20 ns. See Figure 7. Maximum DC voltage on input or I/Os is V_{CC} + 0.5 V. During voltage transitions, input or I/O pins may overshoot to V_{CC} + 2.0 V for periods up to 20 ns. See Figure 8.
- Minimum DC input voltage on pins A9, OE#, and ACC is −0.5 V. During voltage transitions, A9, OE#, and ACC may overshoot V_{SS} to −2.0 V for periods of up to 20 ns. See Figure 7. Maximum DC input voltage on pin A9, OE#, and ACC is +12.5 V which may overshoot to +14.0V for periods up to 20 ns.
- *3.* No more than one output may be shorted to ground at a time. Duration of the short circuit should not be greater than one second.
- 4. Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this data sheet is not implied. Exposure of the device to absolute maximum rating conditions for extended periods may affect device reliability.

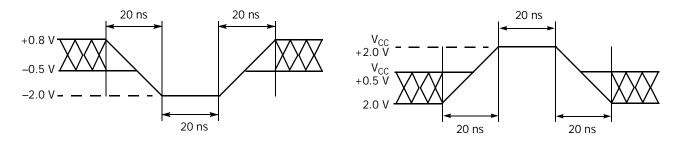


Figure 7. Maximum Negative Overshoot Waveform

Figure 8. Maximum Positive Overshoot Waveform

Operating Ranges

Industrial (I) Devices

| Ambient Temperature (T _A) | 40°C to +85°C |
|---------------------------------------|-------------------------|
| Supply Voltages | |
| V _{CC} | |
| v ₁₀ (Note 2) | + 1.650 (0 1.950 0) VCC |

Notes:

1. Operating ranges define those limits between which the functionality of the device is guaranteed.

2. See "Product Selector Guide" section on page 20.



CMOS Compatible-S29GLI28N, S29GL256N, S29GL5I2N

| Parameter Symbol | Parameter Description (Notes) | Test Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|------------------------|-----|------------------------|------|
| L., | Input Load Current (1) | $V_{IN} = V_{SS}$ to V_{CC} , | | | WP/ACC: ±2.0 | |
| ILI | | $V_{CC} = V_{CC max}$ | | | Others: ±1.0 | μA |
| I _{LIT} | A9 Input Load Current | $V_{CC} = V_{CC max}; A9 = 12.5 V$ | | | 35 | μΑ |
| I _{LO} | Output Leakage Current | $V_{OUT} = V_{SS}$ to V_{CC} , $V_{CC} = V_{CC max}$ | | | ±1.0 | μΑ |
| | V Active Devel Comment (1) | $CE\# = V_{IL}, OE\# = V_{IH}, V_{CC} = V_{CCmax},$ f = 5 MHz | | 30 | 50 | mA |
| I _{CC1} | V _{CC} Active Read Current (1) | $\begin{array}{l} CE\# = V_{IL}, OE\# = V_{IH}, V_{CC} = V_{CCmax}, \\ f = 10 \; MHz \end{array}$ | | 60 | 90 | |
| | V. John Deer Deel Convert (1) | $\begin{array}{l} CE\# = V_{IL,}OE\# = V_{IH,}V_{CC} = V_{CCmax}\\ f = 10\;MHz \end{array}$ | | 1 | 10 | |
| I _{CC2} | V _{CC} Intra-Page Read Current (1) | $\begin{array}{l} CE\#=V_{IL},OE\#=V_{IH},V_{CC}=V_{CCmax},\\ f{=}33\;MHz \end{array}$ | | 5 | 20 | - mA |
| I _{CC3} | V _{CC} Active Erase/Program Current (2, 3) | $CE\# = V_{IL}, OE\# = V_{IH}, V_{CC} = V_{CCmax}$ | | 50 | 80 | mA |
| I _{CC4} | V _{CC} Standby Current | CE#, RESET# = V_{SS} \pm 0.3 V, OE# = V_{IH}, V_{CC} = $V_{CCmax} V_{IL}$ = V_{SS} + 0.3 V/- 0.1V | | 1 | 5 | mA |
| I _{CC5} | V _{CC} Reset Current | $V_{CC} = V_{CCmax};$ $V_{IL} = V_{SS} + 0.3 V/-0.1V,$ $RESET\# = V_{SS} \pm 0.3 V$ | | 1 | 5 | μΑ |
| I _{CC6} | Automatic Sleep Mode (4) | | | 1 | 5 | μΑ |
| I _{ACC} | ACC Accelerated Program Current | $CE\# = V_{IL}, OE\# = V_{IH}, V_{CC} = V_{CCmax},$ | WP#/ACC pin | 10 | 20 | mA |
| Acc | | WP#/ACC = V _{IH} | V _{CC} pin | 50 | 80 | |
| V _{IL} | Input Low Voltage (5) | | -0.1 | | 0.3 x V _{IO} | V |
| V _{IH} | Input High Voltage (5) | | 0.7 x V _{IO} | | V _{IO} + 0.3 | V |
| V _{HH} | Voltage for ACC Erase/Program Acceleration | $V_{\rm CC} = 2.7 - 3.6 \rm V$ | 11.5 | | 12.5 | v |
| V _{ID} | Voltage for Autoselect and Temporary Sector Unprotect | $V_{CC} = 2.7 - 3.6 V$ | 11.5 | | 12.5 | v |
| V _{OL} | Output Low Voltage (5) | I _{OL} = 100 μA | | | 0.15 x V _{IO} | V |
| V _{OH} | Output High Voltage (5) | Ι _{ΟΗ} = -100 μΑ | 0.85 x V _{IO} | | | V |
| V _{LKO} | Low V _{CC} Lock-Out Voltage (3) | | 2.3 | | 2.5 | V |

Notes:

1. The I_{CC} current listed is typically less than 2 mA/MHz, with OE# at V_{IH}.

- 2. I_{CC} active while Embedded Erase or Embedded Program or Write Buffer Programming is in progress.
- 3. Not 100% tested.
- 4. Automatic sleep mode enables the lower power mode when addresses remain stable tor t_{ACC} + 30 ns.
- 5. $V_{IO} = 1.65 1.95 V \text{ or } 2.7 3.6 V$
- 6. $V_{CC} = 3 V$ and $V_{IO} = 3V$ or 1.8V. When V_{IO} is at 1.8V, I/O pins cannot operate at 3V.



Test Conditions

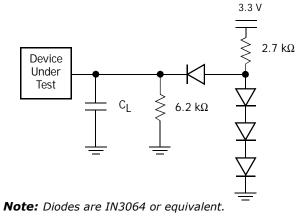


Table I4. Test Specifications

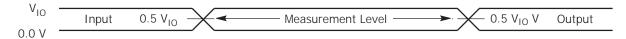
| Test Condition | All Speeds | Unit |
|--|---------------------|------|
| Output Load | 1 TTL gate | |
| Output Load Capacitance, C _L (including jig capacitance) | 30 | pF |
| Input Rise and Fall Times | 5 | ns |
| Input Pulse Levels | 0.0–V _{IO} | V |
| Input timing measurement reference levels (See Note) | 0.5V _{IO} | V |
| Output timing measurement reference levels | 0.5 V _{IO} | V |

Figure 9. Test Setup

Note: If $V_{IO} < V_{CC}$, the reference level is 0.5 V_{IO} .

Key to Switching Waveforms

| Waveform | Inputs | Outputs |
|----------|----------------------------------|--|
| | | Steady |
| | Cha | inging from H to L |
| | Cha | nging from L to H |
| XXXXXX | Don't Care, Any Change Permitted | Changing, State Unknown |
| | Does Not Apply | Center Line is High Impedance State (High Z) |



Note: If $V_{IO} < V_{CC'}$ the input measurement reference level is 0.5 V_{IO} .





Read-Only Operations-S29GLI28N, S29GL256N, S29GL5I2N

| Paran | neter | | | | | S | | | | |
|-------------------|-------------------|--|-----------------------------|--------------------------------|-------|----|-----|-----|-----|------|
| JEDEC | Std. | Description | | Test Setup | | 90 | 100 | 110 | 110 | Unit |
| + | + | Read Cycle Time | | $V_{1O} = V_{CC} = 3 V$ | Min | 90 | 100 | 110 | | ns |
| t _{AVAV} | t _{RC} | | | $V_{10} = 1.8 V, V_{CC} = 3 V$ | | | | | 110 | 115 |
| + | + | Address to Output Delay | y | $V_{IO} = V_{CC} = 3 V$ | Мах | 90 | 100 | 110 | | ns |
| t _{AVQV} | t _{ACC} | (Note 2) | | $V_{10} = 1.8 V, V_{CC} = 3 V$ | IVIAX | | | | 110 | 115 |
| + | + | Chip Enable to Output D | Delay | $V_{IO} = V_{CC} = 3 V$ | Мах | 90 | 100 | 110 | | |
| t _{ELQV} | t _{CE} | (Note 3) | - | $V_{10} = 1.8 V, V_{CC} = 3 V$ | wax | | | | 110 | ns |
| | t _{PACC} | Page Access Time | | | Max | 25 | 25 | 25 | 30 | ns |
| t _{GLQV} | t _{OE} | Output Enable to Outpu | t Delay | | Max | 25 | 25 | 35 | 35 | ns |
| t _{EHQZ} | t _{DF} | Chip Enable to Output H | ligh Z (Note 1) | | Max | | 2 | 0 | | ns |
| t _{GHQZ} | t _{DF} | Output Enable to Outpu (Note 1) | t High Z | | Max | | 2 | 0 | | ns |
| t _{AXQX} | t _{OH} | Output Hold Time From A or OE#, Whichever Occ | | | Min | | C |) | | ns |
| | | Output Enchla Llaid | Read | | Min | | C |) | | ns |
| | t _{OEH} | Output Enable Hold Time (Note 1) | Toggle and Data# Polling | | Min | | 1 | 0 | | ns |
| | t _{CEH} | Chip Enable Hold Time | Read | | Min | | 3 | 5 | | ns |

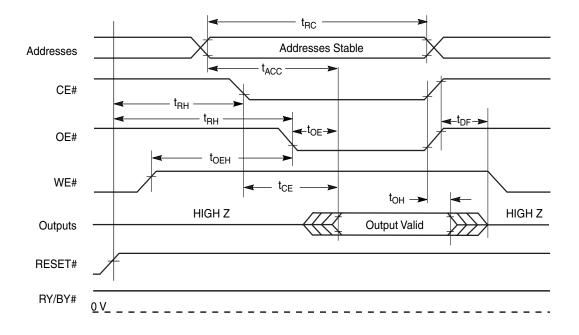
Notes:

1. Not 100% tested.

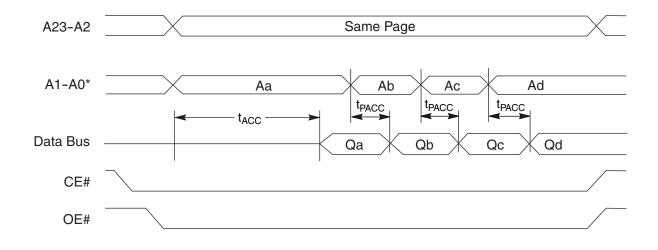
2. CE#, OE# = V_{IL}

- 3. $OE\# = V_{IL}$
- 4. See Figure 9 and Table 14 for test specifications.
- 5. Unless otherwise indicated, AC specifications for 90 ns, 100 ns, and 110 ns speed options are tested with $V_{IO} = V_{CC} = 3 V$. AC specifications for 110 ns speed options are tested with $V_{IO} = 1.8 V$ and $V_{CC} = 3.0 V$.









1. Figure shows word mode.





Hardware Reset (RESET#)

| Paran | neter | | | | |
|-------|--------------------|--|-----|----------------|------|
| JEDEC | Std. | Description | | Speed (Note 2) | Unit |
| | t _{Ready} | RESET# Pin Low (During Embedded Algorithms) to Read Mode (See Note) | Max | 20 | ns |
| | t _{Ready} | RESET# Pin Low (NOT During Embedded Algorithms) to Read Mode (See Note) | | 500 | ns |
| | t _{RP} | RESET# Pulse Width | Min | 500 | ns |
| | t _{RH} | Reset High Time Before Read (See Note) | Min | 50 | ns |
| | t _{RPD} | RESET# Low to Standby Mode | Min | 20 | μs |
| | t _{RB} | RY/BY# Recovery Time | Min | 0 | ns |

- 1. Not 100% tested. If ramp rate is equal to or faster than 1V/100μs with a falling edge of the RESET# pin initiated, the RESET# pin needs to be held low only for 100μs for power-up.
- 2. Next generation devices may have different reset speeds.

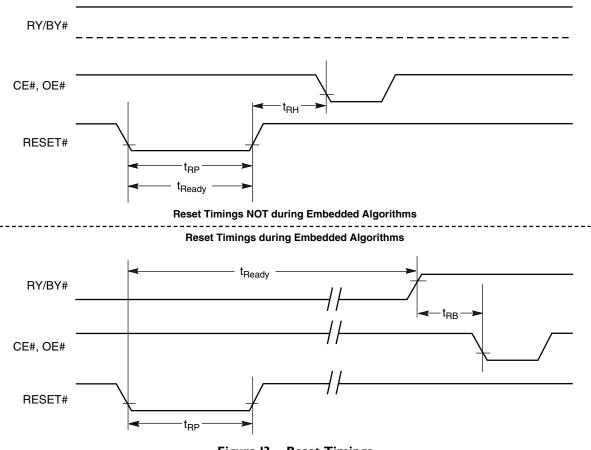


Figure I3. Reset Timings

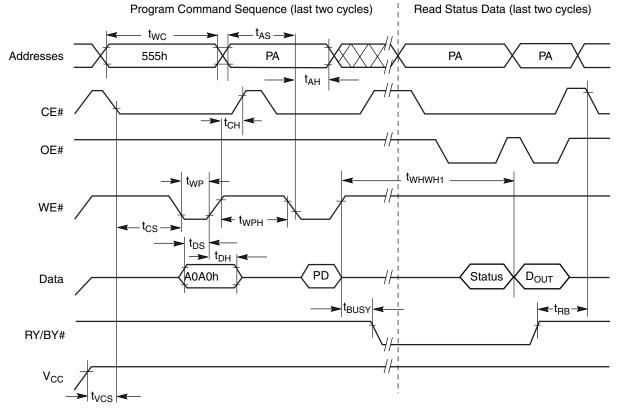


Erase and Program Operations-S29GLI28N, S29GL256N, S29GL5I2N

| Parar | neter | | | | | Speed | l Options | | |
|--------------------|--------------------|---|-------------|-----|-----|-------|-----------|-----|------|
| JEDEC | Std. | Description | | | 90 | 100 | 110 | 110 | Unit |
| t _{AVAV} | t _{WC} | Write Cycle Time (Note 1) | | Min | 90 | 100 | 110 | 110 | ns |
| t _{AVWL} | t _{AS} | Address Setup Time | | Min | 0 | | | ns | |
| | t _{ASO} | Address Setup Time to OE# low du bit polling | ring toggle | Min | | | 15 | | ns |
| t _{WLAX} | t _{AH} | Address Hold Time | | Min | | | 45 | | ns |
| | t _{AHT} | Address Hold Time From CE# or OE# high during toggle bit polling Min 0 | | 0 | | ns | | | |
| t _{DVWH} | t _{DS} | Data Setup Time | | Min | | | 45 | | ns |
| t _{WHDX} | t _{DH} | Data Hold Time | | Min | | | 0 | | ns |
| | t _{CEPH} | CE# High during toggle bit polling | | Min | | | 20 | | |
| | t _{OEPH} | Output Enable High during toggle k | oit polling | Min | 20 | | | ns | |
| t _{GHWL} | t _{GHWL} | Read Recovery Time Before Write (OE# High to WE# Low) | | Min | 0 | | | | ns |
| t _{ELWL} | t _{CS} | CE# Setup Time | | Min | | | 0 | | ns |
| t _{WHEH} | t _{CH} | CE# Hold Time | | Min | | | 0 | | ns |
| t _{WLWH} | t _{WP} | Write Pulse Width | | Min | 35 | | | | ns |
| t _{WHDL} | t _{WPH} | Write Pulse Width High | | Min | | | 30 | | ns |
| | | Write Buffer Program Operation (N | otes 2, 3) | Тур | | | 240 | | μs |
| | | Effective Write Buffer Program Operation (Notes 2, 4) | Per Word | Тур | | | 15 | | μs |
| t _{WHWH1} | t _{WHWH1} | Accelerated Effective Write Buffer Program Operation (Notes 2, 4) | Per Word | Тур | | - | 13.5 | | μs |
| | | Program Operation (Note 2) | Word | Тур | | | 60 | | μs |
| | | Accelerated Programming Operation (Note 2) | Word | Тур | | | 54 | | μs |
| t _{WHWH2} | t _{WHWH2} | 2 Sector Erase Operation (Note 2) | | Тур | 0.5 | | | | sec |
| | t _{VHH} | V _{HH} Rise and Fall Time (Note 1) | | Min | | | 250 | | ns |
| | t _{VCS} | V _{CC} Setup Time (Note 1) | | Min | 50 | | | | μs |
| | t _{BUSY} | Erase/Program Valid to RY/BY# De | lay | Min | | | 90 | | ns |

- 1. Not 100% tested.
- 2. See the "Erase and Programming Performance" section for more information.
- 3. For 1–16 words/1–32 bytes programmed.
- 4. Effective write buffer specification is based upon a 16-word/32-byte write buffer operation.
- 5. Unless otherwise indicated, AC specifications for 90 ns, 100 ns, and 110 ns speed options are tested with $V_{IO} = V_{CC}$ = 3 V. AC specifications for 110 ns speed options are tested with $V_{IO} = 1.8$ V and $V_{CC} = 3.0$ V.





Notes:

- 1. PA = program address, PD = program data, D_{OUT} is the true data at the program address.
- 2. Illustration shows device in word mode.



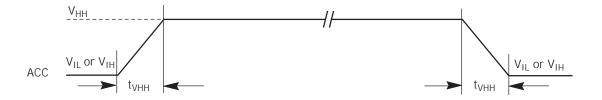
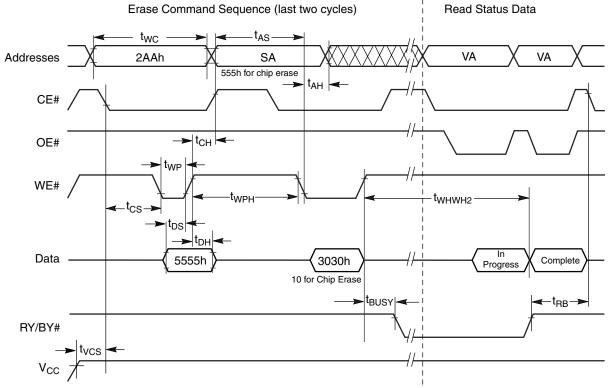


Figure I5. Accelerated Program Timing Diagram

- 1. Not 100% tested.
- 2. CE#, $OE\# = V_{IL}$
- 3. $OE\# = V_{IL}$
- 4. See Figure 9 and Table 14 for test specifications.



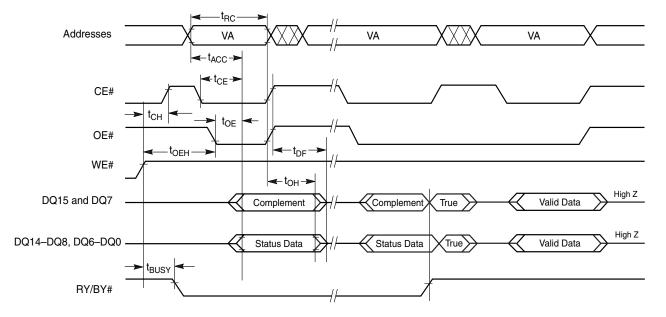


Notes:

- 1. SA = sector address (for Sector Erase), VA = Valid Address for reading status data (see "Write Operation Status".
- 2. These waveforms are for the word mode.

Figure I6. Chip/Sector Erase Operation Timings



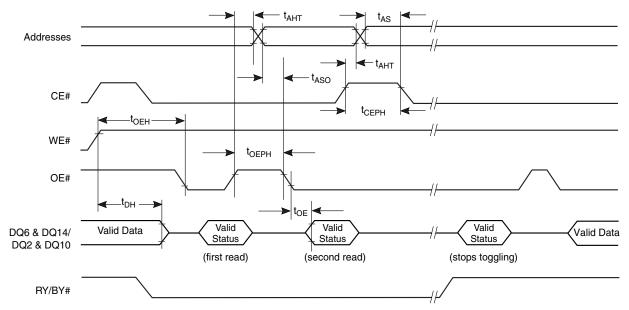


Note:

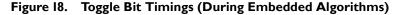
- 1. VA = Valid address. Illustration shows first status cycle after command sequence, last status read cycle, and array data read cycle.
- 2. t_{OE} for data polling is 45 ns when V_{IO} = 1.65 to 2.7 V and is 35 ns when V_{IO} = 2.7 to 3.6 V

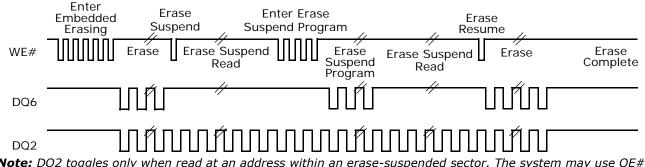
Figure I7. Data# Polling Timings (During Embedded Algorithms)





Note: VA = Valid address; not required for DQ6. Illustration shows first two status cycle after command sequence, last status read cycle, and array data read cycle





Note: DQ2 toggles only when read at an address within an erase-suspended sector. The system may use OE# or CE# to toggle DQ2 and DQ6.

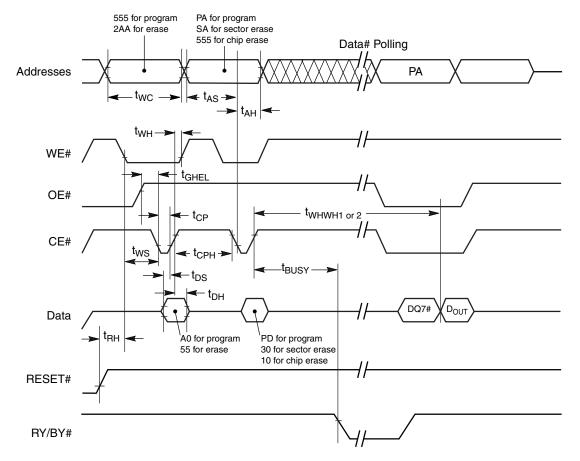
Figure 19. DQ2 vs. DQ6

Alternate CE# Controlled Erase and Program Operations-S29GL128N, S29GL256N, S29GL512N

| Parar | meter | | | | | Speed | Options | | |
|--------------------|--------------------|---|-------------------------------------|-----|----|-------|---------|-----|------|
| JEDEC | Std. | Description | | | 90 | 100 | 110 | 110 | Unit |
| t _{AVAV} | t _{WC} | Write Cycle Time (Note 1) | | Min | 90 | 100 | 110 | 110 | ns |
| t _{AVWL} | t _{AS} | Address Setup Time | | Min | | | 0 | | ns |
| | T _{ASO} | Address Setup Time to OE# I toggle bit polling | low during | Min | 15 | | | | ns |
| t _{ELAX} | t _{AH} | Address Hold Time | | Min | | | 45 | | ns |
| | t _{AHT} | Address Hold Time From CE# during toggle bit polling | old Time From CE# or OE# high Min 0 | | ns | | | | |
| t _{DVEH} | t _{DS} | Data Setup Time | | Min | | | 45 | | ns |
| t _{EHDX} | t _{DH} | Data Hold Time | | Min | | | 0 | | ns |
| | t _{CEPH} | CE# High during toggle bit p | olling | Min | | | 20 | | ns |
| | t _{OEPH} | OE# High during toggle bit p | olling | Min | | | 20 | | ns |
| t _{GHEL} | t _{GHEL} | Read Recovery Time Before V (OE# High to WE# Low) | Write | Min | | 0 | | ns | |
| t _{WLEL} | t _{WS} | WE# Setup Time | | Min | | 0 | | | ns |
| t _{EHWH} | t _{WH} | WE# Hold Time | | Min | | | 0 | | ns |
| t _{ELEH} | t _{CP} | CE# Pulse Width | | Min | | | 35 | | ns |
| t _{EHEL} | t _{CPH} | CE# Pulse Width High | | Min | | | 30 | | ns |
| | | Write Buffer Program Operati 3) | ion (Notes 2, | Тур | | : | 240 | | μs |
| | | Effective Write Buffer Program Operation (Notes 2, 4) | Per Word | Тур | | | 15 | | μs |
| t _{WHWH1} | t _{WHWH1} | Effective Accelerated Write Buffer Program Operation (Notes 2, 4) | Per Word | Тур | | | 13.5 | | μs |
| | | Program Operation (Note 2) | Word | Тур | | | 60 | | μs |
| | | Accelerated Programming Operation (Note 2) | Word | Тур | | | 54 | | μs |
| t _{WHWH2} | t _{WHWH2} | Sector Erase Operation (Note | e 2) | Тур | | | 0.5 | | sec |

- 1. Not 100% tested.
- 2. See the "AC Characteristics" section for more information.
- 3. For 1–16 words/1–32 bytes programmed.
- 4. Effective write buffer specification is based upon a 16-word/32-byte write buffer operation.
- 5. Unless otherwise indicated, AC specifications for 90 ns, 100ns, and 110 ns speed options are tested with $V_{IO} = V_{CC}$ = 3 V. AC specifications for 110 ns speed options are tested with $V_{IO} = 1.8$ V and $V_{CC} = 3.0$ V.





Notes:

- 1. Figure indicates last two bus cycles of a program or erase operation.
- 2. PA = program address, SA = sector address, PD = program data.
- 3. DQ7# is the complement of the data written to the device. D_{OUT} is the data written to the device.
- 4. Waveforms are for the word mode.

Figure 20. Alternate CE# Controlled Write (Erase/Program) Operation Timings



Erase And Programming Performance

| Parameter | | Тур (Note 1) | Max (Note 2) | Unit | Comments |
|--|-----------|-----------------|-----------------|------|--|
| Sector Erase Time | | 0.5 | 3.5 | sec | |
| | S29GL128N | 64 | 256 | | Excludes 00h |
| Chip Erase Time | S29GL256N | 128 | 512 | sec | programming prior to erasure (Note 5) |
| | S29GL512N | 256 | 1024 | | |
| Total Write Buffer Programming Time (Note 3) | | 240 | | μs | |
| Total Accelerated Effective Write Buffer Programming Time (Note 3) | | 200 | | μs | Excludes system level overhead (Note 6) |
| | S29GL128N | 123 | | | |
| Chip Program Time | S29GL256N | 246 | | sec | |
| | S29GL512N | 492 | | | |

Notes:

1. Typical program and erase times assume the following conditions: 25°C, 3.0 V V_{CC}, 10,000 cycles, checkerboard pattern.

- 2. Under worst case conditions of 90°C, $V_{CC} = 3.0 V$, 100,000 cycles.
- 3. Effective write buffer specification is based upon a 16-word write buffer operation.
- 4. The typical chip programming time is considerably less than the maximum chip programming time listed, since most words program faster than the maximum program times listed.
- 5. In the pre-programming step of the Embedded Erase algorithm, all bits are programmed to 00h before erasure.
- 6. System-level overhead is the time required to execute the two- or four-bus-cycle sequence for the program command. See Table 12 for further information on command definitions.

TSOP Pin and BGA Package Capacitance

| Parameter Symbol | Parameter Description | Test S | etup | Тур | Max | Unit |
|------------------|-------------------------|---------------|------|-----|-----|------|
| 6 | Input Conscitonce | N O | TSOP | 6 | 7.5 | pF |
| C _{IN} | Input Capacitance | $V_{IN} = 0$ | BGA | 4.2 | 5.0 | pF |
| | Output Canaditanaa | | TSOP | 8.5 | 12 | pF |
| C _{OUT} | Output Capacitance | $V_{OUT} = 0$ | BGA | 5.4 | 6.5 | pF |
| C C | Control Din Consoltance | N/ 0 | TSOP | 7.5 | 9 | pF |
| C _{IN2} | Control Pin Capacitance | $V_{IN} = 0$ | BGA | 3.9 | 4.7 | pF |

Notes:

1. Sampled, not 100% tested.

2. Test conditions $T_A = 25$ °C, f = 1.0 MHz.



pSRAM Type 7

l6Mb (IM word x l6-bit)

32Mb (2M word x 16-bit)

64Mb (4M word x l6-bit)

CMOS IM/2M/4M-Word x I6-bit Fast Cycle Random Access Memory with Low Power SRAM Interface

Features

- Asynchronous SRAM Interface
- Fast Access Time
 - tCE = tAA = 60ns max (16M)
 - tCE = tAA = 65ns max (32M/64M)
- 8 words Page Access Capability
- tPAA = 20ns max (32M/64M)
- Low Voltage Operating Condition
 - VDD = +2.7V to +3.1V
- Wide Operating Temperature
 - TA = -30° C to $+85^{\circ}$ C
- Byte Control by LB and UB
- Various Power Down modes
 - Sleep (16M)
 - Sleep, 4M-bit Partial, or 8M-bit Partial (32M)
 - Sleep, 8M-bit Partial, or 16M-bit Partial (64M)

Pin Description

| Pin Name | Description |
|-----------------------------------|--|
| A ₂₁ to A ₀ | Address Input: A_{19} to A_0 for 16M, A_{20} to A_0 for 32M, A_{21} to A_0 for 64M |
| CE1# | Chip Enable (Low Active) |
| CE2# | Chip Enable (High Active) |
| WE# | Write Enable (Low Active) |
| OE# | Output Enable (Low Active) |
| UB# | Upper Byte Control (Low Active) |
| LB# | Lower Byte Control (Low Active) |
| DQ ₁₆ -9 | Upper Byte Data Input/Output |
| DQ ₈₋₁ | Lower Byte Data Input/Output |
| V _{DD} | Power Supply |
| V _{SS} | Ground |



Functional Description

| Mode | CE2# | CE1# | WE# | OE# | LB# | UB# | A ₂₁₋₀ | DQ8-1 | DQ ₁₆₋₉ |
|--------------------------|------|------|-----|-----|-----|-----|-------------------|--------------|--------------------|
| Standby (Deselect) | Н | Н | Х | Х | Х | Х | Х | High-Z | High-Z |
| Output Disable (Note 1) | | | Н | Н | Х | Х | Note 3 | High-Z | High-Z |
| Output Disable (No Read) | | | | | Н | Н | Valid | High-Z | High-Z |
| Read (Upper Byte) | | | н | L | Н | L | Valid | High-Z | Output Valid |
| Read (Lower Byte) | | | | | L | Н | Valid | Output Valid | High-Z |
| Read (Word) | н | L | | | L | L | Valid | Output Valid | Output Valid |
| No Write | | | | | Н | Н | Valid | Invalid | Invalid |
| Write (Upper Byte) | | | | | Н | L | Valid | Invalid | Input Valid |
| Write (Lower Byte) | | | L | Н | L | Н | Valid | Input Valid | Invalid |
| Write (Word) | | | | | L | L | Valid | Input Valid | Input Valid |
| Power Down | L | Х | Х | Х | Х | Х | Х | High-Z | High-Z |

Legend: $L = V_{IL}$, $H = V_{IH}$, X can be either V_{IL} or V_{IH} , High-Z = High Impedance.

Notes:

- 1. Should not be kept this logic condition longer than 1 ms. Please contact local Spansion representative for the relaxation of 1ms limitation.
- 2. Power Down mode can be entered from Standby state and all DQ pins are in High-Z state. Data retention depends on the selection of the Power-Down Program, 16M has data retention in all modes except Power Down. Refer to Power Down for details.
- 3. Can be either V_{IL} or V_{IH} but must be valid before Read or Write.

Power Down (for 32M, 64M Only)

Power Down

The Power Down is a low-power idle state controlled by CE2. CE2 Low drives the device in power-down mode and maintains the low-power idle state as long as CE2 is kept Low. CE2 High resumes the device from power-down mode. These devices have three power-down modes. These can be programmed by series of read/write operation. Each mode has following features.

| | 32M | | 64M | | | | |
|-----------------|----------------|--------------------------|-----------------|----------------|-------------------|--|--|
| Mode | Retention Data | Retention Address | Mode | Retention Data | Retention Address | | |
| Sleep (default) | No | N/A | Sleep (default) | No | N/A | | |
| 4M Partial | 4M bit | 00000h to 3FFFFh | 8M Partial | 8M bit | 00000h to 7FFFFh | | |
| 8M Partial | 8M bit | 00000h to 7FFFFh | 16M Partial | 16M bit | 00000h to FFFFFh | | |

The default state is Sleep and it is the lowest power consumption but all data is lost once CE2 is brought to Low for Power Down. It is not required to program to Sleep mode after power-up.



Power Down Program Sequence

The program requires 6 read/write operations with a unique address. Between each read/write operation requires that device be in standby mode. The following table shows the detail sequence.

| Cycle # | Operation | Address | Data |
|---------|-----------|---------------|-----------------|
| 1st | Read | 3FFFFFh (MSB) | Read Data (RDa) |
| 2nd | Write | 3FFFFFh | RDa |
| 3rd | Write | 3FFFFFh | RDa |
| 4th | Write | 3FFFFFh | Don't Care (X) |
| 5th | Write | 3FFFFFh | Х |
| 6th | Read | Address Key | Read Data (RDb) |

The first cycle reads from the most significant address (MSB).

The second and third cycle are to write back the data (RDa) read by first cycle. If the second or third cycle is written into the different address, the program is cancelled, and the data written by the second or third cycle is valid as a normal write operation.

The fourth and fifth cycles write to MSB. The data from the fourth and fifth cycles is "don't care." If the fourth or fifth cycles are written into different address, the program is also cancelled but write data might not be written as normal write operation.

The last cycle is to read from specific address key for mode selection.

Once this program sequence is performed from a Partial mode to the other Partial mode, the written data stored in memory cell array can be lost. So, it should perform this program prior to regular read/write operation if Partial mode is used.

Address Key

The address key has following format.

| Ma | ode | Address | | | | | | | |
|-----------------|-----------------|---------|-----|-----|----------|---------|--|--|--|
| 32M | 64M | A2I | A20 | Al9 | AI8 - A0 | Binary | | | |
| Sleep (default) | Sleep (default) | 1 | 1 | 1 | 1 | 3FFFFFh | | | |
| 4M Partial | N/A | 1 | 1 | 0 | 1 | 37FFFFh | | | |
| 8M Partial | 8M Partial | 1 | 0 | 1 | 1 | 2FFFFFh | | | |
| N/A | 16M Partial | 1 | 0 | 0 | 1 | 27FFFFh | | | |



Absolute Maximum Ratings

| ltem | Symbol | Value | Unit |
|---|------------------------------------|--------------|------|
| Voltage of V_{DD} Supply Relative to V_{SS} | V _{DD} | -0.5 to +3.6 | V |
| Voltage at Any Pin Relative to V_{SS} | V _{IN} , V _{OUT} | -0.5 to +3.6 | V |
| Short Circuit Output Current | I _{OUT} | ±50 | mA |
| Storage temperature | T _{STG} | -55 to +125 | °C |

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

Recommended Operating Conditions

| Parameter | Symbol | Min | Max | Unit |
|-----------------------------------|-----------------|---------------------|----------------------|------|
| Supply Voltage | V _{DD} | 2.7 | 3.1 | V |
| Supply Voltage | V_{SS} | 0 | 0 | V |
| High Level Input Voltage (Note 1) | VIH | V _{DD} 0.8 | V _{DD} +0.2 | V |
| High Level Input Voltage (Note 1) | V _{IL} | -0.3 | V _{DD} 0.2 | V |
| Ambient Temperature | T _A | -30 | 85 | °C |

(See Warning Below)

Notes:

- 1. Maximum DC voltage on input and I/O pins is V_{DD} +0.2V. During voltage transitions, inputs can positive overshoot to V_{DD} +1.0V for periods of up to 5 ns.
- 2. Minimum DC voltage on input or I/O pins is -0.3V. During voltage transitions, inputs can negative overshoot V_{SS} to -1.0V for periods of up to 5ns.

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges can adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

Package Capacitance

Test conditions: $T_A = 25^{\circ}C$, f = 1.0 MHz

| Symbol | Description | Test Setup | Тур | Max | Unit |
|------------------|-------------------------------|---------------|-----|-----|------|
| C _{IN1} | Address Input Capacitance | $V_{IN} = OV$ | _ | 5 | pF |
| C _{IN2} | Control Input Capacitance | $V_{IN} = OV$ | | 5 | pF |
| C _{IO} | Data Input/Output Capacitance | $V_{IO} = OV$ | _ | 8 | pF |



(Under Recommended Conditions Unless Otherwise Noted)

| | | Test Conditions | | 10 | 5M | 32M | | 64M | | |
|--------------------------------------|--------------------|--|-----------------------------|------|------|------|------|------|------|------|
| Parameter | Symbol | | | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| Input Leakage Current | ILI | $V_{IN} = V_{SS}$ to V_{DD} | | -1.0 | +1.0 | -1.0 | +1.0 | -1.0 | +1.0 | μΑ |
| Output Leakage Current | I _{LO} | $V_{OUT} = V_{SS}$ to V_{DD} , Output Disa | able | -1.0 | +1.0 | -1.0 | +1.0 | -1.0 | +1.0 | μΑ |
| Output High Voltage Level | V _{OH} | $V_{DD} = V_{DD}(min), I_{OH} = -0.5m/$ | 4 | 2.2 | _ | 2.4 | _ | 2.4 | _ | V |
| Output Low Voltage Level | V _{OL} | I _{OL} = 1mA | | _ | 0.4 | _ | 0.4 | _ | 0.4 | V |
| I _{DDPS} | I _{DDPS} | | SLEEP | | 10 | _ | 10 | | 10 | μΑ |
| V _{DD} Power | I _{DDP4} | $V_{DD} = V_{DD} max.,$ | 4M Partial | N/A | | _ | 40 | N/A | | μΑ |
| Down Current | I _{DDP8} | $V_{IN} = V_{IH} \text{ or } V_{IL},$ CE2 \leq 0.2 V | 8M Partial | N/A | | _ | 50 | | 80 | μΑ |
| | I _{DDP16} | | 16M Partial | N | N/A | | /A | | 100 | μΑ |
| V _{DD} Standby | I _{DDS} | | | _ | 1 | _ | 1.5 | | 1.5 | mA |
| Current | | $V_{DD} = V_{DD} max.,$ | TA< +85°C | | 100 | | | | 170 | μA |
| | I _{DDS1} | $\frac{V_{IN}}{CE1} \le 0.2V \text{ or } V_{IN} \ge V_{DD} - 0.2V,$ $CE1 = CE2 \ge V_{DD} - 0.2V$ | TA< +40°C | | | _ | 80 | _ | 90 | μΑ |
| V | I _{DDA1} | $V_{DD} = V_{DD} max.,$ | $t_{RC} / t_{WC} = min.$ | - | 20 | _ | 30 | | 40 | mA |
| V _{DD} Active Current | I _{DDA2} | | $t_{RC} / t_{WC} = 1 \mu s$ | _ | 3 | _ | 3 | _ | 5 | mA |
| V _{DD} Page Read Current | I _{DDA3} | | | N | /A | _ | 10 | | 10 | mA |

Notes:

1. All voltages are referenced to V_{SS} .

2. DC Characteristics are measured after following POWER-UP timing.

3. I_{OUT} depends on the output load conditions.



(Under Recommended Operating Conditions Unless Otherwise Noted)

Read Operation

| Demonstern | Granderal | 16M | | 32M | | 64 | ŧм | 11-14 | | |
|-----------------------------------|-------------------|------|------|------|------|------|------|-------|---------|--|
| Parameter | Symbol | Min. | Max. | Min. | Max. | Min. | Max. | Unit | Notes | |
| Read Cycle Time | t _{RC} | 70 | 1000 | 65 | 1000 | 65 | 1000 | ns | 1, 2 | |
| CE1# Access Time | t _{CE} | _ | 60 | _ | 65 | _ | 65 | ns | 3 | |
| OE# Access Time | t _{OE} | _ | 40 | _ | 40 | _ | 40 | ns | 3 | |
| Address Access Time | t _{AA} | _ | 60 | _ | 65 | _ | 65 | ns | 3, 5 | |
| LB# / UB# Access Time | t _{BA} | _ | 30 | _ | 30 | _ | 30 | ns | 3 | |
| Page Address Access Time | t _{PAA} | N | /A | _ | 20 | _ | 20 | ns | 3,6 | |
| Page Read Cycle Time | t _{PRC} | N | /A | 20 | 1000 | 20 | 1000 | ns | 1, 6, 7 | |
| Output Data Hold Time | t _{OH} | 5 | _ | 5 | _ | 5 | — | ns | 3 | |
| CE1# Low to Output Low-Z | t _{CLZ} | 5 | _ | 5 | _ | 5 | — | ns | 4 | |
| OE# Low to Output Low-Z | t _{OLZ} | 0 | _ | 0 | _ | 0 | _ | ns | 4 | |
| LB# / UB# Low to Output Low-Z | t _{BLZ} | 0 | _ | 0 | _ | 0 | — | ns | 4 | |
| CE1# High to Output High-Z | t _{CHZ} | _ | 20 | _ | 20 | _ | 20 | ns | 3 | |
| OE# High to Output High-Z | t _{OHZ} | _ | 20 | _ | 14 | _ | 14 | ns | 3 | |
| LB# / UB# High to Output High-Z | t _{BHZ} | _ | 20 | _ | 20 | _ | 20 | ns | 3 | |
| Address Setup Time to CE1# Low | t _{ASC} | -6 | _ | -6 | _ | -6 | _ | ns | | |
| Address Setup Time to OE# Low | t _{ASO} | 10 | _ | 10 | _ | 10 | _ | ns | | |
| Address Invalid Time | t _{AX} | _ | 10 | _ | 10 | _ | 10 | ns | 5,8 | |
| Address Hold Time from CE1# High | t _{CHAH} | -6 | _ | -6 | _ | -6 | | ns | 9 | |
| Address Hold Time from OE# High | t _{OHAH} | -6 | _ | -6 | _ | -6 | | ns | | |
| WE# High to OE# Low Time for Read | t _{WHOL} | 10 | 1000 | 12 | _ | 25 | _ | ns | 10 | |
| CE1# High Pulse Width | t _{CP} | 10 | _ | 12 | _ | 12 | _ | ns | | |

Notes:

1. Maximum value is applicable if CE#1 is kept at Low without change of address input of A3 to A21. If needed by system operation, please contact local Spansion representative for the relaxation of 1µs limitation.

- 2. Address should not be changed within minimum t_{RC} .
- 3. The output load 50 pF with 50 ohm termination to $V_{DD} \times 0.5$ (16M), The output load 50 pF (32M and 64M).
- 4. The output load 5pF.
- 5. Applicable to A3 to A21 (32M and 64M) when CE1# is kept at Low.
- 6. Applicable only to A0, A1 and A2 (32M and 64M) when CE1# is kept at Low for the page address access.
- 7. In case Page Read Cycle is continued with keeping CE1# stays Low, CE1# must be brought to High within 4 μ s. In other words, Page Read Cycle must be closed within 4 μ s.
- 8. Applicable when at least two of address inputs among applicable are switched from previous state.
- 9. $t_{RC}(min)$ and $t_{PRC}(min)$ must be satisfied.
- 10. If actual value of t_{WHOL} is shorter than specified minimum values, the actual t_{AA} of following Read can become longer by the amount of subtracting the actual value from the specified minimum value.

Write Operation

| | | 16 | 16M 32M 64M | | 32M | | 64M | | |
|--|-------------------|------|-------------|------|------|------|------|------|-------|
| Parameter | Symbol | Min. | Max. | Min. | Max. | Min. | Max. | Unit | Notes |
| Write Cycle Time | t _{WC} | 70 | 1000 | 65 | 1000 | 65 | 1000 | ns | 1,2 |
| Address Setup Time | t _{AS} | 0 | _ | 0 | _ | 0 | _ | ns | 3 |
| CE1# Write Pulse Width | t _{CW} | 45 | _ | 40 | _ | 40 | _ | ns | 3 |
| WE# Write Pulse Width | t _{WP} | 45 | _ | 40 | _ | 40 | _ | ns | 3 |
| LB#/UB# Write Pulse Width | t _{BW} | 45 | _ | 40 | _ | 40 | _ | ns | 3 |
| LB#/UB# Byte Mask Setup Time | t _{BS} | -5 | _ | -5 | _ | -5 | _ | ns | 4 |
| LB#/UB# Byte Mask Hold Time | t _{BH} | -5 | _ | -5 | _ | -5 | _ | ns | 5 |
| Write Recovery Time | t _{WR} | 0 | _ | 0 | _ | 0 | _ | ns | 6 |
| CE1# High Pulse Width | t _{CP} | 10 | — | 12 | — | 12 | — | ns | |
| WE# High Pulse Width | t _{WHP} | 7.5 | 1000 | 7.5 | 1000 | 7.5 | 1000 | ns | 7 |
| LB#/UB# High Pulse Width | t _{BHP} | 10 | 1000 | 12 | 1000 | 12 | 1000 | ns | |
| Data Setup Time | t _{DS} | 15 | _ | 12 | _ | 12 | _ | ns | |
| Data Hold Time | t _{DH} | 0 | _ | 0 | _ | 0 | _ | ns | |
| OE# High to CE1# Low Setup Time for Write | t _{OHCL} | -5 | _ | -5 | _ | -5 | _ | ns | 8 |
| OE# High to Address Setup Time for Write | t _{OES} | 0 | _ | 0 | _ | 0 | _ | ns | 9 |
| LB# and UB# Write Pulse Overlap | t _{BWO} | 30 | — | 30 | — | 30 | _ | ns | |

Notes:

1. Maximum value is applicable if CE1# is kept at Low without any address change. If the relaxation is needed by system operation, please contact local Spansion representative for the relaxation of 1µs limitation.

2. Minimum value must be equal or greater than the sum of write pulse (t_{CW} , t_{WP} or t_{BW}) and write recovery time (t_{WR}).

- 3. Write pulse is defined from High to Low transition of CE1#, WE#, or LB#/UB#, whichever occurs last.
- 4. Applicable for byte mask only. Byte mask setup time is defined to the High to Low transition of CE1# or WE# whichever occurs last.
- 5. Applicable for byte mask only. Byte mask hold time is defined from the Low to High transition of CE1# or WE# whichever occurs first.
- 6. Write recovery is defined from Low to High transition of CE1#, WE#, or LB#/UB#, whichever occurs first.
- 7. t_{WPH} minimum is absolute minimum value for device to detect High level. And it is defined at minimum V_{IH} level.
- 8. If OE# is Low after minimum t_{OHCL} , read cycle is initiated. In other words, OE# must be brought to High within 5ns after CE1# is brought to Low. Once read cycle is initiated, new write pulse should be input after minimum t_{RC} is met.
- If OE# is Low after new address input, read cycle is initiated. In other word, OE# must be brought to High at the same time or before new address valid. Once read cycle is initiated, new write pulse should be input after minimum t_{RC} is met and data bus is in High-Z.



Power Down Parameters

| | | 16 | М | 32 | M | 64M | | | |
|---|-------------------|------|------|------|------|------|------|------|------|
| Parameter | Symbol | Min. | Max. | Min. | Max. | Min. | Max. | Unit | Note |
| CE2 Low Setup Time for Power Down Entry | t _{CSP} | 10 | _ | 10 | _ | 10 | _ | ns | |
| CE2 Low Hold Time after Power Down Entry | t _{C2LP} | 80 | _ | 65 | _ | 65 | _ | ns | |
| CE1# High Hold Time following CE2 High after Power Down Exit [SLEEP mode only] | t _{CHH} | 300 | _ | 300 | _ | 300 | _ | μs | 1 |
| CE1# High Hold Time following CE2 High after Power Down Exit [not in SLEEP mode] | t _{CHHP} | N | /A | 1 | _ | 1 | _ | μs | 2 |
| CE1# High Setup Time following CE2 High after Power Down Exit | t _{CHS} | 0 | _ | 0 | _ | 0 | _ | ns | 1 |

Notes:

1. Applicable also to power-up.

2. Applicable when 4Mb and 8Mb Partial modes are programmed.

Other Timing Parameters

| | | 16 | М | 32M 64M | | M | | | |
|---|-------------------|------|------|---------|------|------|------|------|------|
| Parameter | Symbol | Min. | Max. | Min. | Max. | Min. | Max. | Unit | Note |
| CE1# High to OE# Invalid Time for Standby Entry | t _{CHOX} | 10 | _ | 10 | _ | 10 | _ | ns | |
| CE1# High to WE# Invalid Time for Standby Entry | t _{CHWX} | 10 | _ | 10 | _ | 10 | _ | ns | 1 |
| CE2 Low Hold Time after Power-up | t _{C2LH} | 50 | — | 50 | - | 50 | _ | μs | |
| CE1# High Hold Time following CE2 High after Power-up | t _{CHH} | 300 | — | 300 | - | 300 | — | μs | |
| Input Transition Time | t _T | 1 | 25 | 1 | 25 | 1 | 25 | ns | 2 |

Notes:

1. Some data might be written into any address location if $t_{CHWX}(min)$ is not satisfied.

2. The Input Transition Time (t_T) at AC testing is 5ns as shown in below. If actual tT is longer than 5ns, it can violate the AC specification of some of the timing parameters.



AC Test Conditions

| Symbol | Description | Test Setup | Value | Unit | Note |
|------------------|--------------------------------|-------------------------------|-----------------------|------|------|
| V _{IH} | Input High Level | | V _{DD} * 0.8 | V | |
| V _{IL} | Input Low Level | | V _{DD} * 0.2 | V | |
| V _{REF} | Input Timing Measurement Level | | V _{DD} * 0.5 | V | |
| t _T | Input Transition Time | Between V_{IL} and V_{IH} | 5 | ns | |

AC Measurement Output Load Circuits

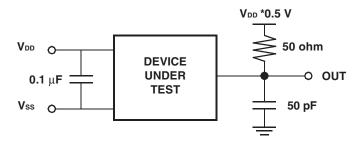


Figure 2I. AC Output Load Circuit – 16 Mb

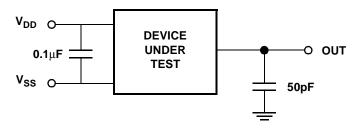
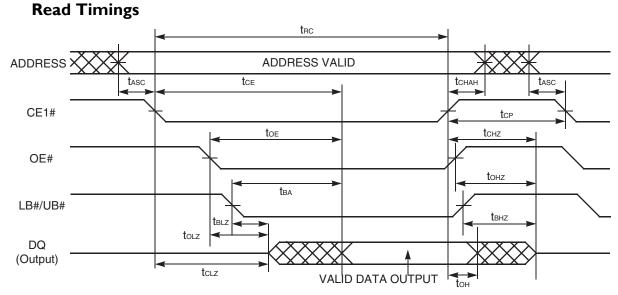


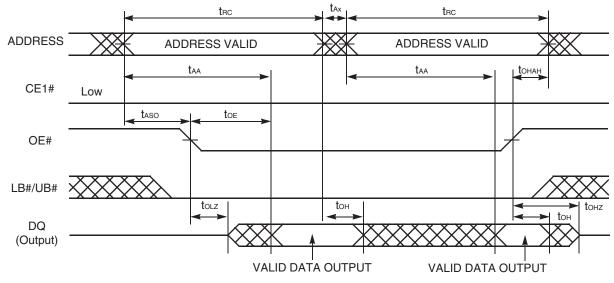
Figure 22. AC Output Load Circuit - 32 Mb and 64 Mb

Timing Diagrams



Note: This timing diagram assumes CE2=H and WE#=H.

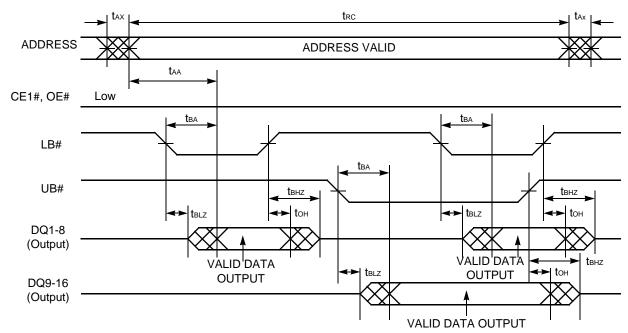




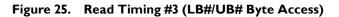
Note: This timing diagram assumes CE2=H and WE#=H.

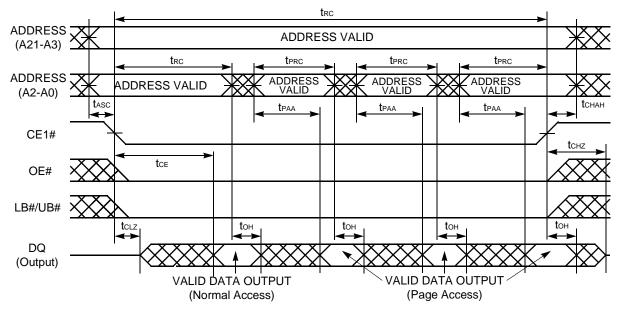
Figure 24. Read Timing #2 (OE# Address Access

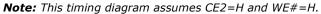


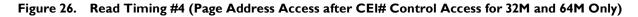


Note: This timing diagram assumes CE2=H and WE#=H.

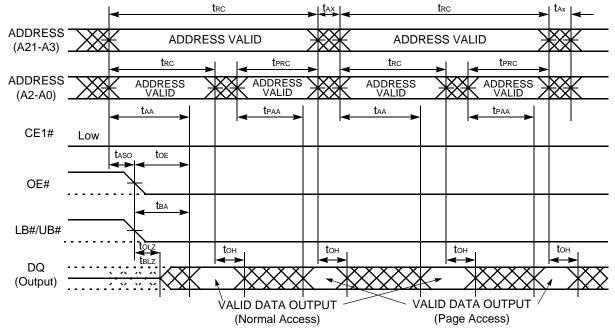










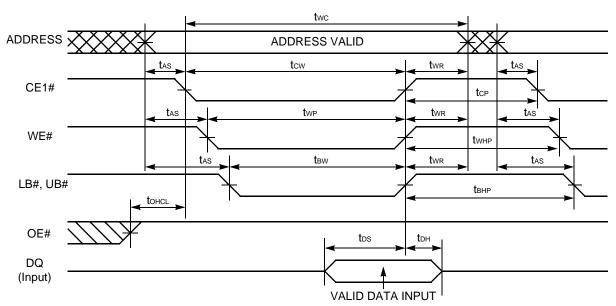


Notes:

1. This timing diagram assumes CE2=H and WE#=H.

2. Either or both LB# and UB# must be Low when both CE1# and OE# are Low.



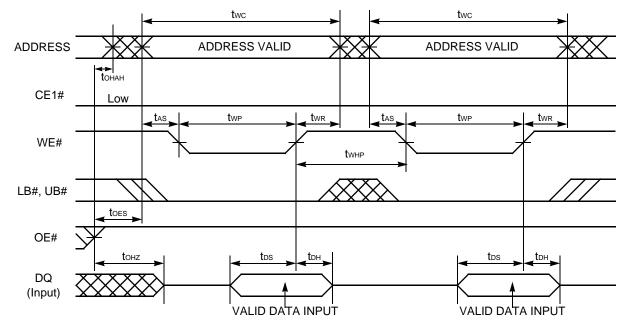


Write Timings

Note: This timing diagram assumes CE2=H.

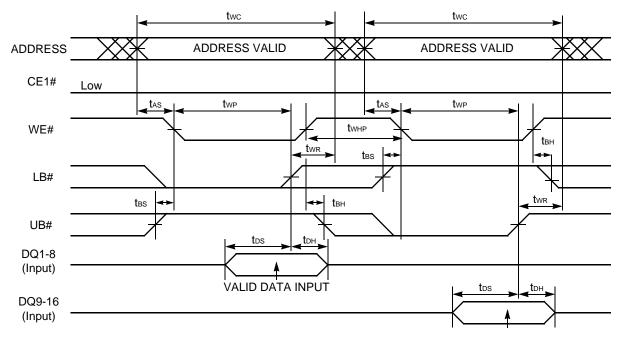
Figure 28. Write Timing #I (Basic Timing)

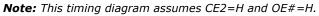




Note: This timing diagram assumes CE2=H.

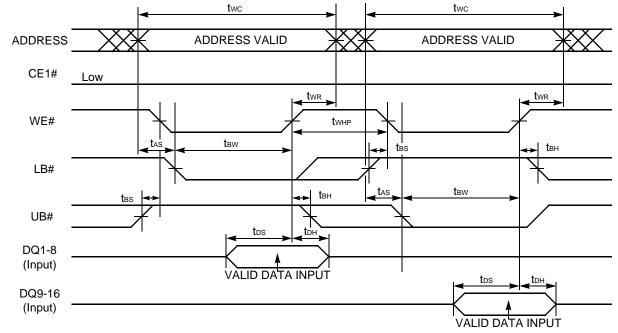






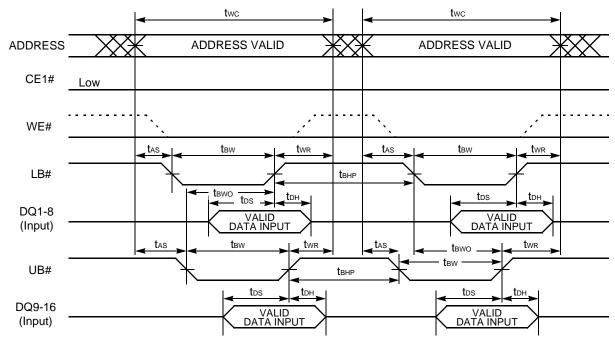






Note: This timing diagram assumes CE2=H and OE#=H.



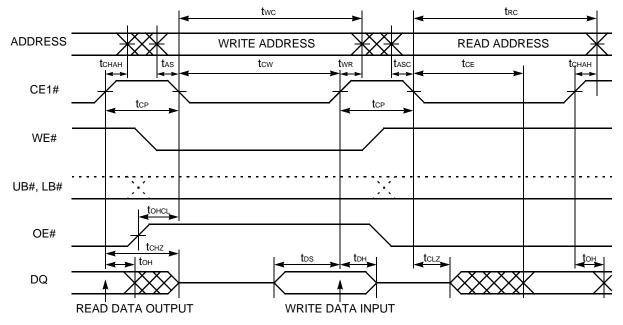


Note: This timing diagram assumes CE2=H and OE#=H.





Read/Write Timings

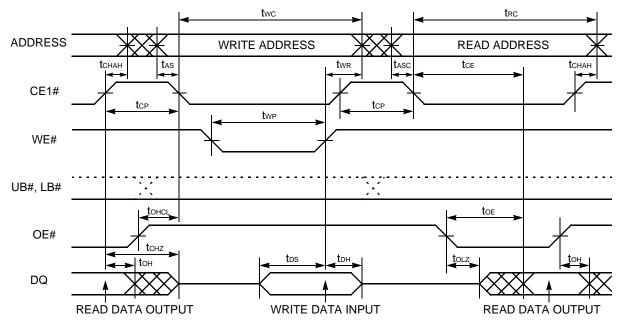


Notes:

1. This timing diagram assumes CE2=H.

2. Write address is valid from either CE1# or WE# of last falling edge.





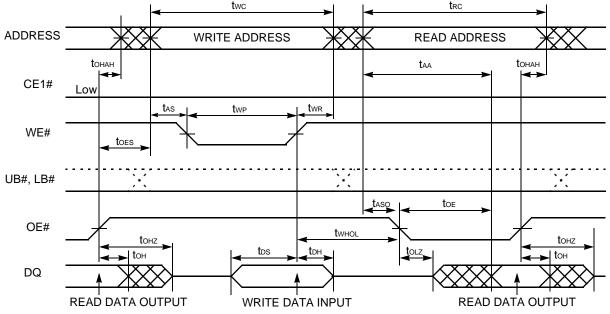
Notes:

1. This timing diagram assumes CE2=H.

2. OE# can be fixed Low during write operation if it is CE1# controlled write at Read-Write-Read sequence.

Figure 34. Read / Write Timing #I-2 (CEI#/WE#/OE# Control)



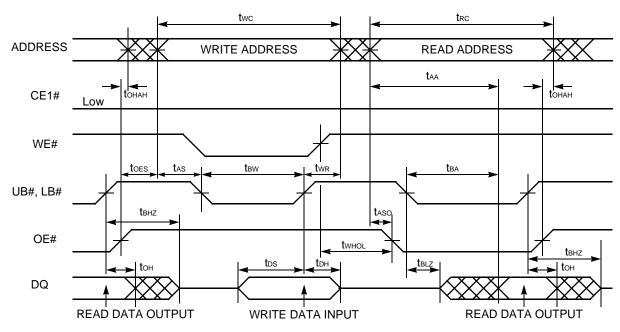


Notes:

1. This timing diagram assumes CE2=H.

2. CE1# can be tied to Low for WE# and OE# controlled operation.

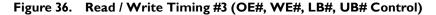




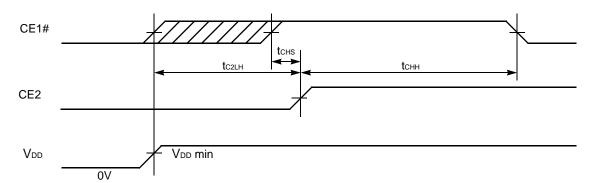
Notes:

1. This timing diagram assumes CE2=H.

2. CE1# can be tied to Low for WE# and OE# controlled operation.

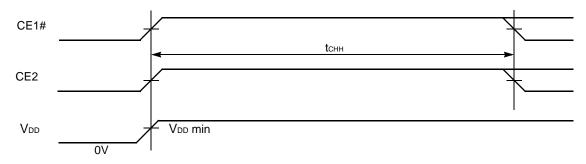






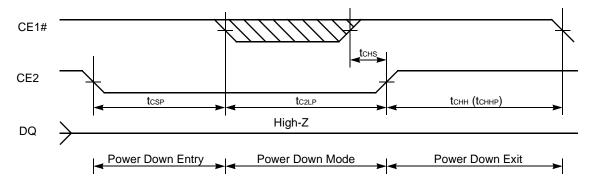
Note: The t_{C2LH} specifies after V_{DD} reaches specified minimum level.

Figure 37. Power-up Timing #I



Note: The t_{CHH} specifies after V_{DD} reaches specified minimum level and applicable to both CE1# and CE2.

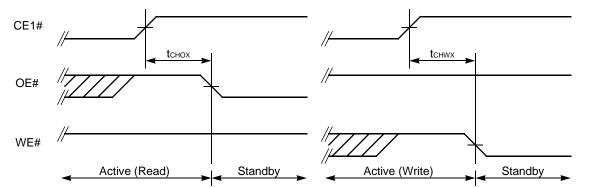
Figure 38. Power-up Timing #2



Note: This Power Down mode can be also used as a reset timing if POWER-UP timing above could not be satisfied and Power-Down program was not performed prior to this reset.

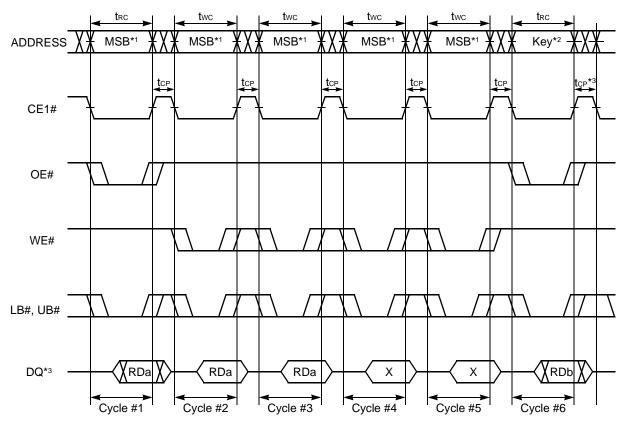
Figure 39. Power Down Entry and Exit Timing





Note: Both t_{CHOX} and t_{CHWX} define the earliest entry timing for Standby mode. If either of timing is not satisfied, it takes t_{RC} (min) period for Standby mode from CE1# Low to High transition.





Notes:

- 1. The all address inputs must be High from Cycle #1 to #5.
- 2. The address key must confirm the format specified in page 106. If not, the operation and data are not guaranteed.
- 3. After t_{CP} following Cycle #6, the Power Down Program is completed and returned to the normal operation.

Figure 4I. Power Down Program Timing (for 32M/64M Only)



Revision Summary

Revision A (December 17, 2004)

Initial release.

Colophon

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